




# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

**MAX17009**

## General Description

The MAX17009 is a 2-phase, step-down interleaved, fixed-frequency controller for AMD's<sup>®</sup> serial VID interface (SVI) CPU core supplies. Power-on detection of the CPU configures the MAX17009 as two independent single-phase regulators for a dual CPU core application, or one high-current, dual-phase, combined-output regulator for a unified core application. A reference buffer output (NBV\_BUF) sets the voltage-regulation level for a North Bridge (NB) regulator, completing the total CPU cores and NB power requirements.

The MAX17009 is fully AMD SVI compliant. Output voltages are dynamically changed through a 2-wire serial interface, allowing the switching regulator and the reference buffer to be individually programmed to different voltages. A programmable slew-rate controller enables controlled transitions between VID codes, soft-start limits the inrush current, and soft-shutdown brings the output voltage back down to zero without any negative ring.

Transient phase repeat improves the response of the fixed-frequency architecture. Independently programmable AC and DC droop and selectable offset improve stability and reduce the total output-capacitance requirement. A thermistor-based temperature sensor allows for a programmable thermal-fault output (VRHOT). The MAX17009 includes thermal-fault protection, undervoltage protection (UVP), and selectable output overvoltage protection (OVP). When any of these protection features detect a fault, the controller shuts down. True differential current sensing improves current limit, load-line accuracy, and current balance when operating in combined mode. The MAX17009 has an adjustable switching frequency, allowing 100kHz to 1.2MHz per-phase operation.

## Applications

Mobile AMD SVI Core Supply  
 Multiphase CPU Core Supply  
 Voltage-Positioned, Step-Down Converters  
 Notebook/Desktop Computers

*Pin Configuration appears at end of data sheet.*

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## Features

- ◆ Dual-Output, Fixed-Frequency, Core Supply Controller
- ◆ Separate or Combinable Outputs Detected at Power-Up
- ◆ Reference Buffer Output for NB Controller
- ◆  $\pm 0.4\%$   $V_{OUT}$  Accuracy Over Line, Load, and Temperature
- ◆ AMD SVI-Compliant Serial Interface
- ◆ 7-Bit On-Board DAC: 0 to +1.550V Output Adjust Range
- ◆ Dynamic Phase Selection Optimizes Active/Sleep Efficiency
- ◆ Transient Phase Repeat Reduces Output Capacitance
- ◆ True Out-of-Phase Operation Reduces Input Capacitance
- ◆ Integrated Boost Switches
- ◆ Programmable AC and DC Droop
- ◆ Programmable 100kHz to 1.2MHz Switching Frequency
- ◆ Accurate Current Balance and Current Limit
- ◆ Adjustable Slew-Rate Control
- ◆ Power-Good (PWRGD) and Thermal-Fault (VRHOT) Outputs
- ◆ System Power-OK (PGD\_IN) Input
- ◆ Drives Large Synchronous-Rectifier MOSFETs
- ◆ 4V to 26V Battery Input-Voltage Range
- ◆ Overvoltage, Undervoltage, and Thermal-Fault Protection
- ◆ Power Sequencing and Timing
- ◆ Soft-Startup and Soft-Shutdown
- ◆  $< 1\mu\text{A}$  Typical Shutdown Current

## Ordering Information

| PART         | TEMP RANGE      | PIN-PACKAGE               | PKG CODE |
|--------------|-----------------|---------------------------|----------|
| MAX17009GTL+ | -40°C to +105°C | 40 TQFN-EP*,<br>5mm x 5mm | T4055-1  |

+Denotes a lead-free package.

\*EP = Exposed pad.



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## ABSOLUTE MAXIMUM RATINGS

|  |                       |
|--|-----------------------|
| VDD1, VDD2, VCC, VDDIO to GND_                 | -0.3V to +6V          |
| PWRGD to GND_                                  | -0.3V to +6V          |
| FBDC_, FBAC_, $\overline{\text{PRO}}$ to GND_  | -0.3V to (VCC + 0.3V) |
| GNDS2, THRM, $\overline{\text{VRHOT}}$ to GND_ | -0.3V to +6V          |
| CSP_, CSN_, ILIM to GND_                       | -0.3V to +6V          |
| SVC, SVD, PGD_IN to GND_                       | -0.3V to +6V          |
| NBV_BUF, NBSKP to GND_                         | -0.3V to (VCC + 0.3V) |
| REF, OSC, TIME, OPTION to GND_                 | -0.3V to (VCC + 0.3V) |
| BST1, BST2 to GND_                             | -0.3V to +36V         |
| BST1 to VDD1                                   | -0.3V to +30V         |
| BST2 to VDD2                                   | -0.3V to +30V         |
| LX1 to BST1                                    | -6V to +0.3V          |
| LX2 to BST2                                    | -6V to +0.3V          |

|   |                         |
|---|-------------------------|
| DH1 to LX1                                      | -0.3V to (VBST1 + 0.3V) |
| DH2 to LX2                                      | -0.3V to (VBST2 + 0.3V) |
| DL1 to GND_                                     | -0.3V to (VDD1 + 0.3V)  |
| DL2 to GND_                                     | -0.3V to (VDD2 + 0.3V)  |
| GNDS1, GNDS_NB to GND_                          | -0.3V to +0.3V          |
| Continuous Power Dissipation (TA = +70°C)       |                         |
| Multilayer PCB (derate 35.7mW/°C above +70°C)   | .....2857mW             |
| Single-Layer PCB (derate 22.2mW/°C above +70°C) | ..1778mW                |
| Operating Temperature Range                     | .....-40°C to +105°C    |
| Junction Temperature                            | .....+150°C             |
| Storage Temperature Range                       | .....-65°C to +150°C    |
| Lead Temperature (soldering, 10s)               | .....+300°C             |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

(Circuit of Figure 2, VIN = 12V, VCC = VDD1 = VDD2 =  $\overline{\text{SHDN}}$  = PGD\_IN = 5V, VDDIO = 1.8V,  $\overline{\text{PRO}}$  = OPTION = GNDS\_NB = GNDS\_ = GND\_, FBDC\_ = FBAC\_ = CSP\_ = CSN\_ = 1.2V, all DAC codes set to the 1.2V code, TA = 0°C to +85°C, unless otherwise noted. Typical values are at TA = +25°C.)

| PARAMETER                              | SYMBOL     | CONDITIONS  | MIN   | TYP   | MAX   | UNITS |
|--|------------|---|-------|-------|-------|-------|
| <b>INPUT SUPPLIES</b>                  |            |   |       |       |       |       |
| Input Voltage Range                    | VIN        | Drain of external high-side MOSFET  | 4     |       | 26    | V     |
|  | VBIAS      | VCC, VDD1, VDD2   | 4.5   |       | 5.5   |       |
|  | VDDIO      |   | 1.0   |       | 2.7   |       |
| VCC Undervoltage-Lockout Threshold     | VUVLO      | VCC rising 50mV typical hysteresis  | 4.10  | 4.25  | 4.45  | V     |
| VCC Power-On Reset Threshold           | VCC        | Falling edge, typical hysteresis = 1.1V, faults cleared and DL_ forced high when VCC falls below this level |       | 1.8   |       | V     |
| VDDIO Undervoltage-Lockout Threshold   |            | VDDIO rising 100mV typical hysteresis   | 0.7   | 0.8   | 0.9   | V     |
| Quiescent Supply Current (VCC)         | ICC        | Skip mode, FBDC_ forced above their regulation points   |       | 5     | 10    | mA    |
| Quiescent Supply Currents (VDD1, VDD2) | IDD1, IDD2 | Skip mode, FBDC_ forced above their regulation points   |       | 0.01  | 1     | μA    |
| Quiescent Supply Current (VDDIO)       | IDDIO      |   |       | 10    | 25    | μA    |
| Shutdown Supply Current (VCC)          |            | $\overline{\text{SHDN}}$ = GND  |       | 0.01  | 1     | μA    |
| Shutdown Supply Currents (VDD1, VDD2)  |            | $\overline{\text{SHDN}}$ = GND  |       | 0.01  | 1     | μA    |
| Shutdown Supply Current (VDDIO)        |            | $\overline{\text{SHDN}}$ = GND  |       | 0.01  | 1     | μA    |
| Reference Voltage                      | VREF       | VCC = 4.5V to 5.5V, no REF load   | 1.986 | 2.000 | 2.014 | V     |
| Reference Load Regulation              |            | Sourcing: IREF = 0 to 500μA   | -2    | -0.2  |       | mV    |
|  |            | Sinking: IREF = 0 to -100μA   |       | 0.21  | 6.2   |       |
| REF Fault Lockout Voltage              |            | Typical hysteresis = 85mV   |       | 1.84  |       | V     |

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## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 2,  $V_{IN} = 12V$ ,  $V_{CC} = V_{DD1} = V_{DD2} = \overline{SHDN} = PGD\_IN = 5V$ ,  $V_{DDIO} = 1.8V$ ,  $\overline{PRO} = OPTION = GNDS\_NB = GNDS\_ = GND\_$ ,  $FBDC\_ = FBAC\_ = CSP\_ = CSN\_ = 1.2V$ , all DAC codes set to the 1.2V code,  $T_A = 0^{\circ}C$  to  $+85^{\circ}C$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

| PARAMETER                           | SYMBOL        | CONDITIONS   | MIN   | TYP          | MAX            | UNITS   |            |
|-------------------------------------|---------------|--|---|--------------|----------------|---------|------------|
| <b>MAIN SMPS CONTROLLERS</b>        |               |  |   |              |                |         |            |
| DC Output-Voltage Accuracy (Note 1) | $V_{OUT}$     | DAC codes from 0.8375V to 1.5500V  | -0.4  |              | +0.4           | %       |            |
|                                     |               | DAC codes from 0.5000V to 0.8250V  | -4  |              | +4             | mV      |            |
|                                     |               | DAC codes below 0.4875V  | -10   |              | +10            |         |            |
| DC Load Regulation                  |               | Either SMPS, PWM mode, droop disabled, zero to full load   |   | -0.1         |                | %       |            |
| Line-Regulation Error               |               | Either SMPS, $4V < V_{IN} < 26V$   |   | 0.03         |                | %/V     |            |
| GNDS_ Input Range                   | $V_{GNDS\_}$  | Separate mode  | -200  |              | +200           | mV      |            |
| GNDS_ Gain                          | $A_{GNDS\_}$  | Separate: $\Delta V_{OUT\_}/\Delta V_{GNDS\_}$ , $-200mV \leq V_{GNDS\_} \leq +200mV$ ;<br>combined: $\Delta V_{OUT\_}/\Delta V_{GNDS1}$ , $-200mV \leq V_{GNDS1} \leq +200mV$ | 0.95  | 1.00         | 1.05           | V/V     |            |
| GNDS_ Input Bias Current            | $I_{GNDS\_}$  |  | -2  |              | +2             | $\mu A$ |            |
| Combined-Mode Detection Threshold   |               | GNDS2, detection after REFOK, latched, cleared by cycling $\overline{SHDN}$  | 0.7   | 0.8          | 0.9            | V       |            |
| FBDC_ Input Bias Current            | $I_{FBDC0\_}$ | $CSP\_ = CSN\_$  | -3  |              | +3             | $\mu A$ |            |
| Switching-Frequency Accuracy        | $f_{OSC}$     | $R_{OSC} = 143k\Omega$ ( $f_{OSC} = 300kHz$ nominal)   | -5  |              | +5             | %       |            |
|                                     |               | $R_{OSC} = 35.7k\Omega$ ( $f_{OSC} = 1.2MHz$ nominal) to $432k\Omega$ ( $f_{OSC} = 99kHz$ nominal)   | -7.5  |              | +7.5           |         |            |
| Maximum Duty Factor                 | $D_{MAX}$     |  | 90  | 92           |                | %       |            |
| Minimum On-Time                     | $t_{ONMIN}$   |  |   |              | 175            | ns      |            |
| SMPS1-to-SMPS2 Phase Shift          |               | SMPS2 starts after SMPS1   |   | 50           |                | %       |            |
|                                     |               |  |   | 180          |                | Degrees |            |
| TIME Slew-Rate Accuracy             |               | During transition  | $R_{TIME} = 143k\Omega$ , $SR = 6.25mV/\mu s$                                 | -10          |                | +10     | %          |
|                                     |               |  | $R_{TIME} = 35.7k\Omega$ to $357k\Omega$ , $SR = 25mV/\mu s$ to $2.5mV/\mu s$ | -15          |                | +15     |            |
|                                     |               | Startup and shutdown   |   |              | 1              |         | $mV/\mu s$ |
| <b>CURRENT LIMIT</b>                |               |  |   |              |                |         |            |
| Current-Limit Threshold Tolerance   | $V_{LIMIT}$   | $V_{CSP\_} - V_{CSN\_} = 0.05 \times (V_{REF} - V_{ILIM})$ , $(V_{REF} - V_{ILM}) = 0.2V$ to $1.0V$  | -3  |              | +3             | mV      |            |
| Zero-Crossing Threshold             | $V_{ZX}$      | $V_{GND\_} - V_{LX\_}$ , SKIP mode   |   | 3            |                | mV      |            |
| Idle Mode™ Threshold Tolerance      | $V_{IDLE}$    | $V_{CSP\_} - V_{CSN\_}$ , SKIP mode, $0.15 \times V_{LIMIT}$   | -1.5  |              | +1.5           | mV      |            |
| CS_ Input-Leakage Current           |               | $CSP\_$ and $CSN\_$  | -0.2  |              | +0.2           | $\mu A$ |            |
| CS_ Common-Mode Input Range         |               | $CSP\_$ and $CSN\_$  | 0   |              | 2              | V       |            |
| Phase-Disable Threshold             |               | CSP2   | 3   | $V_{CC} - 1$ | $V_{CC} - 0.4$ | V       |            |

Idle Mode is a trademark of Maxim Integrated Products, Inc.

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## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 2,  $V_{IN} = 12V$ ,  $V_{CC} = V_{DD1} = V_{DD2} = \overline{SHDN} = PGD_{IN} = 5V$ ,  $V_{DDIO} = 1.8V$ ,  $\overline{PRO} = \text{OPTION} = \text{GNDS\_NB} = \text{GNDS\_} = \text{GND\_}$ ,  $\text{FBDC\_} = \text{FBAC\_} = \text{CSP\_} = \text{CSN\_} = 1.2V$ , all DAC codes set to the 1.2V code,  $T_A = 0^\circ\text{C to } +85^\circ\text{C}$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ\text{C}$ .)

| PARAMETER  | SYMBOL                | CONDITIONS  | MIN   | TYP  | MAX  | UNITS         |    |
|--|-----------------------|---|---|------|------|---------------|----|
| <b>DROOP AND CURRENT BALANCE</b>   |                       |   |   |      |      |               |    |
| DC Droop Amplifier Transconductance  | $G_{m(\text{FBDC}_)}$ | $\Delta I_{\text{FBDC}_}/(\Delta V_{\text{CS}_}),$<br>$V_{\text{FBDC}_} = V_{\text{CSN}_} = 1.2V,$<br>$V_{\text{CSP}_} - V_{\text{CSN}_} = -60\text{mV to } +60\text{mV}$ | 0.97  | 1.00 | 1.03 | mS            |    |
| DC Droop and Current-Balance Amplifier Offset  |                       | $I_{\text{FBDC}_}/G_{m(\text{FBDC}_)}$  | -1.5  |      | +1.5 | mV            |    |
| AC Droop and Current-Balance Amplifier Transconductance  | $G_{m(\text{FBAC}_)}$ | $\Delta I_{\text{FBAC}_}/(\Delta V_{\text{CS}_}),$<br>$V_{\text{FBAC}_} = V_{\text{CSN}_} = 1.2V,$<br>$V_{\text{CSP}_} - V_{\text{CSN}_} = -60\text{mV to } +60\text{mV}$ | 0.97  | 1.00 | 1.03 | mS            |    |
| AC Droop and Current-Balance Amplifier Offset  |                       | $I_{\text{FBAC}_}/G_{m(\text{FBAC}_)}$  | -1.5  |      | +1.5 | mV            |    |
| No-Load Positive Offset with Offset Enabled  |                       | Offset enabled, OPTION = REF or GND   |   | 12.5 |      | mV            |    |
| Transient Detection Threshold  |                       | Measured at $\text{FBDC}_$ with respect to steady-state $\text{FBDC}_$ regulation voltage, 5mV hysteresis (typ), transient phase-repeat enabled, OPTION = OPEN or GND     | -32   |      | -18  | mV            |    |
| <b>NB BUFFER</b>   |                       |   |   |      |      |               |    |
| NBV_BUF Output Voltage Accuracy  | $V_{\text{NBV\_BUF}}$ | DAC codes from 0.8375V to 1.5500V   | -0.4  |      | +0.4 | %             |    |
|  |                       | DAC codes from 0.5000V to 0.8250V   | -4  |      | +4   | mV            |    |
|  |                       | DAC codes below 0.4875V to 0.0125V  | -10   |      | +10  | mV            |    |
| NBV_BUF Short-Circuit Current (Sets Slew Rate Together with External Capacitor $C_{\text{NBV\_BUF}}$ ) |                       | DAC code set to 1.2V, $V_{\text{NBV\_BUF}} = 0.4V$ and 2V   | $R_{\text{TIME}} = 143\text{k}\Omega,$<br>$I_{\text{NBV\_BUF}} = 7.0\mu\text{A}$  | -10  |      | +10           | %  |
|  |                       |   | $R_{\text{TIME}} = 35.7\text{k}\Omega$ to $357\text{k}\Omega,$<br>$I_{\text{NBV\_BUF}} = 28\mu\text{A}$ to $2.8\mu\text{A}$ | -15  |      | +15           | %  |
| GNDS_NB Input Range  | $V_{\text{GNDS\_NB}}$ |   | -200  |      | +200 | mV            |    |
| GNDS_NB Gain   | $A_{\text{GNDS\_NB}}$ | $\Delta V_{\text{NBV\_BUF}}/\Delta V_{\text{GNDS\_NB}},$<br>$-200\text{mV} \leq V_{\text{GNDS\_NB}} \leq +200\text{mV}$   | 0.95  | 1.00 | 1.05 | V/V           |    |
| GNDS_NB Input Bias Current   | $I_{\text{GNDS\_NB}}$ |   | -2  |      | +2   | $\mu\text{A}$ |    |
| <b>FAULT DETECTION</b>   |                       |   |   |      |      |               |    |
| Output Overvoltage Trip Threshold  | $V_{\text{OVP}_}$     | Measured at $\text{FBDC}_$ , rising edge  | Normal operation  | 250  | 300  | 350           | mV |
|  |                       |   | Output not in regulation after a downward VID transition  | 1.80 | 1.85 | 1.90          | V  |
|  |                       |   | Minimum OVP threshold   |      | 0.8  |               |    |
| Output Overvoltage Fault-Propagation Delay   | $t_{\text{OVP}}$      | $\text{FBDC}_$ forced 25mV above trip threshold   |   | 10   |      | $\mu\text{s}$ |    |
| Output Undervoltage-Protection Trip Threshold  | $V_{\text{UVP}}$      | Measured at $\text{FBDC}_$ with respect to unloaded output voltage  | -450  | -400 | -350 | mV            |    |

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## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 2,  $V_{IN} = 12V$ ,  $V_{CC} = V_{DD1} = V_{DD2} = \overline{SHDN} = PGD\_IN = 5V$ ,  $V_{DDIO} = 1.8V$ ,  $\overline{PRO} = OPTION = GNDS\_NB = GNDS\_ = GND\_$ ,  $FBDC\_ = FBAC\_ = CSP\_ = CSN\_ = 1.2V$ , all DAC codes set to the 1.2V code,  $T_A = 0^{\circ}C$  to  $+85^{\circ}C$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

| PARAMETER  | SYMBOL                 | CONDITIONS   |  | MIN  | TYP  | MAX  | UNITS    |
|--|------------------------|--|--|------|------|------|----------|
| Output Undervoltage Fault-Propagation Delay      | $t_{UVP}$              | FBDC_ forced 25mV below trip threshold   |  |      | 10   |      | $\mu s$  |
| PWRGD Threshold                                  |                        | Measured at FBDC_ with respect to unloaded output voltage  | Lower threshold, falling edge (undervoltage) | -350 | -300 | -250 | V        |
|  |                        | 15mV hysteresis (typ)  | Upper threshold, rising edge (overvoltage)   | +150 | +200 | +250 |          |
| PWRGD Propagation Delay                          | $t_{PWRGD\_}$          | FBDC_ forced 25mV outside the PWRGD trip thresholds  |  |      | 10   |      | $\mu s$  |
| PWRGD Output Low Voltage                         |                        | $I_{SINK} = 4mA$   |  |      |      | 0.4  | V        |
| PWRGD Leakage Current                            | $I_{PWRGD\_}$          | High state, PWRGD forced to 5.5V   |  |      |      | 1    | $\mu A$  |
| PWRGD Startup Delay and Transition Blanking Time | $t_{BLANK}$            | Measured from the time when FBDC_ reaches the target voltage based on the slew rate set by RTIME |  |      | 20   |      | $\mu s$  |
| $\overline{VRHOT}$ Trip Threshold                |                        | Measured at THRM, with respect to $V_{CC}$ , falling edge, 115mV hysteresis (typ)                |  | 29.5 | 30   | 30.5 | %        |
| $\overline{VRHOT}$ Delay                         | $t_{\overline{VRHOT}}$ | THRM forced 25mV below the $\overline{VRHOT}$ trip threshold, falling edge                       |  |      | 10   |      | $\mu s$  |
| $\overline{VRHOT}$ Output Low Voltage            |                        | $I_{SINK} = 4mA$   |  |      |      | 0.4  | V        |
| $\overline{VRHOT}$ Leakage Current               |                        | High state, $\overline{VRHOT}$ forced to 5V  |  |      |      | 1    | $\mu A$  |
| THRM Input Leakage                               |                        |  |  | -100 |      | +100 | nA       |
| Thermal-Shutdown Threshold                       | $T_{SHDN}$             | Hysteresis = 15°C  |  |      | 160  |      | °C       |
| <b>GATE DRIVERS</b>                              |                        |  |  |      |      |      |          |
| DH_ Gate-Driver On-Resistance                    | $R_{ON(DH\_)}$         | BST_ - LX_ forced to 5V  | High state (pullup)                          |      | 0.9  | 2.0  | $\Omega$ |
|  |                        |  | Low state (pulldown)                         |      | 0.7  | 2.0  |          |
| DL_ Gate-Driver On-Resistance                    | $R_{ON(DL\_)}$         | DL_, high state  |  |      | 0.7  | 2.0  | $\Omega$ |
|  |                        | DL_, low state   |  |      | 0.25 | 0.6  |          |
| DH_ Gate-Driver Source/Sink Current              | $I_{DH\_}$             | DH_ forced to 2.5V, BST_ - LX_ forced to 5V  |  |      | 2.2  |      | A        |
| DL_ Gate-Driver Source Current                   | $I_{DL\_}$ (SOURCE)    | DL_ forced to 2.5V   |  |      | 2.7  |      | A        |
| DL_ Gate-Driver Sink Current                     | $I_{DL\_}$ (SINK)      | DL_ forced to 2.5V   |  |      | 8    |      | A        |
| Dead Time  | $t_{DH\_DL}$           | DH_ low to DL_ high  |  | 15   | 25   | 40   | ns       |
|  | $t_{DL\_DH}$           | DL_ low to DH_ high  |  | 9    | 20   | 35   |          |
| Internal Boost Diode Switch $R_{ON}$             |                        | BST1 to $V_{DD1}$ , BST2 to $V_{DD2}$ ; measure with 10mA of current                             |  |      | 10   | 20   | $\Omega$ |

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## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 2,  $V_{IN} = 12V$ ,  $V_{CC} = V_{DD1} = V_{DD2} = \overline{SHDN} = PGD\_IN = 5V$ ,  $V_{DDIO} = 1.8V$ ,  $\overline{PRO} = OPTION = GND\_NB = GND\_ = GND\_$ ,  $FBDC\_ = FBAC\_ = CSP\_ = CSN\_ = 1.2V$ , all DAC codes set to the 1.2V code,  $T_A = 0^{\circ}C$  to  $+85^{\circ}C$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

| PARAMETER                               | SYMBOL                          | CONDITIONS   | MIN                   | TYP            | MAX                   | UNITS   |
|---|---------------------------------|--|-----------------------|----------------|-----------------------|---------|
| <b>2-WIRE SVI BUS LOGIC INTERFACE</b>   |                                 |  |                       |                |                       |         |
| SVI Logic Input Current                 |                                 | SVC, SVD   | -1                    |                | +1                    | $\mu A$ |
| SVI Logic Input Threshold               |                                 | SVC, SVD, rising edge, hysteresis = $0.15V_{DDIO}$   | $0.3 \times V_{DDIO}$ |                | $0.7 \times V_{DDIO}$ | V       |
| SVC Clock Frequency                     | f <sub>SVC</sub>                |  |                       |                | 3.4                   | MHz     |
| START Condition Hold Time               | t <sub>HD,STA</sub>             |  | 160                   |                |                       | ns      |
| Repeated START Condition Setup Time     | t <sub>SU,STA</sub>             |  | 160                   |                |                       | ns      |
| STOP Condition Setup Time               | t <sub>SU,STO</sub>             |  | 160                   |                |                       | ns      |
| Data Hold                               | t <sub>HD,DAT</sub>             | A master device must internally provide a hold time of at least 300ns for the SDA signal (referred to the $V_{IL}$ of SCK signal) to bridge the undefined region of SCL's falling edge |                       |                | 70                    | ns      |
| Data Setup Time                         | t <sub>SU,DAT</sub>             |  | 10                    |                |                       | ns      |
| SVC Low Period                          | t <sub>LOW</sub>                |  | 160                   |                |                       | ns      |
| SVC High Period                         | t <sub>HIGH</sub>               |  | 60                    |                |                       | ns      |
| SVC/SVD Rise and Fall Time              | t <sub>R</sub> , t <sub>F</sub> | Measured from 10% to 90% of $V_{DDIO}$   |                       |                | 40                    | ns      |
| Pulse Width of Spike Suppression        |                                 | Input filters on SVD and SVC suppress noise spikes less than 50ns  |                       | 20             |                       | ns      |
| <b>INPUTS AND OUTPUTS</b>               |                                 |  |                       |                |                       |         |
| Logic Input Current                     |                                 | $\overline{SHDN}$ , PGD_IN   | -1                    |                | +1                    | $\mu A$ |
|   |                                 | $\overline{PRO}$ , OPTION  | -3                    |                | +3                    |         |
| Logic Input Threshold                   |                                 | $\overline{SHDN}$ , rising edge, hysteresis = 225mV  | 0.8                   |                | 2.0                   | V       |
| Four-Level Input-Logic Levels           |                                 | OPTION   | High                  | $V_{CC} - 0.4$ |                       | V       |
|   |                                 |  | Open                  | 3.15           | 3.85                  |         |
|   |                                 |  | REF                   | 1.65           | 2.35                  |         |
|   |                                 |  | Low                   |                | 0.4                   |         |
| Tri-Level Input-Logic Levels            |                                 | $\overline{PRO}$   | High                  | $V_{CC} - 0.4$ |                       | V       |
|   |                                 |  | Open                  | 3.15           | 3.85                  |         |
|   |                                 |  | Low                   |                | 0.4                   |         |
| PGD_IN Logic Input Threshold            |                                 | PGD_IN   | $0.3 \times V_{DDIO}$ |                | $0.7 \times V_{DDIO}$ | V       |
| $\overline{NBSKP}$ Logic Output Voltage |                                 | Low state, I <sub>SINK</sub> = 3mA   |                       |                | 0.4                   | V       |
|   |                                 | High state, I <sub>SOURCE</sub> = 3mA  | $V_{CC} - 0.4$        |                |                       |         |

# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

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## ELECTRICAL CHARACTERISTICS

(Circuit of Figure 2,  $V_{IN} = 12V$ ,  $V_{CC} = V_{DD1} = V_{DD2} = \overline{SHDN} = PGD\_IN = 5V$ ,  $V_{DDIO} = 1.8V$ ,  $\overline{PRO} = OPTION = GNDS\_NB = GNDS\_ = GND\_$ ,  $FBDC\_ = FBAC\_ = CSP\_ = CSN\_ = 1.2V$ , all DAC codes set to the 1.2V code,  $T_A = -40^{\circ}C$  to  $+105^{\circ}C$ , unless otherwise noted.) (Note 2)

| PARAMETER   | SYMBOL                | CONDITIONS   | MIN   | MAX  | UNITS   |   |
|---|-----------------------|--|---|------|---------|---|
| <b>INPUT SUPPLIES</b>                               |                       |  |   |      |         |   |
| Input Voltage Range                                 | $V_{IN}$              | Drain of external high-side MOSFET   | 4   | 26   | V       |   |
|   | $V_{BIAS}$            | $V_{CC}$ , $V_{DD1}$ , $V_{DD2}$   | 4.5   | 5.5  |         |   |
|   | $V_{DDIO}$            |  | 1.0   | 2.7  |         |   |
| $V_{CC}$ Undervoltage-Lockout Threshold             | $V_{UVLO}$            | $V_{CC}$ rising 50mV typical hysteresis  | 4.10  | 4.45 | V       |   |
| $V_{DDIO}$ Undervoltage-Lockout Threshold           |                       | $V_{DDIO}$ rising 100mV typical hysteresis   | 0.8   | 0.9  | V       |   |
| Quiescent Supply Current ( $V_{CC}$ )               | $I_{CC}$              | Skip mode, $FBDC\_$ forced above their regulation points   |   | 10   | mA      |   |
| Quiescent Supply Currents ( $V_{DD1}$ , $V_{DD2}$ ) | $I_{DD1}$ , $I_{DD2}$ | Skip mode, $FBDC\_$ forced above their regulation points, $T_A = -40^{\circ}C$ to $+85^{\circ}C$   |   | 1    | $\mu A$ |   |
| Quiescent Supply Current ( $V_{DDIO}$ )             | $I_{DDIO}$            |  |   | 25   | $\mu A$ |   |
| Shutdown Supply Current ( $V_{CC}$ )                |                       | $\overline{SHDN} = GND$ , $T_A = -40^{\circ}C$ to $+85^{\circ}C$   |   | 1    | $\mu A$ |   |
| Shutdown Supply Currents ( $V_{DD1}$ , $V_{DD2}$ )  |                       | $\overline{SHDN} = GND$ , $T_A = -40^{\circ}C$ to $+85^{\circ}C$   |   | 1    | $\mu A$ |   |
| Shutdown Supply Current ( $V_{DDIO}$ )              |                       | $T_A = -40^{\circ}C$ to $+85^{\circ}C$   |   | 1    | $\mu A$ |   |
| Reference Voltage                                   | $V_{REF}$             | $V_{CC} = 4.5V$ to $5.5V$ , no REF load  | 1.98  | 2.02 | V       |   |
| Reference Load Regulation                           |                       | Sourcing: $I_{REF} = 0$ to $500\mu A$  | -2  |      | mV      |   |
|   |                       | Sinking: $I_{REF} = 0$ to $-100\mu A$  |   | 6.2  |         |   |
| <b>MAIN SMPS CONTROLLERS</b>                        |                       |  |   |      |         |   |
| DC Output-Voltage Accuracy (Note 1)                 | $V_{OUT}$             | DAC codes from 0.8375V to 1.5500V  | -0.6  | +0.6 | %       |   |
|   |                       | DAC codes from 0.5000V to 0.8250V  | -6  | +6   | mV      |   |
|   |                       | DAC codes from 0.4875V to 0.0125V  | -15   | +15  |         |   |
| $GNDS\_$ Input Range                                | $V_{GNDS\_}$          | Separate mode  | -200  | +200 | mV      |   |
| $GNDS\_$ Gain                                       | $A_{GNDS\_}$          | Separate: $\Delta V_{OUT\_}/\Delta V_{GNDS\_}$ , $-200mV \leq V_{GNDS\_} \leq +200mV$ ,<br>Combined: $\Delta V_{OUT\_}/\Delta V_{GNDS1}$ , $-200mV \leq V_{GNDS1} \leq +200mV$ | 0.95  | 1.05 | V/V     |   |
| Combined-Mode Detection Threshold                   |                       | $GNDS2$ , detection after REFOK, latched, cleared by cycling $\overline{SHDN}$   | 0.7   | 0.9  | V       |   |
| Switching-Frequency Accuracy                        | $f_{OSC}$             | $R_{OSC} = 143k\Omega$ ( $f_{OSC} = 300kHz$ nominal)   | -7.5  | +7.5 | %       |   |
|   |                       | $R_{OSC} = 35.7k\Omega$ ( $f_{OSC} = 1.2MHz$ nominal) to $432k\Omega$ ( $f_{OSC} = 99kHz$ nominal)   | -10   | +10  |         |   |
| Maximum Duty Factor                                 | $DMAX$                |  | 90  |      | %       |   |
| Minimum On-Time                                     | $t_{ONMIN}$           |  |   | 185  | ns      |   |
| TIME Slew-Rate Accuracy                             |                       | During transition  | $R_{TIME} = 143k\Omega$ , $SR = 6.25mV/\mu s$                                 | -10  | +10     | % |
|   |                       |  | $R_{TIME} = 35.7k\Omega$ to $357k\Omega$ , $SR = 25mV/\mu s$ to $2.5mV/\mu s$ | -15  | +15     |   |



# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 2,  $V_{IN} = 12V$ ,  $V_{CC} = V_{DD1} = V_{DD2} = \overline{SHDN} = PGD\_IN = 5V$ ,  $V_{DDIO} = 1.8V$ ,  $\overline{PRO} = OPTION = GNDS\_NB = GNDS\_ = GND\_$ ,  $FBDC\_ = FBAC\_ = CSP\_ = CSN\_ = 1.2V$ , all DAC codes set to the 1.2V code,  $T_A = -40^{\circ}C$  to  $+105^{\circ}C$ , unless otherwise noted.) (Note 2)

| PARAMETER   | SYMBOL          | CONDITIONS  | MIN  | MAX            | UNITS |   |
|---|-----------------|---|--|----------------|-------|---|
| <b>CURRENT LIMIT</b>  |                 |   |  |                |       |   |
| Current-Limit Threshold Tolerance   | $V_{LIMIT}$     | $V_{CSP\_} - V_{CSN\_} = 0.05 \times (V_{REF} - V_{ILIM})$ ,<br>$(V_{REF} - V_{ILM}) = 0.2V$ to $1.0V$  | -3   | +3             | mV    |   |
| Idle Mode Threshold Tolerance   | $V_{IDLE}$      | $V_{CSP\_} - V_{CSN\_}$ , SKIP mode, $0.15 \times V_{LIMIT}$  | -1.5   | +1.5           | mV    |   |
| CS_ Common-Mode Input Range   |                 | CSP_ and CSN_   | 0  | 2              | V     |   |
| Phase Disable Threshold   |                 | CSP2  | 3  | $V_{CC} - 0.4$ | V     |   |
| <b>DROOP AND CURRENT BALANCE</b>  |                 |   |  |                |       |   |
| DC Droop Amplifier Transconductance   | $G_{m(FBDC\_)}$ | $\Delta I_{FBDC\_} / (\Delta V_{CS\_})$ ,<br>$V_{FBDC\_} = V_{CSN\_} = 1.2V$ ,<br>$V_{CSP\_} - V_{CSN\_} = -60mV$ to $+60mV$                                    | 0.97   | 1.03           | mS    |   |
| DC Droop Amplifier Offset   |                 | $I_{FBDC\_} / G_{m(FBDC\_)}$  | -1.5   | +1.5           | mV    |   |
| AC Droop and Current-Balance Amplifier Transconductance   | $G_{m(FBAC\_)}$ | $\Delta I_{FBAC\_} / (\Delta V_{CS\_})$ ,<br>$V_{FBAC\_} = V_{CSN\_} = 1.2V$ ,<br>$V_{CSP\_} - V_{CSN\_} = -60mV$ to $+60mV$                                    | 0.97   | 1.03           | mS    |   |
| AC Droop and Current-Balance Amplifier Offset   |                 | $I_{FBAC\_} / G_{m(FBAC\_)}$  | -1.5   | +1.5           | mV    |   |
| Transient-Detection Threshold   |                 | Measured at FBDC_ with respect to steady-state<br>FBDC_ regulation voltage,<br>5mV hysteresis (typ),<br>transient phase repeat enabled,<br>OPTION = OPEN or GND | -32  | -18            | mV    |   |
| <b>NB BUFFER</b>  |                 |   |  |                |       |   |
| NBV_BUF Output-Voltage Accuracy   | $V_{NBV\_BUF}$  | DAC codes from 0.8375V to 1.5500V   | -0.6   | +0.6           | %     |   |
|   |                 | DAC codes from 0.5000V to 0.8250V   | -6   | +6             | mV    |   |
|   |                 | DAC codes from 0.4875V to 0.0125V   | -15  | +15            | mV    |   |
| NBV_BUF Short-Circuit Current (Sets Slew Rate Together with External Capacitor $C_{NBV\_BUF}$ ) |                 | DAC code set to 1.2V, $V_{NBV\_BUF} = 0.4V$ and 2V  | $R_{TIME} = 143k\Omega$ ,<br>$I_{NBV\_BUF} = 7.0\mu A$                               | -10            | +10   | % |
|   |                 |   | $R_{TIME} = 35.7k\Omega$ to $357k\Omega$ ,<br>$I_{NBV\_BUF} = 28\mu A$ to $2.8\mu A$ | -15            | +15   |   |
| GNDS_NB Input Range   | $V_{GNDS\_NB}$  |   | -200   | +200           | mV    |   |
| GNDS_NB Gain  | $A_{GNDS\_NB}$  | $\Delta V_{NBV\_BUF} / \Delta V_{GNDS\_NB}$ ,<br>$-200mV \leq V_{GNDS\_NB} \leq +200mV$   | 0.95   | 1.05           | V/V   |   |



# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

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## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 2,  $V_{IN} = 12V$ ,  $V_{CC} = V_{DD1} = V_{DD2} = \overline{SHDN} = PGD\_IN = 5V$ ,  $V_{DDIO} = 1.8V$ ,  $\overline{PRO} = OPTION = GNDS\_NB = GNDS\_ = GND\_$ ,  $FBDC\_ = FBAC\_ = CSP\_ = CSN\_ = 1.2V$ , all DAC codes set to the 1.2V code,  $T_A = -40^{\circ}C$  to  $+105^{\circ}C$ , unless otherwise noted.) (Note 2)

| PARAMETER                                     | SYMBOL         | CONDITIONS   |  | MIN                   | MAX                   | UNITS    |
|---|----------------|--|--|-----------------------|-----------------------|----------|
| <b>FAULT DETECTION</b>                        |                |  |  |                       |                       |          |
| Output Overvoltage Trip Threshold             | $V_{OVP\_}$    | Measured at FBDC_, rising edge   | Normal operation                             | 250                   | 350                   | mV       |
| Output Undervoltage-Protection Trip Threshold | $V_{UVP}$      | Measured at FBDC_ with respect to unloaded output voltage  |  | -450                  | -350                  | mV       |
| PWRGD Threshold                               |                | Measured at FBDC_ with respect to unloaded output voltage  | Lower threshold, falling edge (undervoltage) | -350                  | -250                  | V        |
|   |                | 15mV hysteresis (typ)  | Upper threshold, rising edge (overvoltage)   | +150                  | +250                  |          |
| PWRGD Output Low Voltage                      |                | $I_{SINK} = 4mA$   |  |                       | 0.4                   | V        |
| $\overline{VRHOT}$ Trip Threshold             |                | Measured at THRM, with respect to $V_{CC}$ , falling edge, 115mV hysteresis (typ)  |  | 29.5                  | 30.5                  | %        |
| $\overline{VRHOT}$ Output Low Voltage         |                | $I_{SINK} = 4mA$   |  |                       | 0.4                   | V        |
| <b>GATE DRIVERS</b>                           |                |  |  |                       |                       |          |
| DH_ Gate-Driver On-Resistance                 | $R_{ON(DH\_)}$ | BST_ - LX_ forced to 5V  | High state (pullup)                          |                       | 2.0                   | $\Omega$ |
|   |                |  | Low state (pulldown)                         |                       | 2.0                   |          |
| DL_ Gate-Driver On-Resistance                 | $R_{ON(DL\_)}$ | DL_, high state  |  |                       | 2.0                   | $\Omega$ |
|   |                | DL_, low state   |  |                       | 0.6                   |          |
| Dead Time                                     | $t_{DH\_DL}$   | DH_ low to DL_ high  |  | 15                    | 40                    | ns       |
|   | $t_{DL\_DH}$   | DL_ low to DH_ high  |  | 9                     | 40                    |          |
| Internal Boost Diode Switch $R_{ON}$          |                | BST1 to $V_{DD1}$ , BST2 to $V_{DD2}$ , measured with 10mA of current  |  |                       | 20                    | $\Omega$ |
| <b>2-WIRE SVI BUS LOGIC INTERFACE</b>         |                |  |  |                       |                       |          |
| SVI Logic Input Threshold                     |                | SVC, SVD, rising edge, hysteresis = $0.15 \times V_{DDIO}$   |  | $0.3 \times V_{DDIO}$ | $0.7 \times V_{DDIO}$ | V        |
| SVC Clock Frequency                           | $f_{SVC}$      |  |  |                       | 3.4                   | MHz      |
| START Condition Hold Time                     | $t_{HD,STA}$   |  |  | 160                   |                       | ns       |
| Repeated START Condition Setup Time           | $t_{SU,STA}$   |  |  | 160                   |                       | ns       |
| STOP Condition Setup Time                     | $t_{SU,STO}$   |  |  | 160                   |                       | ns       |
| Data Hold                                     | $t_{HD,DAT}$   | A master device must internally provide a hold time of at least 300ns for the SDA signal (referred to the $V_{IL}$ of SCK signal) to bridge the undefined region of SCL's falling edge |  |                       | 70                    | ns       |
| Data Setup Time                               | $t_{SU,DAT}$   |  |  | 10                    |                       | ns       |
| SVC Low Period                                | $t_{LOW}$      |  |  | 160                   |                       | ns       |
| SVC High Period                               | $t_{HIGH}$     |  |  | 60                    |                       | ns       |
| SVC/SVD Rise and Fall Time                    | $t_R, t_F$     | Measured from 10% to 90% of $V_{DDIO}$   |  |                       | 40                    | ns       |

# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

## ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 2,  $V_{IN} = 12V$ ,  $V_{CC} = V_{DD1} = V_{DD2} = \overline{SHDN} = PGD\_IN = 5V$ ,  $V_{DDIO} = 1.8V$ ,  $\overline{PRO} = OPTION = GNDS\_NB = GNDS\_ = GND\_$ ,  $FBDC\_ = FBAC\_ = CSP\_ = CSN\_ = 1.2V$ , all DAC codes set to the 1.2V code,  $T_A = -40^{\circ}C$  to  $+105^{\circ}C$ , unless otherwise noted.) (Note 2)

| PARAMETER                     | SYMBOL | CONDITIONS  | MIN                   | MAX                   | UNITS |      |
|-------------------------------|--------|---|-----------------------|-----------------------|-------|------|
| <b>INPUTS AND OUTPUTS</b>     |        |   |                       |                       |       |      |
| Logic Input Threshold         |        | $\overline{SHDN}$ , rising edge, hysteresis = 225mV | 0.8                   | 2.0                   | V     |      |
| Four-Level Input Logic Levels |        | OPTION  | High                  | $V_{CC} - 0.4$        | V     |      |
|                               |        |   | Open                  | 3.15                  |       | 3.85 |
|                               |        |   | REF                   | 1.65                  |       | 2.35 |
|                               |        |   | Low                   |                       |       | 0.4  |
| Tri-Level Input Logic Levels  |        | $\overline{PRO}$                                    | High                  | $V_{CC} - 0.4$        | V     |      |
|                               |        |   | Open                  | 3.15                  |       | 3.85 |
|                               |        |   | Low                   |                       |       | 0.4  |
| PGD_IN Logic Input Threshold  |        | PGD_IN  | $0.3 \times V_{DDIO}$ | $0.7 \times V_{DDIO}$ | V     |      |

**Note 1:** When the inductor is in continuous conduction, the output voltage has a DC regulation level lower than the error comparator threshold by 50% of the ripple. In discontinuous conduction, the output voltage will have a DC regulation level higher than the error comparator threshold by 50% of the ripple.

**Note 2:** Specifications to  $T_A = -40^{\circ}C$  to  $+105^{\circ}C$  are guaranteed by design, not production tested.

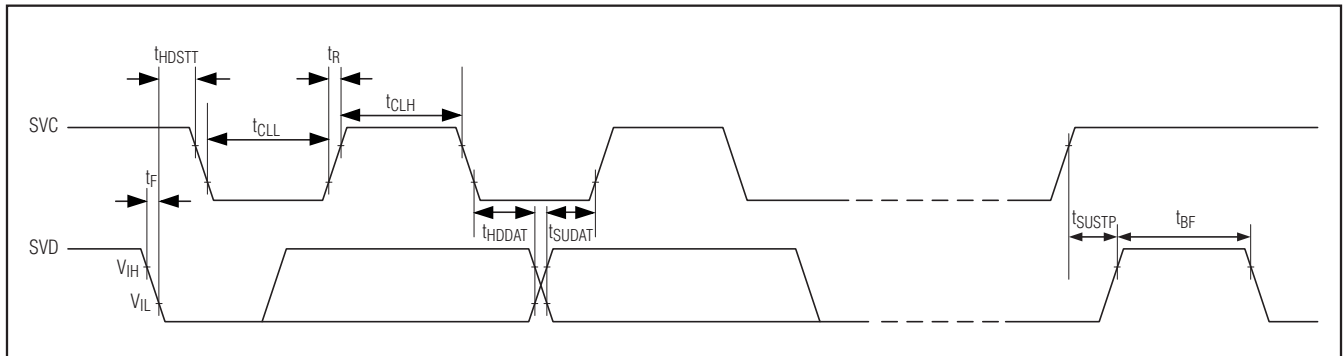


Figure 1. Timing Definitions Used in the Electrical Characteristics

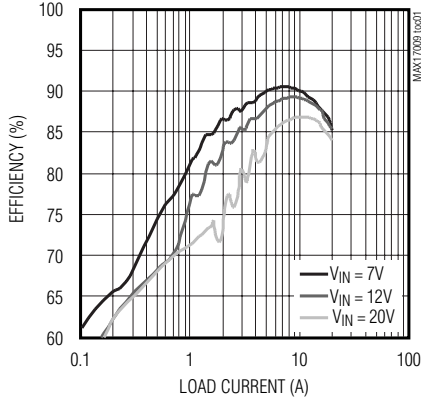
# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

## Typical Operating Characteristics

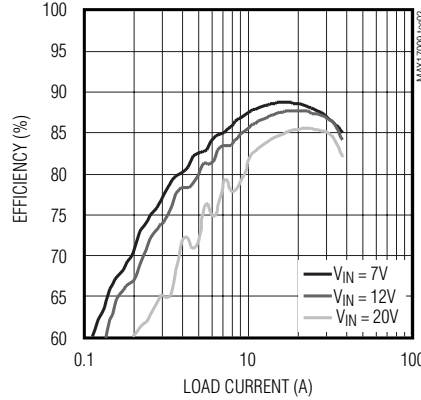
(Circuit of Figure 2,  $V_{IN} = 12V$ ,  $V_{DD} = V_{CC} = 5V$ ,  $V_{DDIO} = 2.5V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

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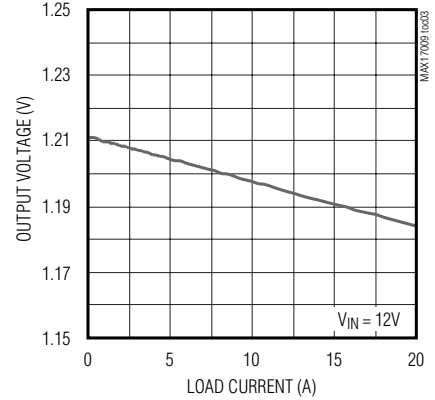
**1-PHASE EFFICIENCY vs. LOAD CURRENT**  
( $V_{OUT} = 1.2125V$ )



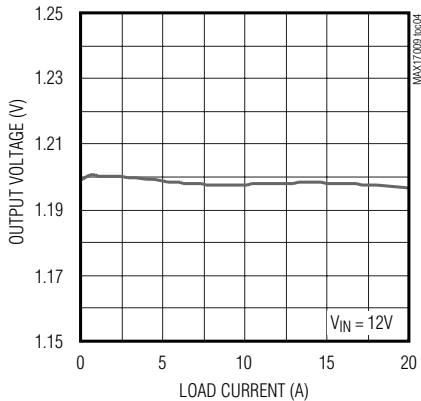
**2-PHASE EFFICIENCY vs. LOAD CURRENT**  
( $V_{OUT} = 1.2125V$ )



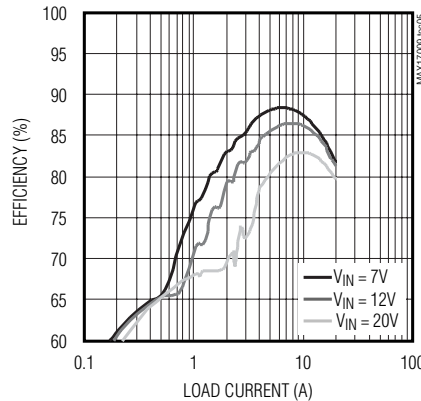
**1-PHASE OUTPUT VOLTAGE vs. LOAD CURRENT**  
( $V_{OUT} = 1.2125V$ ,  $-1.2mV/A$  DROOP)



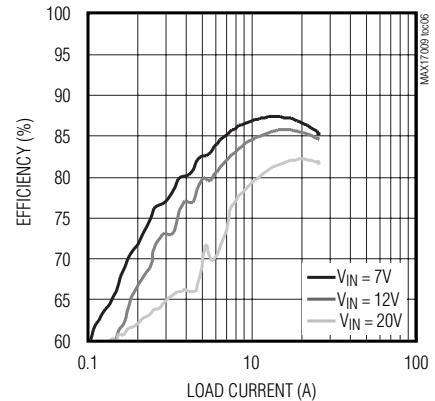
**1-PHASE OUTPUT VOLTAGE vs. LOAD CURRENT**  
( $V_{OUT} = 1.2000V$ , NO DROOP)



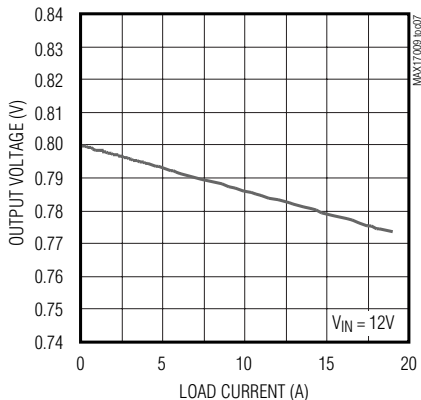
**1-PHASE EFFICIENCY vs. LOAD CURRENT**  
( $V_{OUT} = 0.8000V$ )



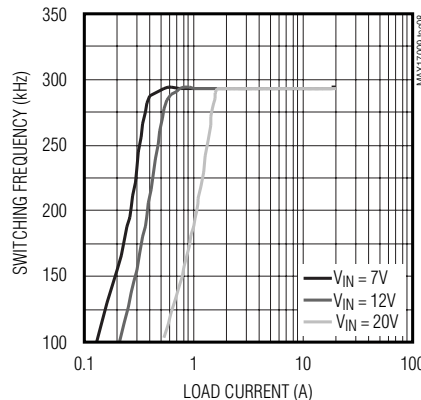
**2-PHASE EFFICIENCY vs. LOAD CURRENT**  
( $V_{OUT} = 0.8000V$ )



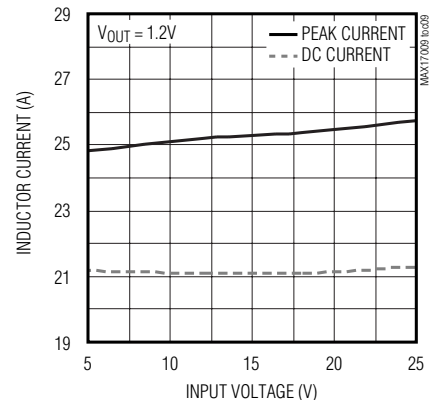
**1-PHASE OUTPUT VOLTAGE vs. LOAD CURRENT**  
( $V_{OUT} = 0.8000V$ ,  $-1.2mV/A$  DROOP)



**1-PHASE SWITCHING FREQUENCY vs. LOAD CURRENT**



**MAXIMUM INDUCTOR CURRENT vs. INPUT VOLTAGE**

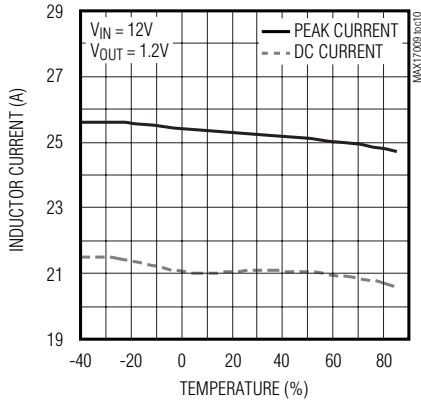


# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

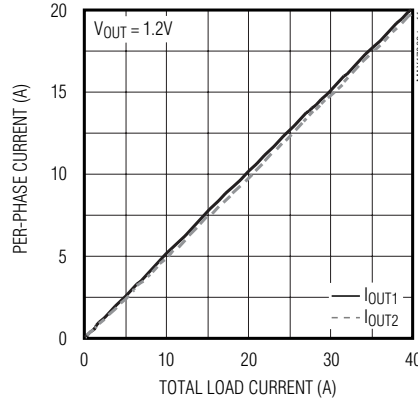
## Typical Operating Characteristics (continued)

(Circuit of Figure 2,  $V_{IN} = 12V$ ,  $V_{DD} = V_{CC} = 5V$ ,  $V_{DDIO} = 2.5V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

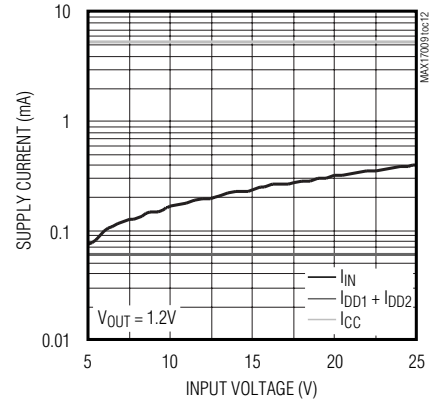
**MAXIMUM INDUCTOR CURRENT vs. TEMPERATURE**



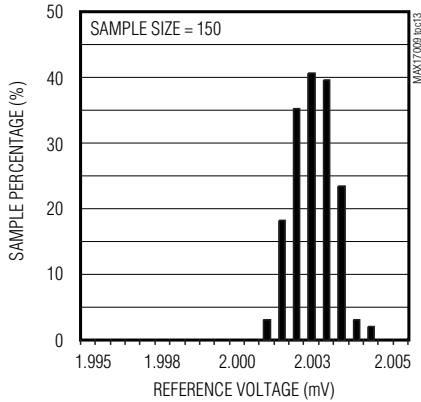
**CURRENT BALANCE vs. LOAD CURRENT**



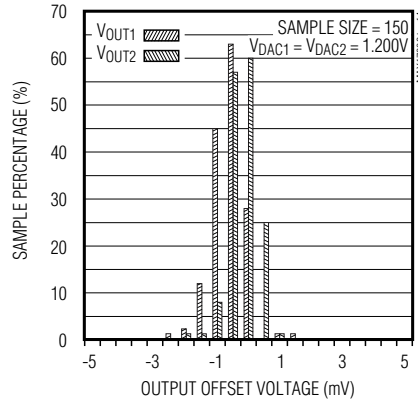
**NO-LOAD SUPPLY CURRENT vs. INPUT VOLTAGE**



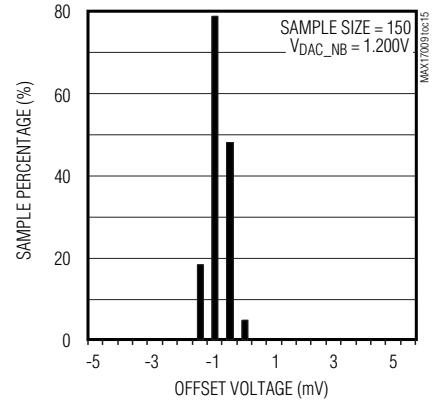
**REFERENCE VOLTAGE DISTRIBUTION**



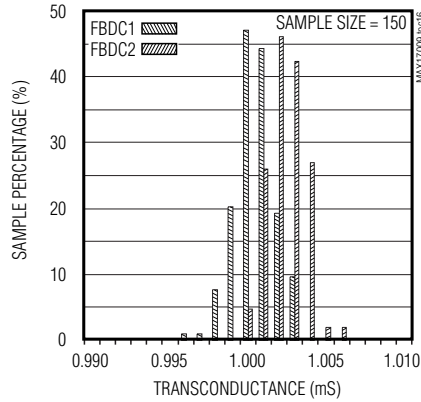
**SMPS OUTPUT OFFSET VOLTAGE DISTRIBUTION**



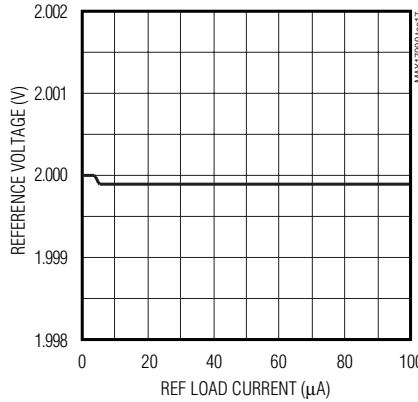
**NBV\_BUF OFFSET VOLTAGE DISTRIBUTION**



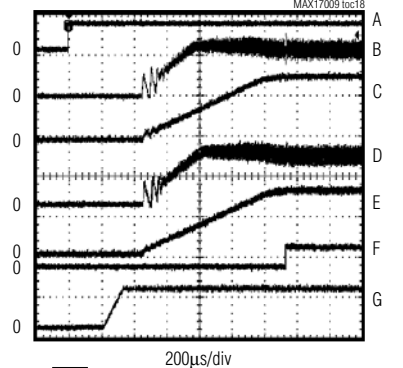
**FBDC TRANSCONDUCTANCE DISTRIBUTION**



**REFERENCE VOLTAGE vs. LOAD CURRENT**



**STARTUP WAVEFORMS (HEAVY LOAD)**



$V_{IN} = 12V$ ,  $V_{BOOT} = 0.8V$ ,  $I_{LOAD1} = I_{LOAD2} = 12A$

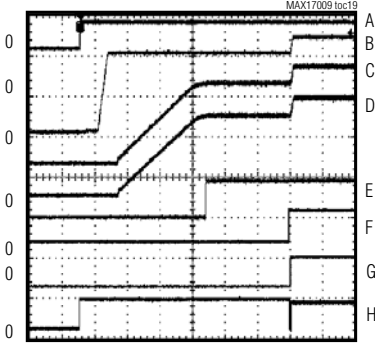
# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

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## Typical Operating Characteristics (continued)

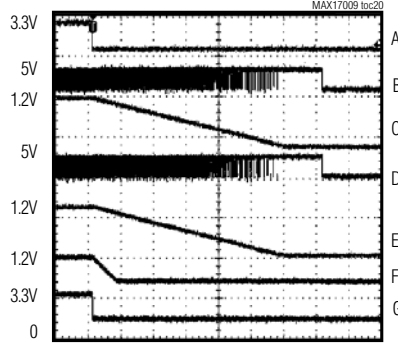
(Circuit of Figure 2,  $V_{IN} = 12V$ ,  $V_{DD} = V_{CC} = 5V$ ,  $V_{DDIO} = 2.5V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

### STARTUP SEQUENCE WAVEFORMS



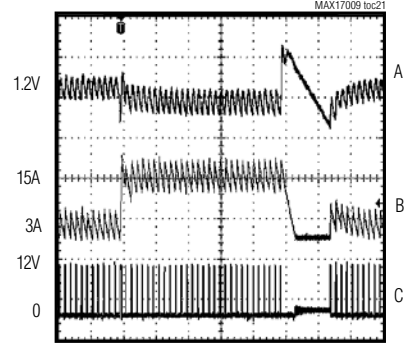
A. SHDN, 5V/div  
B. VNBV\_BUF, 0.5V/div  
C. VOUT1, 0.5V/div  
D. VOUT2, 0.5V/div  
E. PWRGD, 3.3V/div  
F. PGD\_IN, 3.3V/div  
G. SVC, 2V/div  
H. SVD, 2V/div  
 $V_{IN} = 12V$ ,  $V_{BOOT} = 1.0V$ ,  $I_{LOAD1} = I_{LOAD2} = 3A$

### SHUTDOWN WAVEFORMS



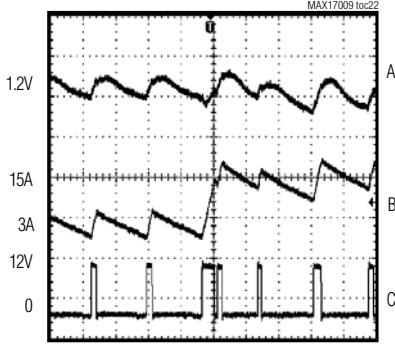
A. SHDN, 5V/div  
B. DL1, 10V/div  
C. VOUT1, 0.5V/div  
D. DL2, 10V/div  
E. VOUT2, 0.5V/div  
F. VNBV\_BUF, 2V/div  
G. PWRGD, 5V/div  
 $V_{IN} = 12V$ ,  $I_{LOAD1} = I_{LOAD2} = 3A$

### 1-PHASE LOAD TRANSIENT (-1.2mV/A DROOP)



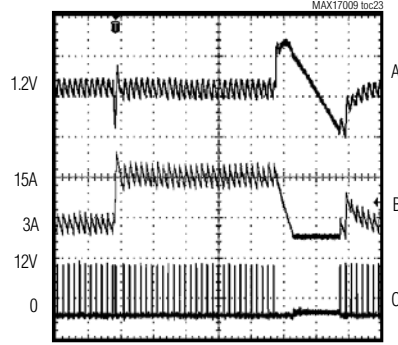
A. VOUT1, 50mV/div  
B. ILX1, 10A/div  
C. LX1, 10V/div  
 $V_{IN} = 12V$   
 $I_{LOAD1} = 3A$  TO 15A TO 3A

### 1-PHASE TRANSIENT PHASE REPEAT (-1.2mV/A DROOP)



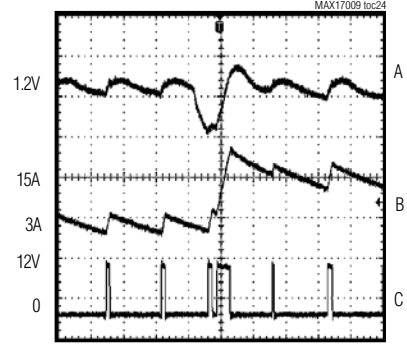
A. VOUT1, 50mV/div  
B. ILX1, 10A/div  
C. LX1, 10V/div  
 $V_{IN} = 12V$   
 $I_{LOAD1} = 3A$  TO 15A TO 3A

### 1-PHASE LOAD TRANSIENT (NO DROOP)



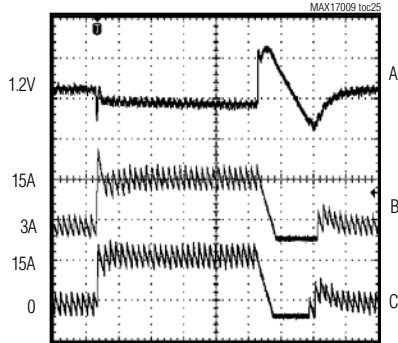
A. VOUT1, 50mV/div  
B. ILX1, 10A/div  
C. LX1, 10V/div  
 $V_{IN} = 12V$   
 $I_{LOAD1} = 3A$  TO 15A TO 3A

### 1-PHASE TRANSIENT PHASE REPEAT (NO DROOP)



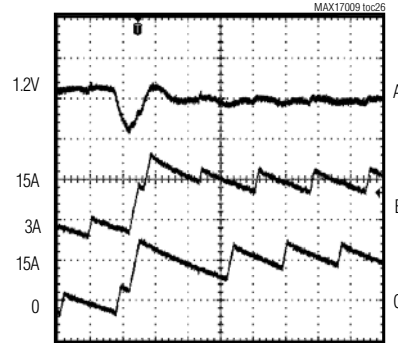
A. VOUT1, 50mV/div  
B. ILX1, 10A/div  
C. LX1, 10V/div  
 $V_{IN} = 12V$   
 $I_{LOAD1} = 3A$  TO 15A TO 3A

### 2-PHASE LOAD TRANSIENT (-1.2mV/A DROOP)



A. VOUT1, 50mV/div  
B. ILX1, 10A/div  
C. ILX2, 10A/div  
 $V_{IN} = 12V$   
 $I_{LOAD} = 6A$  TO 30A TO 6A

### 2-PHASE TRANSIENT PHASE REPEAT (-1.2mV/A DROOP)



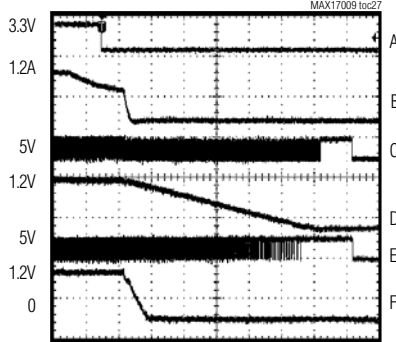
A. VOUT1, 50mV/div  
B. ILX1, 10A/div  
C. ILX2, 10A/div  
 $V_{IN} = 12V$   
 $I_{LOAD} = 6A$  TO 30A TO 6A

# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

## Typical Operating Characteristics (continued)

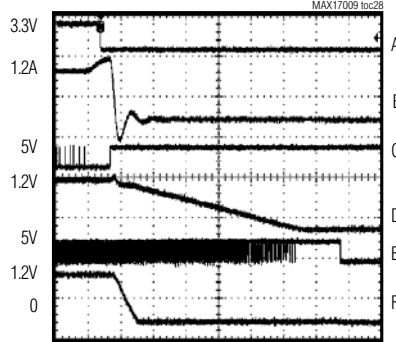
(Circuit of Figure 2,  $V_{IN} = 12V$ ,  $V_{DD} = V_{CC} = 5V$ ,  $V_{DDIO} = 2.5V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

**1-PHASE OUTPUT OVERLOAD**



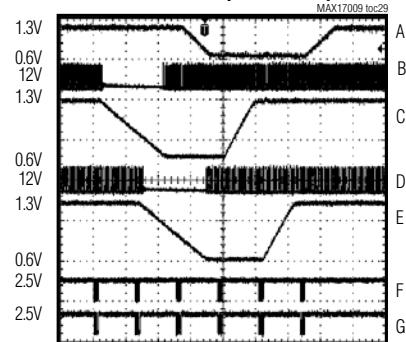
200 $\mu$ s/div  
 A. PWRGD, 5V/div D.  $V_{OUT2}$ , 1V/div  
 B.  $V_{OUT1}$ , 1V/div E. DL2, 10V/div  
 C. DL1, 10V/div F.  $V_{NBV\_BUF}$ , 1V/div  
 $V_{IN} = 12V$ ,  $I_{LOAD1} = 3A$  TO  $30A$ ,  $I_{LOAD2} = 3A$

**1-PHASE OUTPUT OVERVOLTAGE**



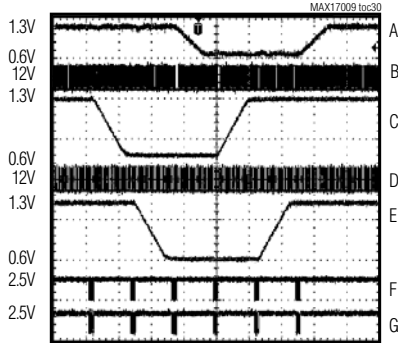
200 $\mu$ s/div  
 A. PWRGD, 5V/div D.  $V_{OUT2}$ , 1V/div  
 B.  $V_{OUT1}$ , 1V/div E. DL2, 10V/div  
 C. DL1, 10V/div F.  $V_{NBV\_BUF}$ , 1V/div  
 $V_{IN} = 12V$ ,  $I_{LOAD1} = 50mA$ ,  $I_{LOAD2} = 3A$

**DYNAMIC OUTPUT-VOLTAGE TRANSITIONS (LIGHT LOAD)**



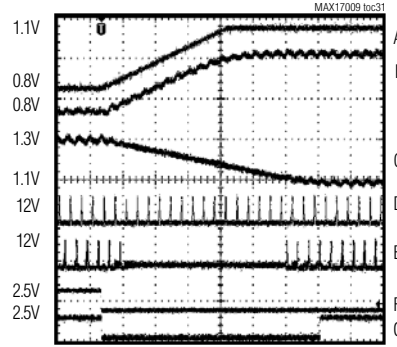
100 $\mu$ s/div  
 A.  $V_{NBV\_BUF}$ , 1V/div E.  $V_{OUT2}$ , 0.5V/div  
 B. LX1, 20V/div F. SVC, 5V/div  
 C.  $V_{OUT1}$ , 0.5V/div G. SVD, 5V/div  
 D. LX2, 20V/div  
 $V_{IN} = 12V$ ,  $V_{DACS} = 1.3V$  TO  $0.6V$  TO  $1.3V$ ,  
 $I_{LOAD1} = I_{LOAD2} = 3A$

**DYNAMIC OUTPUT-VOLTAGE TRANSITIONS (HEAVY LOAD)**



100 $\mu$ s/div  
 A.  $V_{NBV\_BUF}$ , 1V/div E.  $V_{OUT2}$ , 0.5V/div  
 B. LX1, 20V/div F. SVC, 5V/div  
 C.  $V_{OUT1}$ , 0.5V/div G. SVD, 5V/div  
 D. LX2, 20V/div  
 $V_{IN} = 12V$ ,  $V_{DACS} = 1.3V$  TO  $0.6V$  TO  $1.3V$ ,  
 $I_{LOAD1} = I_{LOAD2} = 10A$

**PGD\_IN FALLING TRANSITIONS**



10 $\mu$ s/div  
 A.  $V_{NBV\_BUF}$ , 200mV/div E. LX2, 20V/div  
 B.  $V_{OUT1}$ , 200mV/div F. PGD\_IN, 5V/div  
 C.  $V_{OUT2}$ , 200mV/div G. PWRGD, 5V/div  
 D. LX1, 20V/div  
 $V_{IN} = 12V$ ,  $V_{BOOT} = 1.1V$ ,  $V_{DAC1} = 0.8V$ ,  $V_{DAC2} = 1.3V$ ,  
 $V_{NBV\_BUF} = 0.8V$ ,  $I_{LOAD1} = I_{LOAD2} = 3A$

# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

## Pin Description

MAX17009

| PIN | NAME                     | FUNCTION  |   |     |   |   |   |   |     |     |   |   |     |     |   |   |     |     |   |   |     |     |
|-----|--------------------------|---|---|-----|---|---|---|---|-----|-----|---|---|-----|-----|---|---|-----|-----|---|---|-----|-----|
| 1   | PWRGD                    | <p>Open-Drain, Power-Good Output. PWRGD indicates when both SMPSs are in regulation. PWRGD is forced high impedance whenever the slew-rate controller is active (output-voltage transitions). After output-voltage transitions, except during power-up and power-down, if FBDC_ is in regulation, then PWRGD is high impedance.</p> <p>During startup, PWRGD is held low an additional 20μs after the MAX17009 reaches the startup boot voltage set by the SVC, SVD pins. The MAX17009 stores the boot VID when PWRGD first goes high. The stored boot VID is cleared by rising <math>\overline{\text{SHDN}}</math>.</p> <p>PWRGD is forced low in shutdown.</p> <p>When in pulse-skipping mode, the upper PWRGD threshold comparator is blanked during a lower VID transition. The upper PWRGD threshold comparator is reenabled once the output is in regulation (Figure 4).</p>  |   |     |   |   |   |   |     |     |   |   |     |     |   |   |     |     |   |   |     |     |
| 2   | NBV_BUF                  | <p>North Bridge Buffered Reference Voltage. This output is connected to the REFIN input of the NB controller (switcher or LDO) to set the NB regulator voltage. The NBV_BUF output current is set by the TIME resistor. The NBV_BUF current and the total output capacitance set the NBV_BUF slew rate:</p> $I_{\text{NBV\_BUF}} = (7\mu\text{A}) \times (143\text{k}\Omega / R_{\text{TIME}})$ $\text{NBV\_BUF Slew rate} = I_{\text{NBV\_BUF}} / C_{\text{NBV\_BUF}}$ <p><math>I_{\text{NBV\_BUF}}</math> is the same during startup, shutdown, and any VID transition.</p> <p>Bypass to GND with a 100pF minimum low-ESR (ceramic) capacitor at the NBV_BUF pin.</p>   |   |     |   |   |   |   |     |     |   |   |     |     |   |   |     |     |   |   |     |     |
| 3   | $\overline{\text{SHDN}}$ | <p>Shutdown Control Input. Connect high (2V to <math>V_{\text{CC}}</math>) for normal operation. Connect to ground to put the IC into its 1μA max shutdown state.</p> <p>During startup, the SMPS output voltages and the NBV_BUF voltage are ramped up to the voltage set by the SVC, SVD inputs. The SMPSs start up and shut down at a fixed slew rate of 1mV/μs.</p> <table border="1"> <thead> <tr> <th>SVC</th> <th>SVD</th> <th>BOOT VOLTAGE (<math>V_{\text{BOOT}}</math>)<br/>(<math>\overline{\text{PRO}} = V_{\text{CC}}</math> OR GND)</th> <th>BOOT VOLTAGE (<math>V_{\text{BOOT}}</math>)<br/>(<math>\overline{\text{PRO}} = \text{OPEN}</math>)</th> </tr> </thead> <tbody> <tr> <td>0</td> <td>0</td> <td>1.1</td> <td>1.1</td> </tr> <tr> <td>0</td> <td>1</td> <td>1.0</td> <td>1.2</td> </tr> <tr> <td>1</td> <td>0</td> <td>0.9</td> <td>1.0</td> </tr> <tr> <td>1</td> <td>1</td> <td>0.8</td> <td>0.8</td> </tr> </tbody> </table> <p>The MAX17009 stores the boot VID when PWRGD first goes high. The stored boot VID is cleared by rising <math>\overline{\text{SHDN}}</math>.</p> | SVC   | SVD | BOOT VOLTAGE ( $V_{\text{BOOT}}$ )<br>( $\overline{\text{PRO}} = V_{\text{CC}}$ OR GND) | BOOT VOLTAGE ( $V_{\text{BOOT}}$ )<br>( $\overline{\text{PRO}} = \text{OPEN}$ ) | 0 | 0 | 1.1 | 1.1 | 0 | 1 | 1.0 | 1.2 | 1 | 0 | 0.9 | 1.0 | 1 | 1 | 0.8 | 0.8 |
| SVC | SVD                      | BOOT VOLTAGE ( $V_{\text{BOOT}}$ )<br>( $\overline{\text{PRO}} = V_{\text{CC}}$ OR GND)   | BOOT VOLTAGE ( $V_{\text{BOOT}}$ )<br>( $\overline{\text{PRO}} = \text{OPEN}$ ) |     |   |   |   |   |     |     |   |   |     |     |   |   |     |     |   |   |     |     |
| 0   | 0                        | 1.1   | 1.1   |     |   |   |   |   |     |     |   |   |     |     |   |   |     |     |   |   |     |     |
| 0   | 1                        | 1.0   | 1.2   |     |   |   |   |   |     |     |   |   |     |     |   |   |     |     |   |   |     |     |
| 1   | 0                        | 0.9   | 1.0   |     |   |   |   |   |     |     |   |   |     |     |   |   |     |     |   |   |     |     |
| 1   | 1                        | 0.8   | 0.8   |     |   |   |   |   |     |     |   |   |     |     |   |   |     |     |   |   |     |     |
| 4   | REF                      | <p>2.0V Reference Output. Bypass to GND with a 1μF maximum low-ESR (ceramic) capacitor. REF sources up to 500μA for external loads. Loading REF degrades output accuracy, according to the REF load-regulation error.</p>   |   |     |   |   |   |   |     |     |   |   |     |     |   |   |     |     |   |   |     |     |
| 5   | ILIM                     | <p>Current-Limit Adjust Input. The positive current-limit threshold voltage is precisely 1/20 of the voltage between REF and ILIM over a 0.2V to 1.0V range of <math>V(\text{REF}, \text{ILIM})</math>. The <math>I_{\text{MIN}}</math> minimum current-limit threshold voltage in skip mode is precisely 15% of the corresponding positive current-limit threshold voltage.</p>  |   |     |   |   |   |   |     |     |   |   |     |     |   |   |     |     |   |   |     |     |
| 6   | OSC                      | <p>Oscillator Adjustment Input. Connect a resistor (<math>R_{\text{OSC}}</math>) between OSC and GND to set the switching frequency (per phase):</p> $f_{\text{OSC}} = 300\text{kHz} \times 143\text{k}\Omega / R_{\text{OSC}}$ <p>A 35.7kΩ to 432kΩ corresponds to switching frequencies of 1.2MHz to 100kHz, respectively. Switching-frequency selection is limited by the minimum on-time. See the Switching frequency bullet in the <i>SMPS Design Procedure</i> section.</p>   |   |     |   |   |   |   |     |     |   |   |     |     |   |   |     |     |   |   |     |     |



# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

## Pin Description (continued)

| PIN | NAME    | FUNCTION  |
|-----|---------|---|
| 7   | TIME    | <p>Slew-Rate Adjustment Pin. Connect a resistor <math>R_{TIME}</math> from TIME to GND to set the internal slew rate:</p> $\text{PWM Slew rate} = (6.25\text{mV}/\mu\text{s}) \times (143\text{k}\Omega / R_{TIME})$ $\text{NBV\_BUF Slew rate} = (7\mu\text{A}) \times (143\text{k}\Omega / R_{TIME}) / C_{NBV\_BUF}$ <p>where <math>R_{TIME}</math> is between <math>35.7\text{k}\Omega</math> and <math>357\text{k}\Omega</math> for corresponding slew rates between <math>25\text{mV}/\mu\text{s}</math> to <math>2.5\text{mV}/\mu\text{s}</math>, respectively, for the SMPSs, and NBV_BUF currents between <math>28\mu\text{A}</math> and <math>2.8\mu\text{A}</math>, respectively, for the NBV_BUF.</p> <p>This slew rate applies to both upward and downward VID transitions, and to the transition from boot mode to VID mode. Downward VID transition slew rate can appear slower because the output transition is not forced by the SMPS.</p> <p>The SMPS slew rate for startup and shutdown is fixed at <math>1\text{mV}/\mu\text{s}</math>.</p> <p>The NBV_BUF slew rate is the same during startup, shutdown, and normal VID transitions.</p>   |
| 8   | SVC     | Serial VID Clock. During the power-up sequence and in debug mode, SVC is the MSB of the 2-bit VID DAC.  |
| 9   | SVD     | Serial VID Data. During the power-up sequence and in debug mode, SVD is the LSB of the 2-bit VID DAC.   |
| 10  | THRM    | Input of Internal Comparator. Connect the output of a resistor- and thermistor-divider (between $V_{CC}$ and GND) to THRM. Select the components so the voltage at THRM falls below $1.5\text{V}$ (30% of $V_{CC}$ ) at the desired high temperature.   |
| 11  | GNDS2   | SMPS2 Remote Ground-Sense Input. Normally connected to GND directly at the load. GNDS2 internally connects to a transconductance amplifier that fine tunes the output voltage compensating for voltage drops from the regulator ground to the load ground.<br>Connect GNDS2 above $0.9\text{V}$ combined-mode operation (unified core). When operating in combined mode, GNDS1 is used as the remote ground-sense input.  |
| 12  | FBDC2   | <p>Output of the DC Voltage-Positioning Transconductance Amplifier for SMPS2. Connect a resistor <math>R_{FBDC2}</math> between FBDC2 and the positive side of the feedback remote sense to set the DC steady-state droop based on the voltage-positioning gain requirement:</p> $R_{FBDC2} = R_{DROOPDC} / (R_{SENSE2} \times G_m(\text{FBDC2}))$ <p>where <math>R_{DROOPDC}</math> is the desired voltage positioning slope and <math>G_m(\text{FBDC2}) = 1\text{mS}</math> typ. <math>R_{SENSE2}</math> is the value of the current-sense resistor that is used to provide the (CSP2, CSN2) current-sense voltage.<br/>To disable the load-line, short FBDC2 to the positive remote-sense point.<br/>FBDC2 is high impedance in shutdown.</p>  |
| 13  | FBAC2   | <p>Output of the AC Voltage-Positioning Transconductance Amplifier for SMPS2. The resistance between this pin and the positive side of the remote-sensed output voltage sets the transient AC droop:</p> $R_{FBAC2} = R_{DROOPAC} / (R_{SENSE2} \times G_m(\text{FBAC2}))$ <p>where <math>R_{DROOPAC}</math> is the transient (AC) voltage-positioning slope that provides an acceptable tradeoff between stability and load transient response, <math>G_m(\text{FBAC2})</math> and <math>R_{SENSE2}</math> is the value of the current-sense resistor that is used to provide the (CSP2, CSN2) current-sense voltage.<br/>The maximum difference between transient (AC) droop and DC droop should not exceed <math>\pm 80\text{mV}</math> at the maximum allowed load current (DC droop is set at the FBDC2 pin).<br/>Internally, <math>V(\text{FBDC2} - \text{GNDS2})</math> goes to the internal voltage integrator (slow DC loop), whereas <math>V(\text{FBAC2} - \text{GNDS2})</math> goes to the error comparator (fast transient loop).<br/>FBAC2 is high impedance in shutdown.<br/><b>Note:</b> The AC and DC droop cannot be different by more than <math>\pm 3\text{mV}/\text{A}</math>.</p> |
| 14  | VDDIO   | CPU I/O Voltage ( $1.8\text{V}$ or $1.5\text{V}$ ). Logic thresholds for SVD and SVC are relative to the voltage at VDDIO.  |
| 15  | GNDS_NB | North Bridge Feedback Remote-Sense Input, Negative Side. Normally connected to GND directly at the load. GNDS_NB internally connects to a transconductance amplifier that fine tunes the NBV_BUF output voltage compensating for voltage drops from the regulator ground to the load ground.  |

# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

## Pin Description (continued)

MAX17009

| PIN | NAME                      | FUNCTION  |
|-----|---------------------------|---|
| 16  | CSN2                      | Negative Current-Sense Input for SMPS2. Connect to the negative side of the output current-sensing resistor or the filtering capacitor if the DC resistance of the output inductor is utilized for current sensing.   |
| 17  | CSP2                      | Positive Current-Sense Input for SMPS2. Connect to the positive side of the output current-sensing resistor or the filtering capacitor if the DC resistance of the output inductor is utilized for current sensing. Connect CSP2 to V <sub>CC</sub> to disable SMPS2. This allows the MAX17009 to operate as a 1-phase regulator.   |
| 18  | V <sub>CC</sub>           | Controller Supply Voltage. Connect to a 4.5V to 5.5V source. Bypass to GND with 1μF minimum. A V <sub>CC</sub> UVLO event that occurs while the IC is functioning is latched, and can only be cleared by cycling V <sub>CC</sub> power or by toggling $\overline{\text{SHDN}}$ .  |
| 19  | $\overline{\text{NBSKP}}$ | North Bridge Skip Push-Pull Control Output. When $\overline{\text{NBSKP}}$ is high, the NB switching regulator is set to forced-PWM mode. When $\overline{\text{NBSKP}}$ is low, the NB switching regulator is set to pulse-skipping mode. The $\overline{\text{NBSKP}}$ level is set through the serial interface during normal operation. $\overline{\text{NBSKP}}$ is high in shutdown and during soft-shutdown. $\overline{\text{NBSKP}}$ is high in startup until commanded otherwise. |
| 20  | DH2                       | SMPS2 High-Side, Gate-Driver Output. DH2 swings from LX2 to BST2. Low in shutdown.  |
| 21  | LX2                       | SMPS2 Inductor Connection. LX2 is the internal lower supply rail for the DH2 high-side gate driver. Also used as an input to phase 2's zero-crossing comparator.  |
| 22  | BST2                      | Boost Flying-Capacitor Connection for the DH2 High-Side Gate Driver. An internal switch between V <sub>DD2</sub> and BST2 charges the flying capacitor during the time the low-side FET is on.  |
| 23  | V <sub>DD2</sub>          | Supply Voltage Input for the DL2 Driver. V <sub>DD2</sub> is also the supply voltage used to internally recharge the BST2 flying capacitor during the off-time of phase 2. Connect V <sub>DD2</sub> to the 4.5V to 5.5V system supply voltage. Bypass V <sub>DD2</sub> to GND with a 1μF or greater ceramic capacitor.  |
| 24  | DL2                       | SMPS2 Low-Side Gate-Driver Output. DL2 swings from GND2 to V <sub>DD2</sub> . DL2 is forced low in shutdown. DL2 is also forced high when an output overvoltage fault is detected. DL2 is forced low in skip mode after an inductor current zero crossing (GND2 - LX2) is detected.   |
| 25  | GND2                      | Power Ground for SMPS2. Ground connection for the DL2 driver. Also used as an input to SMPS2's zero-crossing comparator. GND1 and GND2 are internally connected.  |
| 26  | GND1                      | Power Ground for SMPS1. Ground connection for the DL1 driver. Also used as an input to SMPS1's zero-crossing comparator. GND1 and GND2 are internally connected.  |
| 27  | DL1                       | SMPS1 Low-Side, Gate-Driver Output. DL1 swings from GND1 to V <sub>DD1</sub> . DL1 is forced low in shutdown. DL1 is also forced high when an output overvoltage fault is detected. DL1 is forced low in skip mode after an inductor current zero crossing (GND1 - LX1) is detected.  |
| 28  | V <sub>DD1</sub>          | Supply Voltage Input for the DL1 Driver. V <sub>DD1</sub> is also the supply voltage used to internally recharge the BST1 flying capacitor during the off-time of phase 1. Connect V <sub>DD1</sub> to the 4.5V to 5.5V system supply voltage. Bypass V <sub>DD1</sub> to GND with a 1μF or greater ceramic capacitor.  |
| 29  | BST1                      | Boost Flying-Capacitor Connection for the DH1 High-Side Gate Driver. An internal switch between V <sub>DD1</sub> and BST1 charges the flying capacitor during the time the low-side FET is on.  |
| 30  | LX1                       | SMPS1 Inductor Connection. LX1 is the internal lower supply rail for the DH1 high-side gate driver. Also used as an input to phase 1's zero-crossing comparator.  |
| 31  | DH1                       | SMPS1 High-Side, Gate-Driver Output. DH1 swings from LX1 to BST1. Low in shutdown.  |
| 32  | $\overline{\text{VRHOT}}$ | Open-Drain Output of Internal Comparator. $\overline{\text{VRHOT}}$ is pulled low when the voltage at THRM goes below 1.5V (30% of V <sub>CC</sub> ). $\overline{\text{VRHOT}}$ is high impedance in shutdown.  |

# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

## Pin Description (continued)

| PIN             | NAME                    | FUNCTION   |        |                |                                |                 |   |   |      |   |   |     |   |   |     |   |   |
|-----------------|-------------------------|--|--------|----------------|--------------------------------|-----------------|---|---|------|---|---|-----|---|---|-----|---|---|
| 33              | $\overline{\text{PRO}}$ | Protection Disable. $\overline{\text{PRO}}$ also sets the MAX17009 in debug mode.<br>Connect $\overline{\text{PRO}}$ high to disable OVP protection.<br>Connect $\overline{\text{PRO}}$ to GND to enable OVP protection.<br>When $\overline{\text{PRO}}$ is floated, the MAX17009 disables the OVP protection and also enters debug mode (see the $\overline{\text{SHDN}}$ pin description). When PGD_IN is low in debug mode, the MAX17009 DAC voltages are set by the 2-bit boot VID. When PGD_IN is high, the MAX17009 changes to serial VID mode.  |        |                |                                |                 |   |   |      |   |   |     |   |   |     |   |   |
| 34              | CSP1                    | Positive Current-Sense Input for SMPS1. Connect to the positive side of the output current-sensing resistor or the filtering capacitor if the DC resistance of the output inductor is utilized for current sensing.  |        |                |                                |                 |   |   |      |   |   |     |   |   |     |   |   |
| 35              | CSN1                    | Negative Current-Sense Input for SMPS1. Connect to the negative side of the output current-sensing resistor or the filtering capacitor if the DC resistance of the output inductor is utilized for current sensing.  |        |                |                                |                 |   |   |      |   |   |     |   |   |     |   |   |
| 36              | PGD_IN                  | System Power-Good Input. Indicates to the MAX17009 that the system is ready to enter serial VID mode. PGD_IN is low when $\overline{\text{SHDN}}$ first goes high, the MAX17009 decodes the boot VID to determine the boot voltage. The boot VID can be changed dynamically while PGD_IN remains low and PWRGD. The boot VID is stored after PWRGD goes high.<br>PGD_IN goes high after the MAX17009 reaches the boot voltage. This indicates that the SVI block is active, and the MAX17009 starts to respond to the serial-interface commands.<br>After PGD_IN has gone high, if at anytime PGD_IN should go low, the MAX17009 regulates to the previously stored boot VID.  |        |                |                                |                 |   |   |      |   |   |     |   |   |     |   |   |
| 37              | OPTION                  | Four-Level Input to Enable Offset and Transient-Phase Repeat <table border="1" style="margin-left: 20px;"> <thead> <tr> <th>OPTION</th> <th>OFFSET ENABLED</th> <th>TRANSIENT-PHASE REPEAT ENABLED</th> </tr> </thead> <tbody> <tr> <td>V<sub>CC</sub></td> <td>0</td> <td>0</td> </tr> <tr> <td>OPEN</td> <td>0</td> <td>1</td> </tr> <tr> <td>REF</td> <td>1</td> <td>0</td> </tr> <tr> <td>GND</td> <td>1</td> <td>1</td> </tr> </tbody> </table> <p>When OFFSET is enabled, the MAX17009 enables a fixed +12.5mV offset on each of the SMPS VID codes after PGD_IN goes high. This configuration is intended for applications that implement a load-line. An external resistor at FBDC_ sets the load-line. The offset can be disabled by setting the PSI_L1 bit to zero through the serial interface.<br/>When OFFSET is disabled, the intended application has no load-line, and the FBDC_ pins are directly connected to the remote-sense points.<br/>Transient phase repeat allows the MAX17009 to reenable the current phase in response to a load transient, even after that phase has finished its on-pulse.</p>  | OPTION | OFFSET ENABLED | TRANSIENT-PHASE REPEAT ENABLED | V <sub>CC</sub> | 0 | 0 | OPEN | 0 | 1 | REF | 1 | 0 | GND | 1 | 1 |
| OPTION          | OFFSET ENABLED          | TRANSIENT-PHASE REPEAT ENABLED   |        |                |                                |                 |   |   |      |   |   |     |   |   |     |   |   |
| V <sub>CC</sub> | 0                       | 0  |        |                |                                |                 |   |   |      |   |   |     |   |   |     |   |   |
| OPEN            | 0                       | 1  |        |                |                                |                 |   |   |      |   |   |     |   |   |     |   |   |
| REF             | 1                       | 0  |        |                |                                |                 |   |   |      |   |   |     |   |   |     |   |   |
| GND             | 1                       | 1  |        |                |                                |                 |   |   |      |   |   |     |   |   |     |   |   |
| 38              | FBAC1                   | Output of the AC Voltage-Positioning Transconductance Amplifier for SMPS1. The resistance between this pin and the positive side of the remote-sensed output voltage sets the transient AC droop:<br>$R_{\text{FBAC1}} = R_{\text{DROOPAC}} / (R_{\text{SENSE1}} \times G_{\text{m}}(\text{FBAC1}))$ where $R_{\text{DROOPAC}}$ is the transient (AC) voltage-positioning slope that $\overline{\text{PRO}}$ vides an acceptable tradeoff between stability and load-transient response, $G_{\text{m}}(\text{FBAC1})$ and $R_{\text{SENSE1}}$ is the value of the current-sense resistor that is used to $\overline{\text{PRO}}$ vide the (CSP1, CSN1) current-sense voltage.<br>The maximum difference between transient (AC) droop and DC droop should not exceed $\pm 80\text{mV}$ at the maximum allowed load current (DC droop is set at the FBDC2 pin).<br>Internally, V(FBDC1 - GNDS1) goes to the internal voltage integrator (slow DC loop), whereas V(FBAC1 - GNDS1) goes to the error comparator (fast-transient loop).<br>FBAC1 is high impedance in shutdown.<br><b>Note:</b> The AC and DC droop cannot be different by more than $\pm 3\text{mV/A}$ . |        |                |                                |                 |   |   |      |   |   |     |   |   |     |   |   |

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## Pin Description (continued)

MAX17009

| PIN | NAME  | FUNCTION   |
|-----|-------|--|
| 39  | FBDC1 | Output of the DC Voltage-Positioning Transconductance Amplifier for SMPS1. Connect a resistor $R_{FBDC1}$ between FBDC1 and the positive side of the feedback remote sense to set the DC steady-state droop based on the voltage-positioning gain requirement:<br>$R_{FBDC1} = R_{DROOPDC} / (R_{SENSE1} \times G_{m(FBDC1)})$ where $R_{DROOPDC}$ is the desired voltage-positioning slope and $G_{m(FBDC1)} = 1\text{mS typ}$ . $R_{SENSE1}$ is the value of the current-sense resistor that is used to provide the (CSP1, CSN1) current-sense voltage. To disable the load-line, short FBDC2 to the positive remote-sense point. FBDC1 is high impedance in shutdown. |
| 40  | GNDS1 | SMPS1 Remote Ground-Sense Input. Normally connected to GND directly at the load. GNDS1 internally connects to a transconductance amplifier that fine tunes the output voltage compensating for voltage drops from the regulator ground to the load ground. GNDS1 is the remote ground-sense input in combined-mode operation.  |
| EP  | EP    | Exposed Pad. Connect the exposed backside pad to GND1 and GND2.  |

Table 1 shows the component selection for standard applications and Table 2 lists component suppliers.

**Table 1. Component Selection for Standard Applications**

| COMPONENT                                  | $V_{IN} = 7V \text{ TO } 20V$<br>$V_{OUT} = 1.0V - 1.3V / 18A \text{ PER PHASE}$                        | $V_{IN} = 4.5V \text{ TO } 14V$<br>$V_{OUT} = 1.0V - 1.3V / 18A \text{ PER PHASE}$ |
|--|---|--|
| MODE                                       | Separate, 2-phase mobile (GNDS2 not high)   | Separate, 2-phase mobile (GNDS2 not high)  |
| Switching Frequency                        | 280kHz<br>( $R_{OSC} = 154k\Omega$ )  | 600kHz<br>( $R_{OSC} = 71.5k\Omega$ )  |
| $C_{IN\_}$ , Input Capacitor (per Phase)   | (2) 10 $\mu$ F, 25V<br>Taiyo Yuden TMK432BJ106KM  | (2) 10 $\mu$ F, 16V<br>Taiyo Yuden TMK432BJ106KM                                   |
| $C_{OUT\_}$ , Output Capacitor (per Phase) | (2) 470 $\mu$ F, 2V, 6m $\Omega$ , low-ESR capacitor<br>NEC/Tokin PSGD0E477M6 or Panasonic EEFUD0D471L6 | (2) 330 $\mu$ F, 2.5V, 6m $\Omega$ , low-ESR capacitor<br>Panasonic EEFSD0D331XR   |
| $N_{H\_}$ High-Side MOSFET                 | (1) Fairchildsemi<br>FDMS8690   | (1) International Rectifier<br>IRF7811W  |
| $N_{L\_}$ Low-Side MOSFET                  | (2) Vishay<br>Si7336ADP   | (2) Fairchildsemi<br>FDMS8660S   |
| $D_{L\_}$ Schottky Rectifier               | 3A, 40V Schottky diode<br>Central Semiconductor<br>CMSh3-40   | None   |
| $L_{\_}$ Inductor                          | 0.45 $\mu$ H, 30A, 1.1m $\Omega$ power inductor<br>TOKO FDUE1040D-R45M or NEC/Tokin MPC1040LR45         | 0.22 $\mu$ H, 25A, 1m $\Omega$ power inductor<br>NEC/Tokin MPC0730LR20             |

**Note:** Mobile applications should be designed for separate mode operation. Component selection dependent on AMD CPU AC and DC specifications.

# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

Table 2. Component Suppliers

| MANUFACTURER            | WEBSITE                |
|-------------------------|------------------------|
| AVX                     | www.avxcorp.com        |
| BI Technologies         | www.bitechnologies.com |
| Central Semiconductor   | www.centalsemi.com     |
| Fairchild Semiconductor | www.fairchildsemi.com  |
| International Rectifier | www.irf.com            |
| KEMET                   | www.kemet.com          |
| NEC Tokin               | www.nec-tokin.com      |
| Panasonic               | www.panasonic.com      |

| MANUFACTURER       | WEBSITE               |
|--------------------|-----------------------|
| Pulse              | www.pulseeng.com      |
| Renesas            | www.renesas.com       |
| SANYO              | www.secc.co.jp        |
| Siliconix (Vishay) | www.vishay.com        |
| Sumida             | www.sumida.com        |
| Taiyo Yuden        | www.t-yuden.com       |
| TDK                | www.component.tdk.com |
| TOKO               | www.tokoam.com        |

## Standard Application Circuits

The MAX17009 standard application circuit (Figure 2) generates two independent 18A outputs for AMD mobile CPU applications. See Table 1 for component selections. Table 2 lists the component manufacturers.

## Detailed Description

The MAX17009 consists of a dual-fixed-frequency PWM controller that generates the supply voltage for two independent CPU cores. A reference buffer output (NBV\_BUF) sets the regulation voltage for a separate NB regulator. The CPU cores can be configured as independent outputs, or as a combined output based on the GNDS2 pin strap (GNDS2 pulled to 1.5V - 1.8V, which are the respective voltages for DDR3 and DDR2).

Both SMPS outputs and the NB buffer can be programmed to any voltage in the VID table (see Table 4) using the SVI. The CPU is the SVI bus master, while the MAX17009 is the SVI slave. Voltage transitions are commanded by the CPU as a single-step command from one VID code to another. The MAX17009 slews the SMPS outputs at the slew rate programmed by the external R<sub>TIME</sub> resistor. For the NB buffer, the slew rate is set by the combination of R<sub>TIME</sub> and the total capacitance on the output of the buffer.

By default, the MAX17009 SMPSs are always in pulse-skip mode. In separate mode, the PSI\_L bit does not change the mode of operation, but removes the +12.5mV offset, if enabled by the OPTION pin. In combined mode, the PSI\_L bit removes the +12.5mV offset and switches from 2-phase to 1-phase operation. The NB\_SKP output always follows the state of PSI\_L for the NB regulator.

## +5V Bias Supply (V<sub>CC</sub>, V<sub>DD</sub>)

The MAX17009 requires an external 5V bias supply in addition to the battery. Typically, this 5V bias supply is the notebook's main 95%-efficient 5V system supply. Keeping the bias supply external to the IC improves efficiency and eliminates the cost associated with the 5V linear regulator that would otherwise be needed to supply the PWM circuit and gate drivers.

The 5V bias supply powers both the PWM controller and internal gate-drive power, so the maximum current drawn is:

$$I_{BIAS} = I_{CC} + f_{sw}Q_G = 10\text{mA to }60\text{mA (typ)}$$

where  $I_{CC}$  is provided in the *Electrical Characteristics* table, and  $f_{sw}Q_G$  (per phase) is the driver's supply current, as defined in the MOSFET's data sheet. If the +5V bias supply is powered up prior to the battery supply, the enable signal (SHDN going from low to high) must be delayed until the battery voltage is present to ensure startup.

## Switching Frequency (OSC)

Connect a resistor (R<sub>OSC</sub>) between OSC and GND to set the switching frequency (per phase):

$$f_{sw} = 300\text{kHz} \times 143\text{k}\Omega / R_{OSC}$$

A 35.7k $\Omega$  to 432k $\Omega$  corresponds to switching frequencies of 1.2MHz to 100kHz, respectively. High-frequency (1.2MHz) operation optimizes the application for the smallest component size, trading off efficiency due to higher switching losses. This may be acceptable in ultra-portable devices where the load currents are lower and the controller is powered from a lower voltage supply. Low-frequency (100kHz) operation offers the best overall efficiency at the expense of component size and board space. Minimum on-time ( $t_{ON(MIN)}$ ) must also be taken into consideration. See the Switching frequency bullet in the *SMPS Design Procedure* section.

# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

MAX17009

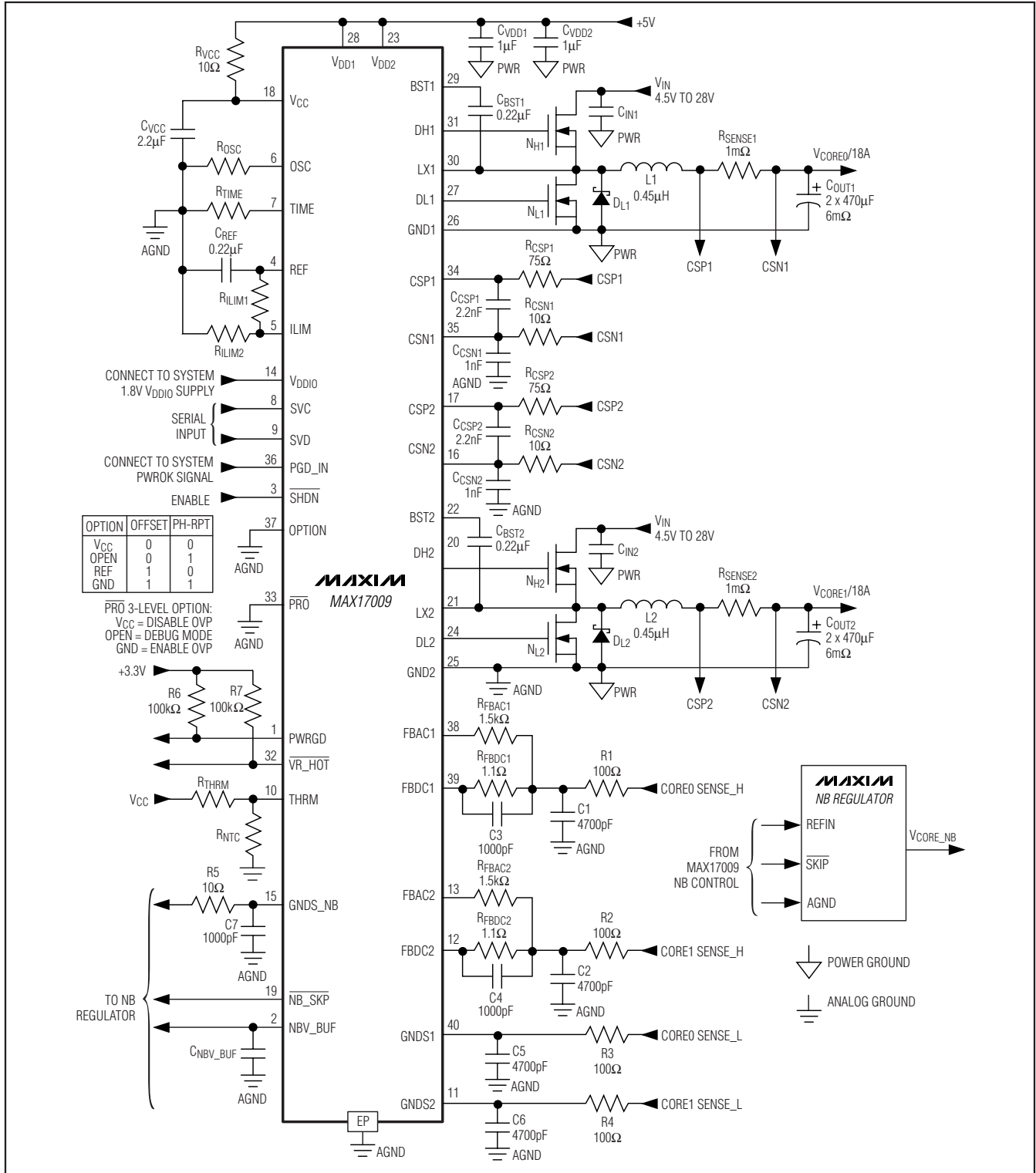


Figure 2. Standard Application Circuit



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## Interleaved Multiphase Operation

The MAX17009 interleaves both phases—resulting in 180° out-of-phase operation that minimizes the input and output filtering requirements, reduces electromagnetic interference (EMI), and improves efficiency. The high-side MOSFETs do not turn on simultaneously during normal operation. The instantaneous input current is effectively reduced by the number of active phases, resulting in reduced input-voltage ripple, ESR power loss, and RMS ripple current (see the *Input-Capacitor Selection* section). Therefore, the controller achieves high performance while minimizing the component count, which reduces cost, saves board space, and lowers component power requirements, making the MAX17009 ideal for high-power, cost-sensitive applications.

## Transient-Phase Repeat

When a transient occurs, the output-voltage deviation depends on the controller's ability to quickly detect the transient and slew the inductor current. A fixed-frequency controller typically responds only when a clock edge occurs, resulting in a delayed transient response. To minimize this delay time, the MAX17009 includes enhanced transient detection and transient-phase-repeat capabilities. If the controller detects that the output voltage has dropped by 25mV, the transient-detection comparator immediately retriggers the phase that completed its on-time last. The controller triggers the subsequent phases as normal on the appropriate oscillator edges. This effectively triggers a phase a full cycle early, increasing the total inductor-current slew rate and providing an immediate transient response.

The OPTION pin setting enables or disables the transient phase-repeat feature. Keep OPTION OPEN or connected to GND to enable transient-phase repeat. Connect OPTION to VCC or REF to disable transient-phase repeat. See the *Offset and Transient-Phase Repeat (OPTION)* section.

## Feedback Adjustment Amplifiers

### Steady-State Voltage-Positioning Amplifier (DC Droop)

Each of the MAX17009 SMPS controllers includes two transconductance amplifiers—one for steady-state DC droop, and another for AC droop. The amplifiers' inputs are generated by summing their respective current-sense inputs, which differentially sense the voltage across either current-sense resistors or the inductor's DCR.

The DC droop amplifier's output (FBDC) connects to the remote-sense point of the output through a resistor that sets each phase's DC voltage-positioning gain:

$$V_{OUT} = V_{TARGET} - R_{FBDC} I_{FBDC}$$

where the target voltage ( $V_{TARGET}$ ) is defined in the *Nominal Output-Voltage Selection* section, and the FBDC amplifier's output current ( $I_{FBDC}$ ) is determined by each phase's current-sense voltage:

$$I_{FBDC} = G_m(FBDC) V_{CS}$$

where  $V_{CS} = V_{CSP} - V_{CSN}$  is the differential current-sense voltage, and  $G_m(FBDC)$  is typically 1mS as defined in the *Electrical Characteristics* table.

DC droop is typically used together with the +12.5mV offset feature to keep within the DC tolerance window of the application. See the *Offset and Transient-Phase Repeat (OPTION)* section. The ripple voltage on FBDC must be less than the 18mV (min) transient phase repeat threshold:

$$\Delta I_L R_{SENSE} G_m(FBDC) R_{FBDC} + \Delta I_L R_{ESR} \leq 18\text{mV}$$

$$R_{FBDC} \leq \left( \frac{18\text{mV}}{\Delta I_L} - R_{ESR} \right) - R_{SENSE} G_m(FBDC)$$

where  $\Delta I_L$  is the inductor ripple current,  $R_{ESR}$  is the effective output ESR at the remote sense point,  $R_{SENSE}$  is the current-sense element, and  $G_m(FBDC)$  is 1.03mS (max) as defined in the *Electrical Characteristics* table. The worst-case inductor ripple occurs at the maximum input voltage and the minimum output-voltage conditions:

$$\Delta I_L(\text{MAX}) = \frac{V_{OUT}(\text{MIN})(V_{IN}(\text{MAX}) - V_{OUT}(\text{MIN}))}{V_{IN}(\text{MAX}) f_{OSC} L}$$

To disable voltage positioning, set  $R_{FBDC}$  to zero.

### Transient Voltage-Positioning Amplifier (AC Droop)

The AC droop amplifier's output (FBAC) connects to the remote-sense point of the output through a resistor that sets each phase's AC voltage-positioning gain:

$$V_{OUT} = V_{TARGET} - R_{FBAC} I_{FBAC}$$

where the target voltage ( $V_{TARGET}$ ) is defined in the *Nominal Output-Voltage Selection* section, and the FBAC amplifier's output current ( $I_{FBAC}$ ) is determined by each phase's current-sense voltage:

$$I_{FBAC} = G_m(FBAC) V_{CS}$$

where  $V_{CS} = V_{CSP} - V_{CSN}$  is the differential current-sense voltage, and  $G_m(FBAC)$  is 1.03mS (max), as defined in the *Electrical Characteristics* table.

AC droop is required for stable operation of the MAX17009. A minimum of 1mV/A is recommended. AC droop must not be disabled.



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The maximum allowable AC droop is limited by the recommended integrator correction range of  $\pm 100\text{mV}$  and on the DC droop:

$$|R_{\text{FBAC}} - R_{\text{FBDC}}| \leq \frac{100\text{mV}}{1.03\text{mS}_{\text{LOAD(MAX)}}R_{\text{SENSE}}}$$

## Differential Remote Sense

The MAX17009 controller includes independent differential, remote-sense inputs for each CPU core to eliminate the effects of voltage drops along the PC board (PCB) traces and through the processor's power pins. The feedback-sense (FBDC\_) input connects to the voltage-positioning resistor (RFBDC\_). The ground-sense (GNDS\_) input connects to an amplifier that adds an offset directly to the target voltage, effectively adjusting the output voltage to counteract the voltage drop in the ground path. Connect the feedback-sense (FBDC\_) voltage-positioning resistor (RFBDC\_), and ground-sense (GNDS\_) input directly to the respective CPU core's remote-sense outputs as shown in Figure 2.

GNDS2 has a dual function. At power-on, the voltage level on GNDS2 configures the MAX17009 as two independent switching regulators, or one higher current two-phase regulator. Keep GNDS2 low during power-up to configure the MAX17009 in separate mode. Connect GNDS2 to a voltage above 0.8V (typ) for combined-mode operation. In the AMD mobile system, this is automatically done by the CPU that is plugged into the socket that pulls GNDS2 to the VDDIO voltage level.

The MAX17009 checks the GNDS2 level at the time when the internal REFOK signal goes high, and latches the operating mode information (separate or combined mode). This latch is cleared by cycling the SHDN pin.

## Integrator Amplifier

An internal integrator amplifier forces the DC average of the FBDC\_ voltage to equal the target voltage. This transconductance amplifier integrates the feedback voltage and provides a fine adjustment to the regulation voltage (Figure 3), allowing accurate DC output-voltage regulation regardless of the output-ripple voltage. The integrator amplifier has the ability to shift the output voltage by  $\pm 100\text{mV}$  (min).

The MAX17009 disables the integrator by connecting the amplifier inputs together at the beginning of all VID transitions done in pulse-skipping mode. The integrator remains disabled until  $20\mu\text{s}$  after the transition is completed (the internal target settles), and the output is in regulation (edge detected on the error comparator).

When voltage positioning is disabled ( $R_{\text{FBDC}} = 0\Omega$ ), the AC droop setting must be less than the  $\pm 100\text{mV}$

minimum adjustment range of the integrator amplifier to guarantee proper DC output-voltage accuracy. See the *Steady State Voltage-Positioning Amplifiers (DC Droop)* and the *Transient Voltage-Positioning Amplifiers (AC Droop)* sections.

## 2-Wire Serial Interface (SVC, SVD)

The MAX17009 supports the 2-wire, write only, serial-interface bus as defined by the AMD Serial VID Interface Specification. The serial interface is similar to the high-speed 3.4MHz I<sup>2</sup>C bus, but without the master mode sequence. The bus consists of a clock line (SVC) and a data line (SVD). The CPU is the bus master, and the MAX17009 is the slave. The MAX17009 serial interface works from 100kHz to 3.4MHz. In the AMD mobile application, the bus runs at 3.4MHz.

The serial interface is active only after PGD\_IN goes high in the startup sequence. The CPU sets the VID voltage of the three internal DACs and the PSI\_L bit through the serial interface.

During the startup sequence, the SVC and SVD inputs serve an alternate function to set the 2-bit boot VID for all three DACs while PWRGD is low. In debug mode, the SVC and SVD inputs function in the 2-bit VID mode when PGD\_IN is low, and in the serial-interface mode when PGD\_IN is high.

## Nominal Output-Voltage Selection

### SMPS Output Voltage

The nominal no-load output voltage ( $V_{\text{TARGET}}$ ) for each SMPS is defined by the selected voltage reference (VID DAC) plus the remote ground-sense adjustment ( $V_{\text{GNDS}}$ ) and the offset voltage ( $V_{\text{OFFSET}}$ ) as defined in the following equation:

$$V_{\text{TARGET}} = V_{\text{FBDC}} = V_{\text{DAC}} + V_{\text{GNDS}} + V_{\text{OFFSET}}$$

where  $V_{\text{DAC}}$  is the selected VID voltage of the SMPS DAC,  $V_{\text{GNDS}}$  is the ground-sense correction voltage, and  $V_{\text{OFFSET}}$  is the +12.5mV offset enabled by the OPTION pin, when the PSI\_L is set high.

### NBV\_BUF Output Voltage

The nominal output voltage ( $V_{\text{TARGET}}$ ) for the NBV\_BUF is defined by the selected voltage reference (VID DAC) plus the remote ground-sense adjustment ( $V_{\text{GNDS}}$ ), as defined in the following equation:

$$V_{\text{TARGET}} = V_{\text{NBV\_BUF}} = V_{\text{DAC}} + V_{\text{GNDS\_NB}}$$

where  $V_{\text{DAC}}$  is the selected VID voltage of the NBV\_BUF DAC, and  $V_{\text{GNDS\_NB}}$  is the ground-sense correction voltage. The offset voltage ( $V_{\text{OFFSET}}$ ) is not applied to NBV\_BUF.

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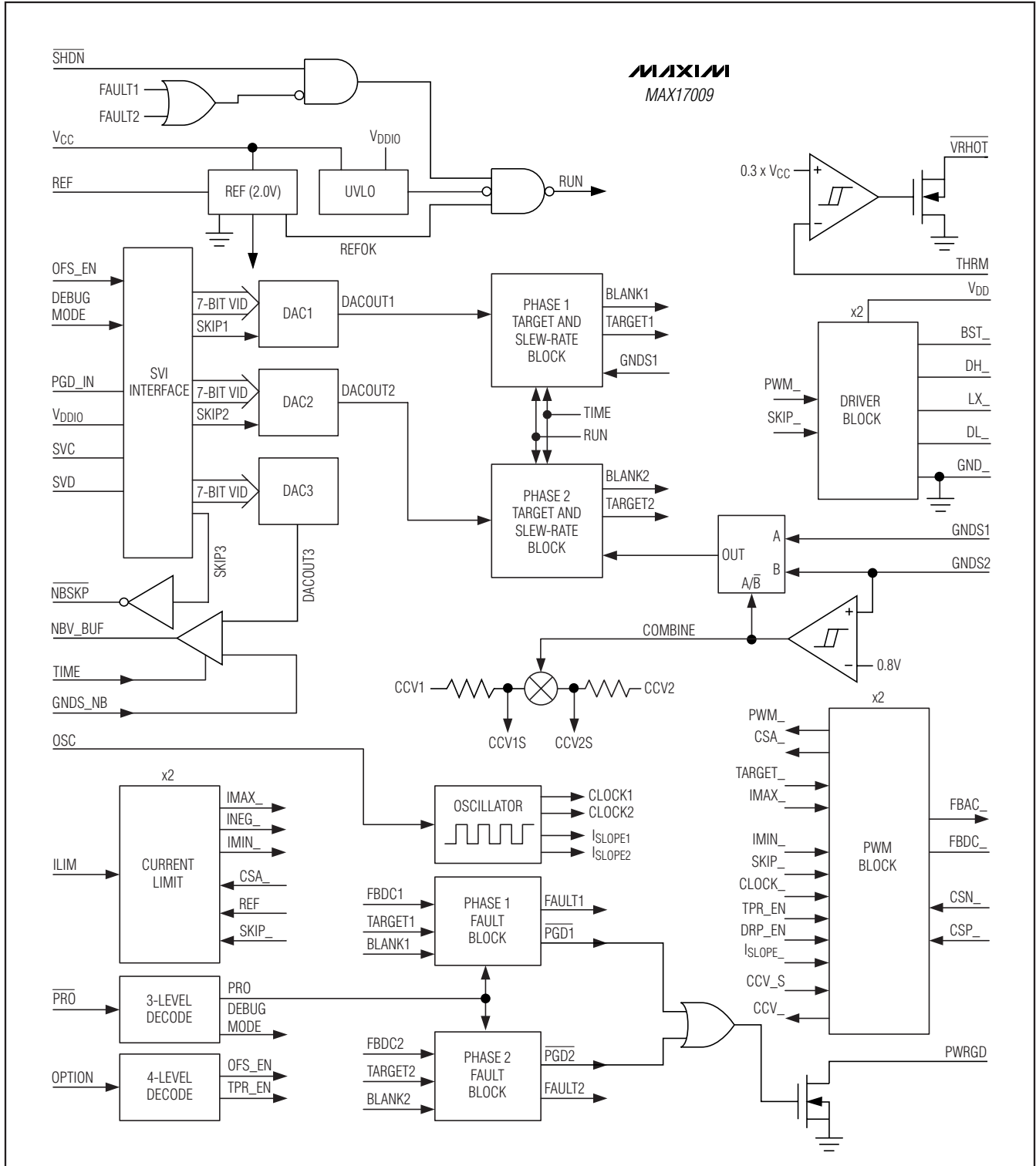


Figure 3. Functional Diagram

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## 7-Bit DAC

Inside the MAX17009 are three 7-bit digital-to-analog converters (DACs). Each DAC can be individually programmed to different voltage levels through the serial-interface bus. The DAC sets the target for the output voltage for the SMPSs and the NB buffer output (NBV\_BUF). The available DAC codes and resulting output voltages are compatible with the AMD SVI (Table 4) specifications

## Boot Voltage

On startup, the MAX17009 slews the target for all three DACs from ground to the boot voltage set by the SVC and SVD pin voltage levels. While the output is still below regulation, the SVC and SVD levels can be changed, and the MAX17009 sets the DACs to the new boot voltage. Once the programmed boot voltage is reached and PWRGD goes high, the MAX17009 stores the boot VID. Changes in the SVC and SVD settings do not change the output voltage once the boot VID is stored. When PGD\_IN goes high, the MAX17009 exits boot mode, and the three DACs can be independently set to any voltage in the VID table through the serial interface.

If PGD\_IN goes from high to low anytime after the boot VID is stored, the MAX17009 sets all three DACs back to the voltage of the stored boot VID.

When in debug mode ( $\overline{\text{PRO}} = \text{OPEN}$ ), the MAX17009 uses a different boot-voltage code set. Keeping PGD\_IN low allows the SVC and SVD inputs to set the three DACs to different voltages in the boot-voltage code table. When PGD\_IN is subsequently set high, the three DACs can be independently set to any voltage in the VID table serial interface. Table 3 shows the boot-voltage code table.

**Table 3. Boot-Voltage Code Table**

| SVC | SVD | BOOT VOLTAGE<br>(V <sub>BOOT</sub> )<br>( $\overline{\text{PRO}} = \text{V}_{\text{CC}}$ OR GND) | BOOT VOLTAGE<br>(V <sub>BOOT</sub> )<br>( $\overline{\text{PRO}} = \text{OPEN}$ ) |
|-----|-----|--|---|
| 0   | 0   | 1.1  | 1.4   |
| 0   | 1   | 1.0  | 1.2   |
| 1   | 0   | 0.9  | 1.0   |
| 1   | 1   | 0.8  | 0.8   |

## Offset

A +12.5mV offset can be added to both SMPS DAC voltages for applications that include DC droop. The offset is applied only after the MAX17009 exits boot mode (PGD\_IN going from low to high), and the MAX17009 enters the serial-interface mode. The offset is disabled when the PSI\_L bit is set, saving more power when the load is light.

The OPTION pin setting enables or disables the +12.5mV offset. Connect OPTION to REF or GND to enable the offset. Keep OPTION open or connected to V<sub>CC</sub> to disable the offset. See the *Offset and Transient-Phase Repeat (OPTION)* section.

## Output-Voltage Transition Timing

### SMPS Output-Voltage Transition

The MAX17009 performs positive voltage transitions in a controlled manner, automatically minimizing input surge currents. This feature allows the circuit designer to achieve nearly ideal transitions, guaranteeing just-in-time arrival at the new output voltage level with the lowest possible peak currents for a given output capacitance. The slew rate (set by resistor R<sub>TIME</sub>) must be set fast enough to ensure that 35.7k $\Omega$  and 357k $\Omega$  for corresponding slew rates between 25mV/ $\mu$ s to 2.5mV/ $\mu$ s, respectively, for the SMPSs.

At the beginning of an output-voltage transition, the MAX17009 blanks both PWRGD comparator thresholds, preventing the PWRGD open-drain output from changing states during the transition. At the end of an upward VID transition, the controller enables both PWRGD thresholds approximately 20 $\mu$ s after the slew-rate controller reaches the target output voltage. At the end of a downward VID transition, the upper PWRGD threshold is enabled only after the output reaches the lower VID code setting.

The MAX17009 automatically controls the current to the minimum level required to complete the transition in the calculated time. The slew-rate controller uses an internal capacitor and current source programmed by R<sub>TIME</sub> to transition the output voltage. The total transition time depends on R<sub>TIME</sub>, the voltage difference, and the accuracy of the slew-rate controller (CSLEW accuracy). The slew rate is not dependent on the total output capacitance, as long as the surge current is less than the current limit set by ILIM. For all dynamic positive VID transitions, the transition time (t<sub>TRAN</sub>) is given by:

$$t_{\text{TRAN}} = \frac{|V_{\text{NEW}} - V_{\text{OLD}}|}{(dV_{\text{TARGET}}/dt)}$$

where  $dV_{\text{TARGET}}/dt = 6.25\text{mV}/\mu\text{s} \times 143\text{k}\Omega / R_{\text{TIME}}$  is the slew rate, V<sub>OLD</sub> is the original output voltage, and V<sub>NEW</sub> is the new target voltage. See the TIME Slew-Rate Accuracy row in the *Electrical Characteristics* table for slew-rate limits.

The output voltage tracks the slewed target voltage, making the transitions relatively smooth. The average inductor current per phase required to make an output-voltage transition is:

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$$I_L \cong C_{OUT} \times (dV_{TARGET} / dt)$$

where  $dV_{TARGET}/dt$  is the required slew rate,  $C_{OUT}$  is the total output capacitance.

The MAX17009 SMPSSs remain in a pulse-skipping mode even during upward and downward VID transitions. As such, downward VID transitions are not forced, and the output voltage may take a longer time to settle to the lower VID code. The discharge rate of the output voltage during downward transitions is dependent on the load current and total output capacitance for loads less than a minimum current, and dependent on the  $R_{TIME}$  programmed slew rate for

heavier loads. The critical load current ( $I_{LOAD(CRIT)}$ ) where the transition time is dependent on the load is:

$$I_{LOAD(CRIT)} \cong C_{OUT} \times (dV_{TARGET} / dt)$$

For load currents less than  $I_{LOAD(CRIT)}$ , the transition time is:

$$t_{TRANS} \cong \frac{C_{OUT} \times dV_{TARGET}}{I_{LOAD}}$$

For soft-start and shutdown, the controller uses a fixed slew rate of  $1mV/\mu s$ . Figure 4 is the VID transition timing diagram. Table 4 shows the output-voltage VID DAC codes.

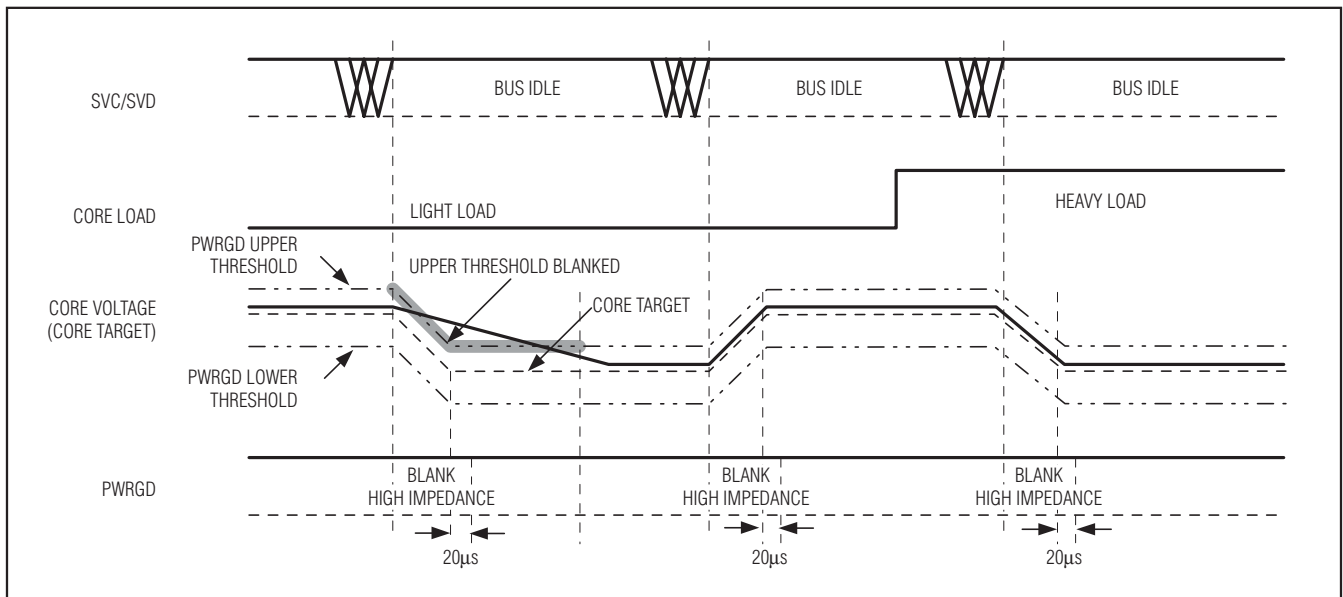


Figure 4. VID Transition Timing Figure

Table 4. Output Voltage VID DAC Codes

| SVID[6:0] | OUTPUT VOLTAGE (V) | SVID[6:0] | OUTPUT VOLTAGE (V) | SVID[6:0] | OUTPUT VOLTAGE (V) | SVID[6:0] | OUTPUT VOLTAGE (V) |
|-----------|--------------------|-----------|--------------------|-----------|--------------------|-----------|--------------------|
| 000_0000  | 1.5500             | 010_0000  | 1.1500             | 100_0000  | 0.7500             | 110_0000  | 0.3500             |
| 000_0001  | 1.5375             | 010_0001  | 1.1375             | 100_0001  | 0.7375             | 110_0001  | 0.3375             |
| 000_0010  | 1.5250             | 010_0010  | 1.1250             | 100_0010  | 0.7250             | 110_0010  | 0.3250             |
| 000_0011  | 1.5125             | 010_0011  | 1.1125             | 100_0011  | 0.7125             | 110_0011  | 0.3125             |
| 000_0100  | 1.5000             | 010_0100  | 1.1000             | 100_0100  | 0.7000             | 110_0100  | 0.3000             |
| 000_0101  | 1.4875             | 010_0101  | 1.0875             | 100_0101  | 0.6875             | 110_0101  | 0.2875             |
| 000_0110  | 1.4750             | 010_0110  | 1.0750             | 100_0110  | 0.6750             | 110_0110  | 0.2750             |
| 000_0111  | 1.4625             | 010_0111  | 1.0625             | 100_0111  | 0.6625             | 110_0111  | 0.2625             |
| 000_1000  | 1.4500             | 010_1000  | 1.0500             | 100_1000  | 0.6500             | 110_1000  | 0.2500             |
| 000_1001  | 1.4375             | 010_1001  | 1.0375             | 100_1001  | 0.6375             | 110_1001  | 0.2375             |

# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

**Table 4. Output Voltage VID DAC Codes (continued)**

| SVID[6:0] | OUTPUT VOLTAGE (V) | SVID[6:0] | OUTPUT VOLTAGE (V) | SVID[6:0] | OUTPUT VOLTAGE (V) | SVID[6:0] | OUTPUT VOLTAGE (V) |
|-----------|--------------------|-----------|--------------------|-----------|--------------------|-----------|--------------------|
| 000_1010  | 1.4250             | 010_1010  | 1.0250             | 100_1010  | 0.6250             | 110_1010  | 0.2250             |
| 000_1011  | 1.4125             | 010_1011  | 1.0125             | 100_1011  | 0.6125             | 110_1011  | 0.2125             |
| 000_1100  | 1.4000             | 010_1100  | 1.0000             | 100_1100  | 0.6000             | 110_1100  | 0.2000             |
| 000_1101  | 1.3875             | 010_1101  | 0.9875             | 100_1101  | 0.5875             | 110_1101  | 0.1875             |
| 000_1110  | 1.3750             | 010_1110  | 0.9750             | 100_1110  | 0.5750             | 110_1110  | 0.1750             |
| 000_1111  | 1.3625             | 010_1111  | 0.9625             | 100_1111  | 0.5625             | 110_1111  | 0.1625             |
| 001_0000  | 1.3500             | 011_0000  | 0.9500             | 101_0000  | 0.5500             | 111_0000  | 0.1500             |
| 001_0001  | 1.3375             | 011_0001  | 0.9375             | 101_0001  | 0.5375             | 111_0001  | 0.1375             |
| 001_0010  | 1.3250             | 011_0010  | 0.9250             | 101_0010  | 0.5250             | 111_0010  | 0.1250             |
| 001_0011  | 1.3125             | 011_0011  | 0.9125             | 101_0011  | 0.5125             | 111_0011  | 0.1125             |
| 001_0100  | 1.3000             | 011_0100  | 0.9000             | 101_0100  | 0.5000             | 111_0100  | 0.1000             |
| 001_0101  | 1.2875             | 011_0101  | 0.8875             | 101_0101  | 0.4875             | 111_0101  | 0.0875             |
| 001_0110  | 1.2750             | 011_0110  | 0.8750             | 101_0110  | 0.4750             | 111_0110  | 0.0750             |
| 001_0111  | 1.2625             | 011_0111  | 0.8625             | 101_0111  | 0.4625             | 111_0111  | 0.0625             |
| 001_1000  | 1.2500             | 011_1000  | 0.8500             | 101_1000  | 0.4500             | 111_1000  | 0.0500             |
| 001_1001  | 1.2375             | 011_1001  | 0.8375             | 101_1001  | 0.4375             | 111_1001  | 0.0375             |
| 001_1010  | 1.2250             | 011_1010  | 0.8250             | 101_1010  | 0.4250             | 111_1010  | 0.0250             |
| 001_1011  | 1.2125             | 011_1011  | 0.8125             | 101_1011  | 0.4125             | 111_1011  | 0.0125             |
| 001_1100  | 1.2000             | 011_1100  | 0.8000             | 101_1100  | 0.4000             | 111_1100  | 0                  |
| 001_1101  | 1.1875             | 011_1101  | 0.7875             | 101_1101  | 0.3875             | 111_1101  | 0                  |
| 001_1110  | 1.1750             | 011_1110  | 0.7750             | 101_1110  | 0.3750             | 111_1110  | 0                  |
| 001_1111  | 1.1625             | 011_1111  | 0.7625             | 101_1111  | 0.3625             | 111_1111  | 0                  |

### NBV\_BUF Output-Voltage Transition

The MAX17009 includes a buffered output voltage that sets the target for the NB regulator. When a voltage transition on the NB DAC occurs, the NBV\_BUF sources or sinks a programmed current on its output. The programmed current ( $I_{NBV\_BUF}$ ) is set by  $R_{TIME}$ .  $R_{TIME}$  is between  $35.7k\Omega$  and  $357k\Omega$  for corresponding  $I_{NBV\_BUF}$  between  $28\mu A$  and  $2.8\mu A$ , respectively:

$$I_{NBV\_BUF} = (7\mu A) \times (143k\Omega / R_{TIME})$$

$I_{NBV\_BUF}$  and the external capacitor ( $C_{NBV\_BUF}$ ) set the voltage slew rate of the NBV\_BUF:

$$dV_{NBV\_BUF}/dt = I_{NBV\_BUF} / C_{NBV\_BUF}$$

Program the NB regulator with a slew rate faster than that set by NBV\_BUF to allow the NBV\_BUF to control the NB regulator's output slew rate.

Alternatively, the NB regulator can be programmed with the desired slew rate, and the NBV\_BUF voltage can approach a step function by keeping  $C_{NBV\_BUF}$  small. A minimum of  $100pF$  capacitor is required.

### Pulse-Skipping Operation

The SMPS of the MAX17009 always operates in pulse-skipping mode. Pulse-skipping mode enables the driver's zero-crossing comparator, so the driver pulls its DL low when "zero" inductor current is detected ( $V_{GND} - V_{LX} = 0$ ). This keeps the inductor from discharging the output capacitors and forces the controller to skip pulses under light-load conditions to avoid overcharging the output.

In the pulse-skipping operation, the controller terminates the on-time when the output voltage exceeds the feedback threshold and when the current-sense voltage exceeds the Idle Mode current-sense threshold ( $V_{IDLE} = 0.15 \times V_{LIMIT}$ ). Under heavy-load conditions, the continuous inductor current remains above the Idle Mode current-sense threshold, so the on-time depends only on the feedback-voltage threshold. Under light-load conditions, the controller remains above the feedback voltage threshold, so the on-time duration depends solely on the Idle Mode current-sense threshold, which is approximately 15% of the full-load peak current-limit threshold set by  $ILIM$ .



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During downward VID transitions, the controller temporarily sets the OVP threshold to 1.85V (typ), preventing false OVP faults. Once the error amplifier detects that the output voltage is in regulation, the OVP threshold tracks the selected VID DAC code. The MAX17009 automatically uses forced-PWM operation during soft-shutdown.

When configured for separate-mode operation, both SMPSs remain in pulse-skipping mode, regardless of the PSI\_L bit state.

When configured for combined-mode operation, the PSI\_L bit sets the MAX17009 in 1-phase pulse-skipping mode or 2-phase pulse-skipping mode.

## Idle Mode Current-Sense Threshold

The Idle Mode current-sense threshold forces a lightly loaded regulator to source a minimum amount of power with each on-time since the controller cannot terminate the on-time until the current-sense voltage exceeds the Idle Mode current-sense threshold ( $V_{IDLE} = 0.15 \times V_{LIMIT}$ ). Since the zero-crossing comparator prevents the switching regulator from sinking current, the controller must skip pulses to avoid overcharging the output. When the clock edge occurs, if the output voltage still exceeds the feedback threshold, the controller does not initiate another on-time. This forces the controller to actually regulate the valley of the output voltage ripple under light-load conditions.

## Automatic Pulse-Skipping Crossover

In skip mode, the MAX17009 zero-crossing comparators are active. Therefore, an inherent automatic switchover to PFM takes place at light loads, resulting in a highly efficient operating mode. This switchover is affected by a comparator that truncates the low-side switch on-time at the inductor current's zero crossing. The driver's zero-crossing comparator senses the inductor current across the low-side MOSFET. Once  $V_{GND} - V_{LX}$  drops below the zero-crossing threshold, the driver forces DL low. This mechanism causes the threshold between pulse-skipping PFM and non-skipping PWM operation to coincide with the boundary between continuous and discontinuous inductor-current operation (also known as the "critical-conduction" point). The load-current level at which the PFM/PWM crossover occurs,  $I_{LOAD(SKIP)}$ , is given by:

$$I_{LOAD(SKIP)} = \frac{V_{OUT}(V_{IN} - V_{OUT})}{2V_{IN}f_{SW}L}$$

The switching waveforms may appear noisy and asynchronous when light loading causes pulse-skipping operation, but this is a normal operating condition that results in high light-load efficiency. Trade-offs in PFM noise vs. light-load efficiency are made by varying the

inductor value. Generally, low inductor values produce a broader efficiency vs. load curve, while higher values result in higher full-load efficiency (assuming that the coil resistance remains fixed) and less output-voltage ripple. Penalties for using higher inductor values include larger physical size and degraded load-transient response (especially at low input-voltage levels).

## Current Sense

The output current of each phase is sensed differentially. A low offset voltage and high gain (10V/V) differential current amplifier at each phase allows low-resistance current-sense resistors to be used to minimize power dissipation. Sensing the current at the output of each phase offers advantages, including less noise sensitivity, more accurate current sharing between phases, and the flexibility of using either a current-sense resistor or the DC resistance of the output inductor.

Using the DC resistance ( $R_{DCR}$ ) of the output inductor allows higher efficiency. In this configuration, the initial tolerance and temperature coefficient of the inductor's DCR must be accounted for in the output-voltage droop-error budget and power monitor. This current-sense method uses an RC filtering network to extract the current information from the output inductor (see Figure 5). The time constant of the RC network should match the inductor's time constant ( $L/R_{DCR}$ ):

$$\frac{L}{R_{DCR}} = R_{EQ}C_{SENSE}$$

where  $C_{SENSE}$  and  $R_{EQ}$  are the time-constant matching components. To minimize the current-sense error due to the current-sense inputs' bias current ( $I_{CSP}$  and  $I_{CSN}$ ), choose  $R_{EQ}$  less than  $2k\Omega$  and use the above equation to determine the sense capacitance ( $C_{SENSE}$ ). Choose capacitors with 5% tolerance and resistors with 1% tolerance specifications. Temperature compensation is recommended for this current-sense method. See the *Voltage-Positioning and Loop Compensation* section for detailed information.

When using a current-sense resistor for accurate output-voltage positioning, the circuit requires a differential RC filter to eliminate the AC voltage step caused by the equivalent series inductance ( $LESL$ ) of the current-sense resistor (see Figure 5). The ESL-induced voltage step does not affect the average current-sense voltage, but results in a significant peak current-sense voltage error that results in unwanted offsets in the regulation voltage and results in early current-limit detection. Similar to the inductor DCR sensing method above, the RC filter's time constant should match the L/R time constant formed by the current-sense resistor's parasitic inductance:

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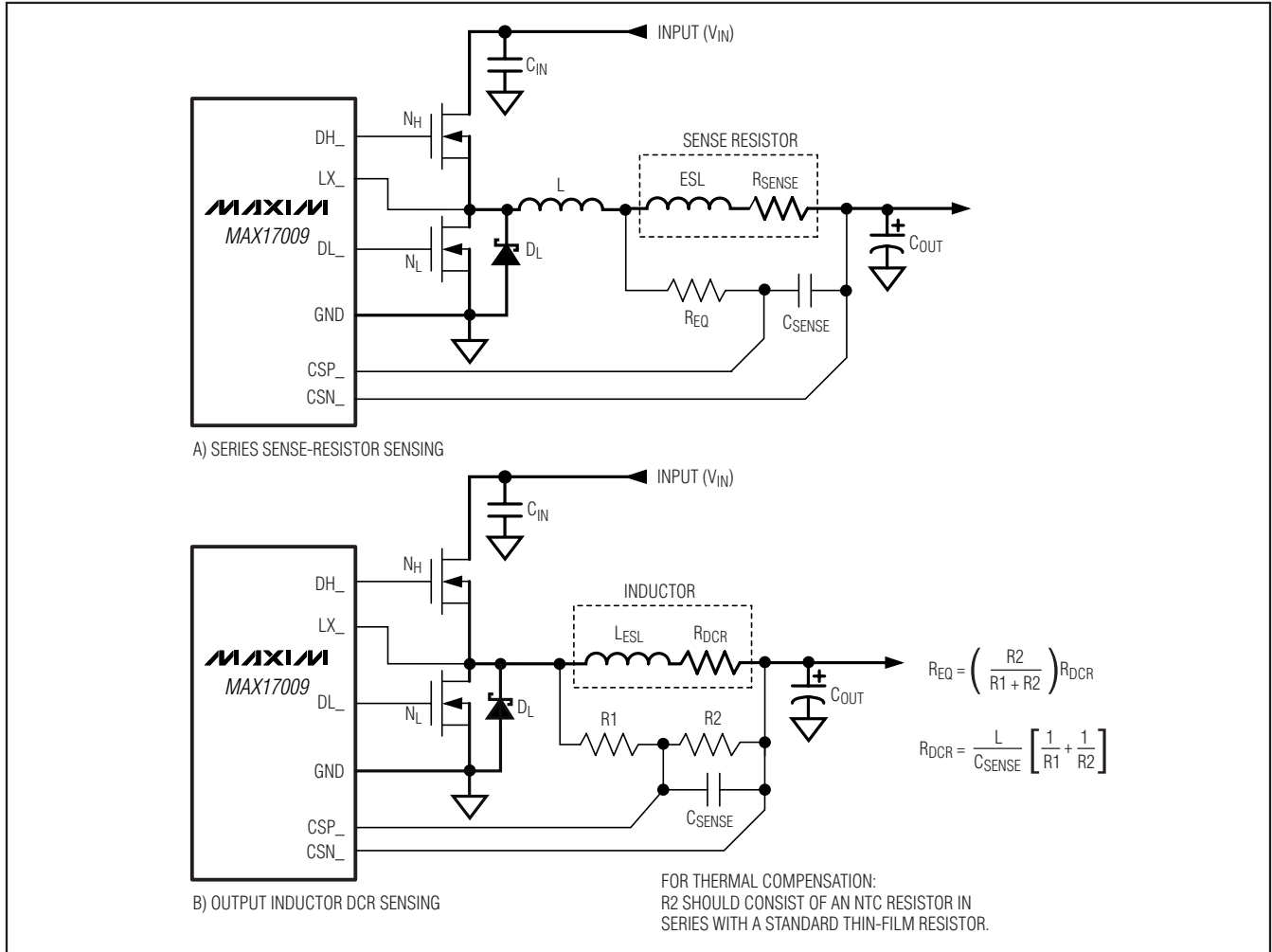


Figure 5. Current-Sense Configurations

$$\frac{L_{ESL}}{R_{SENSE}} = R_{EQ} C_{SENSE}$$

where  $L_{ESL}$  is the equivalent series inductance of the current-sense resistor,  $R_{SENSE}$  is current-sense resistance value, and  $C_{SENSE}$  and  $R_{EQ}$  are the time-constant matching components.

### Combined-Mode Current Balance

When configured in combined mode, the MAX17009 current-mode architecture automatically forces the individual phases to remain current balanced. SMPS1 is the main voltage-control loop, and SMPS2 maintains the

current balance between the phases. This control scheme regulates the peak inductor current of each phase, forcing them to remain properly balanced. Therefore, the average inductor current variation depends mainly on the variation in the current-sense element and inductance value.

### Peak Current Limit

The MAX17009 current-limit circuit employs a fast peak inductor current-sensing algorithm. Once the current-sense signal (CSP to CSN) of the active phase exceeds the peak current-limit threshold, the PWM controller terminates the on-time. See the *Peak-Inductor Current Limit* section in the *SMPS Design Procedure* section.



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## Power-Up Sequence (POR, UVLO, PGD\_IN)

Power-on reset (POR) occurs when V<sub>CC</sub> rises above approximately 2V, resetting the fault latch and preparing the controller for operation. The V<sub>CC</sub> undervoltage lockout (UVLO) circuitry inhibits switching until V<sub>CC</sub> rises above 4.25V. The controller powers up the reference once the system enables the controller—V<sub>CC</sub> above 4.25V and  $\overline{\text{SHDN}}$  driven high. With the reference in regulation, the controller ramps the SMPS and NBV\_BUF voltages to the boot voltage set by the SVC and SVD inputs:

$$t(\text{SMPS-START}) = \frac{V_{\text{BOOT}}}{(1\text{mV}/\mu\text{s})}$$

$$t(\text{NBV\_BUF-START}) = \frac{V_{\text{BOOT}} \times \text{TIMEC}_{\text{NBV\_BUF}}}{(7\mu\text{A} \times 143\text{k}\Omega)}$$

The soft-start circuitry does not use a variable current limit, so full output current is available immediately. PWRGD becomes high impedance approximately 20μs

after the SMPS outputs reach regulation. The boot VID is stored the first time PWRGD goes high. The MAX17009 is in pulse-skipping mode during soft-start, and in forced-PWM mode soft-shutdown.

The NB regulator soft-start time is set by the NB regulator soft-start timer, or by t(NBV\_BUF-START), whichever is longer.

For automatic startup, the battery voltage should be present before V<sub>CC</sub>. If the controller attempts to bring the output into regulation without the battery voltage present, the fault latch trips. The controller remains shut down until the fault latch is cleared by toggling  $\overline{\text{SHDN}}$  or cycling the V<sub>CC</sub> power supply below 0.5V.

If the V<sub>CC</sub> voltage drops below 4.25V, the controller assumes that there is not enough supply voltage to make valid decisions and could also result in the stored boot VIDs being corrupted. As such, the MAX17009 immediately stops switching (DH\_ and DL\_ pulled low), latches off, and discharges the outputs using the internal 10Ω switches from CSL\_ to GND. See Figure 6.

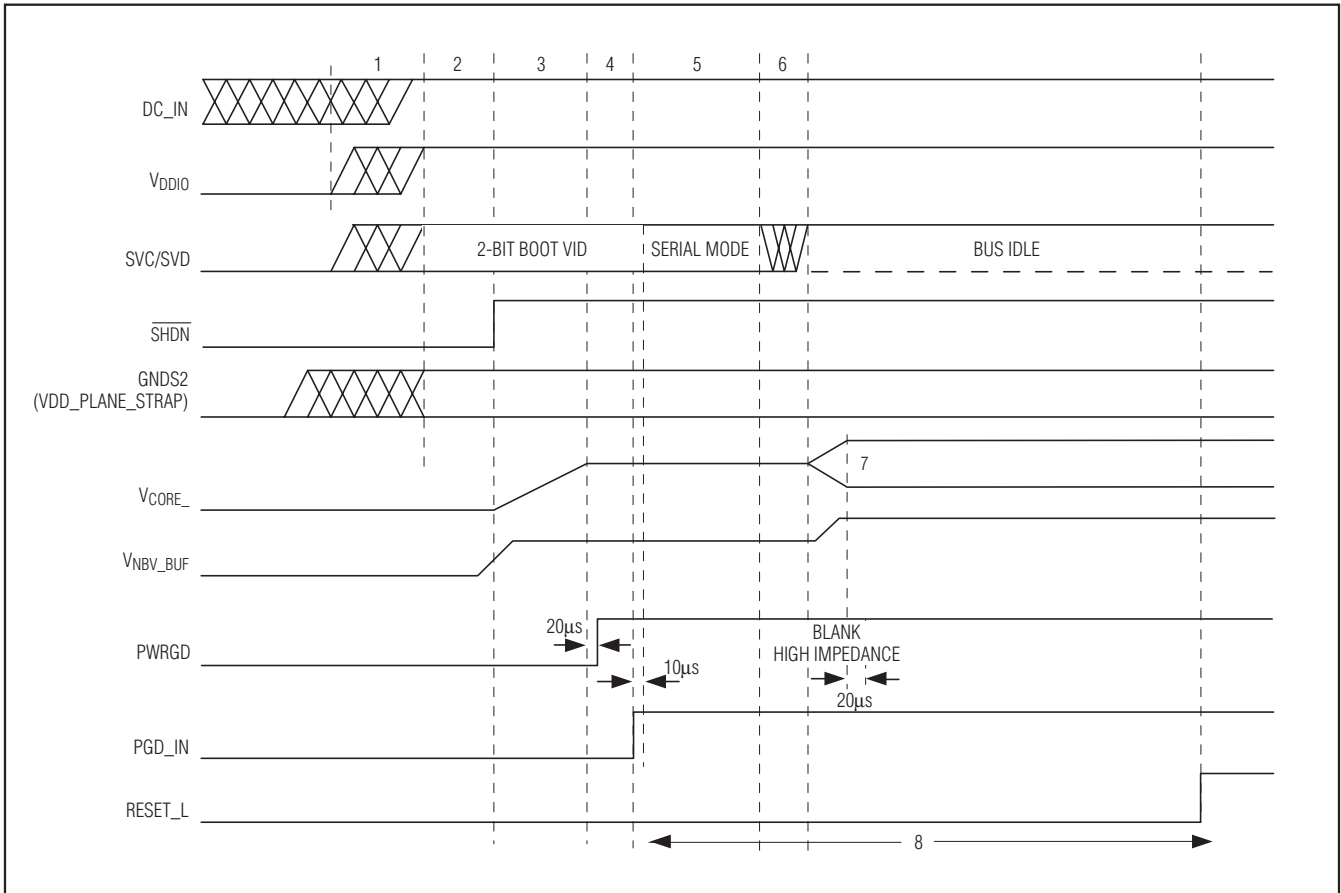


Figure 6. Startup Sequence

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## Notes:

- 1) The relationship between DC\_IN and VDDIO is not guaranteed. It is possible to have VDDIO powered when DC\_IN is not powered, and it is possible to have DC\_IN power-up before VDDIO powers up.
- 2) As the VDDIO power rail comes within specification, VDD\_Plane\_Strap becomes valid and SVC and SVD are driven to the boot VID value by the processor. The system guarantees that VDDIO is in specification and SVC and SVD are driven to the boot VID value for at least 10μs prior to SHDN being asserted to the MAX17009.
- 3) After SHDN is asserted, the MAX17009 samples and latches the VDD\_Plane\_Strap level at its GNDS2 pin when REF reaches the REFOK threshold, and ramps up the voltage-plane outputs to the level indicated by the 2-bit boot VID. The boot VID is stored in the MAX17009 for use when PGD\_IN deasserts. The MAX17009 soft-starts the output rails to limit inrush current from the DC\_IN rail.
- 4) The MAX17009 asserts PWRGD. After PWRGD is asserted and all system-wide voltage planes and free-running clocks are within specification, then the system asserts PGD\_IN.
- 5) The processor holds the 2-bit boot VID for at least 10μs after PGD\_IN is asserted.
- 6) The processor issues the set VID command through SVI.
- 7) The MAX17009 transitions the voltage planes to the set VID. The set VID may be greater than, or less than the boot VID voltage.
- 8) The chipset enforces a 1ms delay between PGD\_IN assertion and RESET\_L deassertion.

## PWRGD

The MAX17009 features internal power-good fault comparators for each phase. The outputs of these individual power-good fault comparators are logically ORed to drive the gate of the open-drain PWRGD output transistor. Each phase's power-good fault comparator has an upper threshold of +200mV (typ) and a lower threshold of -300mV (typ). PWRGD goes low if the output of either phase exceeds its respective thresholds.

PWRGD is forced low during the startup sequence up to 20μs after both SMPS internal DACs reach the boot VID. The 2-bit boot VID is stored when PWRGD goes high during the startup sequence. PWRGD is immediately forced low when SHDN goes low.

PWRGD is blanked high impedance while either of the internal SMPS DACs are slewing during a VID transition, plus an additional 20μs after the DAC transition is completed. For downward VID transitions, the upper threshold of the power-good fault comparators remains blanked until the output reaches regulation again.

PWRGD goes low for a minimum of 20μs when PGD\_IN goes low, and stays low until 20μs after both SMPS internal DACs reach the boot VID.

## PGD\_IN

After the SMPS outputs reach the boot voltage, the MAX17009 switches over to the serial-interface mode when PGD\_IN goes high. Anytime during normal operation, a high-to-low transition on PGD\_IN causes the MAX17009 to slew all three internal DACs back to the stored boot VIDs. PWRGD goes low for a minimum of 20μs when PGD\_IN goes low, and stays low until 20μs after the SMPS outputs are within the PWRGD thresholds. The SVC and SVD inputs are disabled during the time that PGD\_IN is low. The serial interface is reenabled when PGD\_IN goes high again.

In debug mode ( $\overline{PRO}$  = OPEN), the function of the SVC and SVD inputs depend on the PGD\_IN level. If PGD\_IN is low, the SVC and SVD inputs are used as 2-bit inputs to set the three internal DAC voltages. See Table 3. If PGD\_IN is high, the MAX17009 switches over to serial-interface mode. A high-to-low transition on PGD\_IN causes the MAX17009 to slew all three internal DACs back to the stored boot VIDs and revert to the 2-bit VID mode. See Figure 7.

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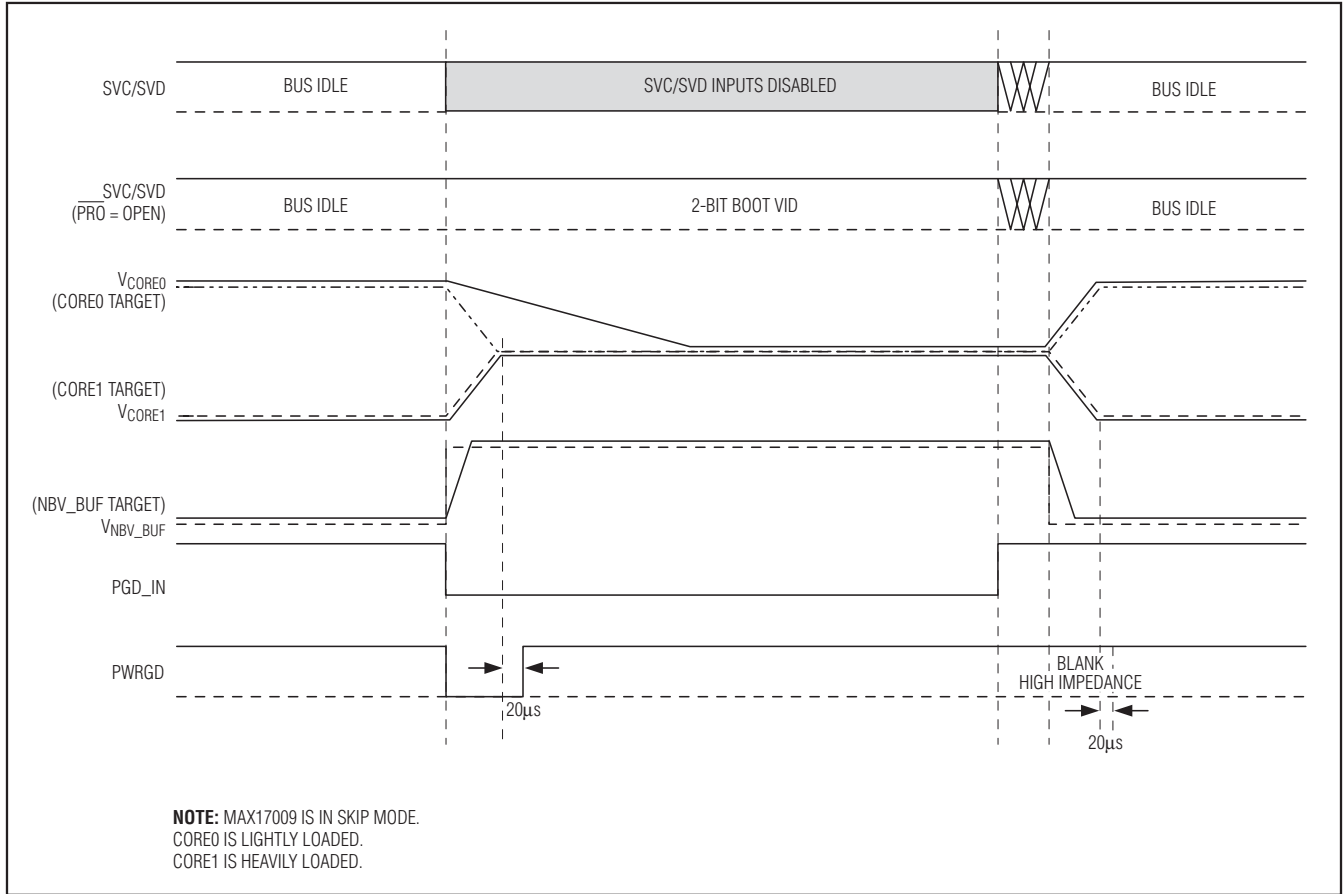


Figure 7. PGD\_IN Timing Figure

## Shutdown

When  $\overline{\text{SHDN}}$  goes low, the MAX17009 enters the low-power shutdown mode. PWRGD is pulled low immediately, and the SMPS output voltages ramp down at  $1\text{mV}/\mu\text{s}$ , while the NBV\_BUF output slews at a rate set by RTIME. At the end of the soft-shutdown sequence, DL\_ is kept low, and the  $10\Omega$  switches from CSL\_ to GND are enabled, holding the outputs low:

$$t_{(\text{SMPS}-\text{SHDN})} = \frac{V_{\text{OUT}}}{(1\text{mV}/\mu\text{s})}$$

$$t_{(\text{NBV\_BUF}-\text{SHDN})} = \frac{V_{\text{NBV\_BUF}} R_{\text{TIME}} C_{\text{NBV\_BUF}}}{(7\mu\text{A} \times 143\text{k}\Omega)}$$

Slowly discharging the output capacitors by slewing the output over a long period of time keeps the average negative inductor current low (damped response), thereby eliminating the negative output-voltage excursion that

occurs when the controller discharges the output quickly by permanently turning on the low-side MOSFET (underdamped response). This eliminates the need for the Schottky diode normally connected between the output and ground to clamp the negative output-voltage excursion. The MAX17009 shuts down completely—the drivers are disabled, the reference turns off, and the supply currents drop to about  $1\mu\text{A}$  (max)— $20\mu\text{s}$  after the controller reaches the  $0\text{V}$  target. When a fault condition—overvoltage or undervoltage—occurs on one SMPS, the other SMPS and the NBV\_BUF immediately go through the soft-shutdown sequence. To clear the fault latch and reactivate the controller, toggle  $\overline{\text{SHDN}}$  or cycle VCC power below  $0.5\text{V}$ .

Soft-shutdown for the NB regulator is determined by the particular NB regulator's shutdown behavior. In the typical application, the NB regulator's SHDN pin or enable pin is toggled at the same time as the MAX17009's SHDN pin.

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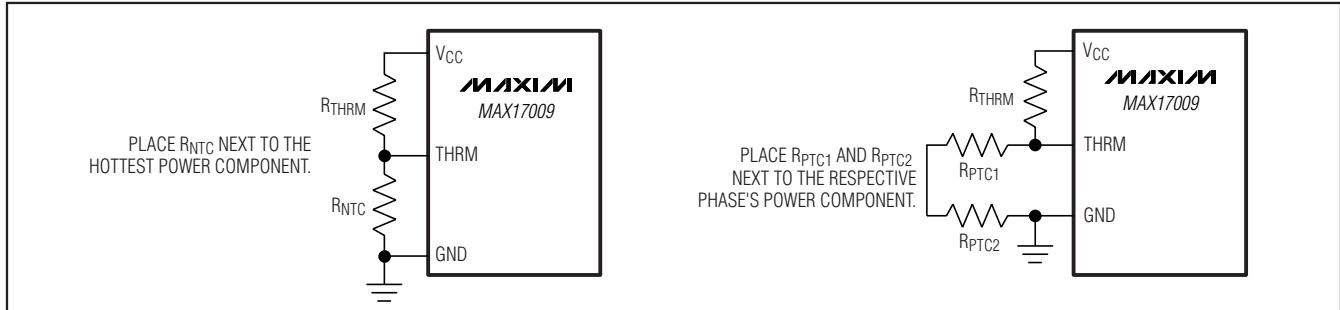


Figure 8. THRM Configuration

## VRHOT Temperature Comparator

The MAX17009 features an independent comparator with an accurate threshold ( $V_{HOT}$ ) that tracks the analog supply voltage ( $V_{HOT} = 0.3 \times V_{CC}$ ). Use a resistor-and-thermistor-divider between  $V_{CC}$  and GND to generate a voltage-regulator overtemperature monitor. Place the thermistor as close to the MOSFETs and inductors as possible.

For combined-mode operations, the current-balance circuit balances the currents between phases. As such, the power loss and heat in each phase should be identical, apart from the effects of placement and airflow over each phase. A single thermistor can be placed near either of the phases and still be effective.

For separate mode operation, the load currents between phases may be very different. Using two “logic-level” thermistors (e.g., Murata PRF series POSITORS) allows the same  $\overline{VRHOT}$  comparator to monitor the temperature of both phases. Figure 8 is the THRM configuration.

## Fault Protection (Latched)

### $\overline{PRO}$ Selectable Overvoltage Protection and Debug Mode

The MAX17009 features a tri-level  $\overline{PRO}$  pin that enables the overvoltage protection feature, or puts the MAX17009 in debug mode. Table 5 shows the  $\overline{PRO}$ -selectable options. Debug mode is intended for applications where the serial interface is not properly functioning, and the output voltage needs to be adjusted to different levels. The DAC voltage settings in debug mode further depend on the PGD\_IN level to switch between the 2-bit VID setting or the serial interface operation.

Table 5.  $\overline{PRO}$  Settings

| $\overline{PRO}$ | DESCRIPTION              |
|------------------|--------------------------|
| VCC              | OVP disabled             |
| OPEN             | Debug mode, OVP disabled |
| GND              | OVP enabled              |

## Output Overvoltage Protection

The overvoltage-protection (OVP) circuit is designed to protect the CPU against a shorted high-side MOSFET by drawing high current and blowing the battery fuse. The MAX17009 continuously monitors the output for an overvoltage fault. The controller detects an OVP fault if the output voltage exceeds the set VID DAC voltage by more than 300mV. The OVP threshold tracks the VID DAC voltage except during a downward VID transition. During a downward VID transition, the OVP threshold is set at 1.80V (min), until the output reaches regulation, when the OVP threshold is reset back to 300mV above the VID setting.

When the OVP circuit detects an overvoltage fault, it immediately forces the external low-side driver high on the faulted side and initiates the soft-shutdown for the other SMPS and the NBV\_BUF. The synchronous-rectifier MOSFETs of the faulted side are turned on with 100% duty, which rapidly discharges the output filter capacitor and forces the output low. If the condition that caused the overvoltage (such as a shorted high-side MOSFET) persists, the battery fuse blows. Toggle  $\overline{SHDN}$  or cycle the  $V_{CC}$  power supply below 0.5V to clear the fault latch and reactivate the controller.

When in combined mode, the synchronous-rectifier MOSFETs of both phases are turned on with 100% duty in response to an overvoltage fault.

Overvoltage protection can be disabled by setting  $\overline{PRO}$  to high or open.

## Output Undervoltage Protection

The output UVP function is similar to foldback current limiting, but employs a timer rather than a variable current limit. If the MAX17009 output voltage is 400mV below the target voltage, the controller activates the shutdown sequence for both SMPS and NBV\_BUF, and sets the fault latch. Toggle  $\overline{SHDN}$  or cycle the  $V_{CC}$  power supply below 0.5V to clear the fault latch and reactivate the controller.

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## Thermal-Fault Protection

The MAX17009 features a thermal-fault protection circuit. When the junction temperature rises above +160°C, a thermal sensor sets the fault latch and shuts down, immediately forcing DH and DL low, without going through the soft-shutdown sequence. Toggle SHDN or cycle the V<sub>CC</sub> power supply below 0.5V to clear the fault latch and reactivate the controller after the junction temperature cools by 15°C.

## MOSFET Gate Drivers

The DH and DL drivers are optimized for driving moderate-sized high-side and larger low-side power MOSFETs. This is consistent with the low duty factor seen in notebook applications where a large V<sub>IN</sub> - V<sub>OUT</sub> differential exists. The high-side gate drivers (DH) source and sink 2.2A, and the low-side gate drivers (DL) source 2.7A and sink 8A. This ensures robust gate drive for high-current applications. The DH floating high-side MOSFET drivers are powered by internal boost switch charge pumps at BST, while the DL synchronous-rectifier drivers are powered directly by the 5V bias supply (V<sub>DD</sub>).

Adaptive dead-time circuits monitor the DL and DH drivers and prevent either FET from turning on until the other is fully off. The adaptive driver dead time allows operation without shoot-through with a wide range of MOSFETs, minimizing delays and maintaining efficiency.

There must be a low-resistance, low-inductance path from the DL and DH drivers to the MOSFET gates for the adaptive dead-time circuits to work properly; otherwise, the sense circuitry in the MAX17009 interprets the MOSFET gates as “off” while charge actually remains. Use very short, wide traces (50 mils to 100 mils wide if the MOSFET is 1in from the driver).

The internal pulldown transistor that drives DL low is robust, with a 0.25Ω (typ) on-resistance. This helps prevent DL from being pulled up due to capacitive coupling from the drain to the gate of the low-side MOSFETs when the inductor node (LX) quickly switches from ground to V<sub>IN</sub>. Applications with high input voltages and long inductive driver traces may require rising LX edges that do not pull up the low-side MOSFETs’ gate, causing shoot-through currents. The capacitive coupling between LX and DL created by the MOSFET’s gate-to-drain capacitance (C<sub>RSS</sub>), gate-to-source capacitance (C<sub>ISS</sub> - C<sub>RSS</sub>), and additional board parasitics should not exceed the following minimum threshold:

$$V_{GS(TH)} > V_{IN} \left( \frac{C_{RSS}}{C_{ISS}} \right)$$

Typically, adding a 4700pF between DL and power ground (C<sub>NL</sub> in Figure 9), close to the low-side MOSFETs, greatly reduces coupling. Do not exceed 22nF of total gate capacitance to prevent excessive turn-off delays.

Alternatively, shoot-through currents can be caused by a combination of fast high-side MOSFETs and slow low-side MOSFETs. If the turn-off delay time of the low-side MOSFET is too long, the high-side MOSFETs can turn on before the low-side MOSFETs have actually turned off. Adding a resistor less than 5Ω in series with BST slows down the high-side MOSFET turn-on time, eliminating the shoot-through currents without degrading the turn-off time (R<sub>BST</sub> in Figure 9). Slowing down the high-side MOSFET also reduces the LX node rise time, thereby reducing EMI and high-frequency coupling responsible for switching noise.

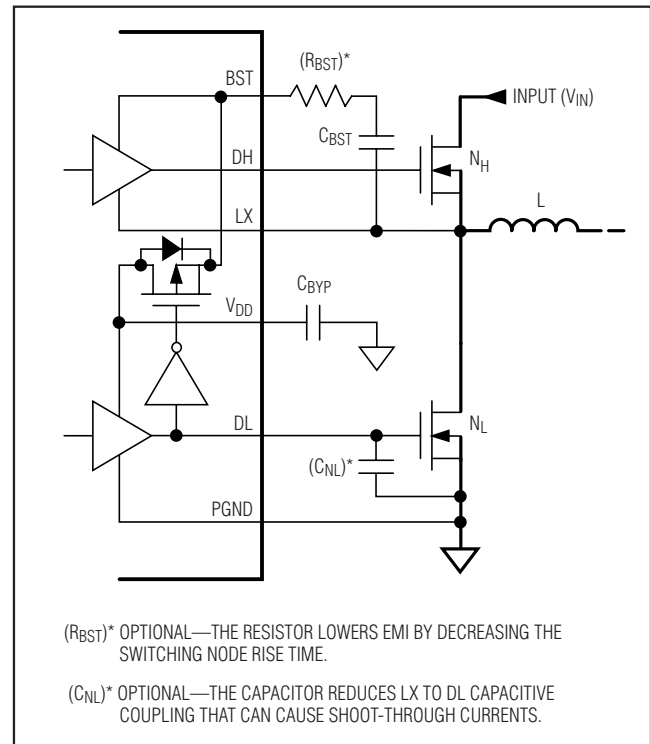


Figure 9. Gate Drive Circuit



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**Table 6. OPTION Pin Settings**

| OPTION | OFFSET ENABLED | TRANSIENT-PHASE REPEAT ENABLED |
|--------|----------------|--------------------------------|
| VCC    | 0              | 0                              |
| OPEN   | 0              | 1                              |
| REF    | 1              | 0                              |
| GND    | 1              | 1                              |

## Offset and Transient-Phase Repeat (OPTION)

The +12.5mV offset and the transient-phase repeat features of the MAX17009 can be selectively enabled and disabled by the OPTION pin setting. Table 6 shows the OPTION pin voltage levels and the features that are enabled. See the *Transient Phase Repeat* section for a detailed description of the respective features. When the offset is enabled, setting the PSI\_L bit low disables the offset reducing power consumption in the low-power state.

## SMPS Design Procedure

Firmly establish the input voltage range and maximum load current before choosing a switching frequency and inductor operating point (ripple-current ratio). The primary design trade-off lies in choosing a good switching frequency and inductor operating point, and the following four factors dictate the rest of the design:

- **Input voltage range:** The maximum value ( $V_{IN(MAX)}$ ) must accommodate the worst-case high AC adapter voltage. The minimum value ( $V_{IN(MIN)}$ ) must account for the lowest input voltage after drops due to connectors, fuses, and battery selector switches. If there is a choice at all, lower input voltages result in better efficiency.
- **Maximum load current:** There are two values to consider. The peak load current ( $I_{LOAD(MAX)}$ ) determines the instantaneous component stresses and filtering requirements, and thus drives output capacitor selection, inductor saturation rating, and the design of the current-limit circuit. The continuous load current ( $I_{LOAD}$ ) determines the thermal stresses and thus drives the selection of input capacitors, MOSFETs, and other critical heat-contributing components. Modern notebook CPUs generally exhibit  $I_{LOAD} = I_{LOAD(MAX)} \times 80\%$ .

For multiphase systems, each phase supports a fraction of the load, depending on the current balancing. When properly balanced, the load current is evenly distributed among each phase:

$$I_{LOAD(PHASE)} = \frac{I_{LOAD}}{\eta_{PH}}$$

where  $\eta_{PH}$  is the total number of active phases.

- **Switching frequency:** This choice determines the basic trade-off between size and efficiency. The optimal frequency is largely a function of maximum input voltage, due to MOSFET switching losses that are proportional to frequency and  $V_{IN}^2$ . The optimum frequency is also a moving target, due to rapid improvements in MOSFET technology that are making higher frequencies more practical.

When selecting a switching frequency, the minimum on-time at the highest input voltage and lowest output voltage must be greater than the 185ns (max) minimum on-time specification in the *Electrical Characteristics* table:

$$V_{OUT(MIN)} / V_{IN(MAX)} \times T_{SW} > t_{ONMIN}$$

A good rule is to choose a minimum on-time of at least 200ns.

When in pulse-skipping operation  $SKIP_ = GND$ , the minimum on-time must take into consideration the time needed for proper skip-mode operation. The on-time for a skip pulse must be greater than the 185ns (max) minimum on-time specification in the *Electrical Characteristics* table:

$$t_{ONMIN} \leq \frac{LV_{IDLE}}{R_{SENSE}(V_{IN(MAX)} - V_{OUT(MIN)})}$$

- **Inductor operating point:** This choice provides trade-offs between size vs. efficiency and transient response vs. output noise. Low inductor values provide better transient response and smaller physical size, but also result in lower efficiency and higher output noise due to increased ripple current. The minimum practical inductor value is one that causes the circuit to operate at the edge of critical conduction (where the inductor current just touches zero with every cycle at maximum load). Inductor values lower than this grant no further size-reduction benefit. The optimum operating point is usually found between 20% and 50% ripple current.

## Inductor Selection

By design, the AMD Mobile Serial VID application should regard each of the MAX17009 SMPSs as independent, single-phase regulators. The switching frequency and operating point (% ripple current or LIR) determine the inductor value as follows:

# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

$$L = \left( \frac{V_{IN} - V_{OUT}}{f_{SW} I_{LOAD(MAX)} LIR} \right) \left( \frac{V_{OUT}}{V_{IN}} \right)$$

where  $I_{LOAD(MAX)}$  is the maximum current per phase, and  $f_{SW}$  is the switching frequency per phase.

Find a low-loss inductor having the lowest possible DC resistance that fits in the allotted dimensions. If using a swinging inductor (where the inductance decreases linearly with increasing current), evaluate the LIR with properly scaled inductance values. For the selected inductance value, the actual peak-to-peak inductor ripple current ( $\Delta I_{INDUCTOR}$ ) is defined by:

$$\Delta I_{INDUCTOR} = \frac{V_{OUT}(V_{IN} - V_{OUT})}{V_{IN} f_{SW} L}$$

Ferrite cores are often the best choice, although powdered iron is inexpensive and can work well at 200kHz. The core must be large enough not to saturate at the peak inductor current ( $I_{PEAK}$ ):

$$I_{PEAK} = \left( \frac{I_{LOAD(MAX)}}{\eta_{PH}} \right) + \left( \frac{\Delta I_{INDUCTOR}}{2} \right)$$

## Peak-Inductor Current Limit (ILIM)

The MAX17009 overcurrent protection employs a peak current-sensing algorithm that uses either current-sense resistors or the inductor's DCR as the current-sense element (see the *Current Sense* section). Since the controller limits the peak inductor current, the maximum average load current is less than the peak current-limit threshold by an amount equal to half the inductor ripple current. Therefore, the maximum load capability is a function of the current-sense resistance, inductor value, switching frequency, and input-to-output voltage difference. When combined with the output undervoltage-protection circuit, the system is effectively protected against excessive overload conditions.

The peak current-limit threshold is set by voltage difference between ILIM and REF using an external resistor-divider:

$$V_{CS(PK)} = V_{CSP\_} - V_{CSN\_} = 0.05 \times (V_{REF} - V_{ILIM})$$

$$I_{LIMIT(PK)} = V_{CS(PK)} / R_{SENSE}$$

where  $R_{SENSE}$  is the resistance value of the current-sense element (inductors' DCR or current-sense resistor), and  $I_{LIMIT(PK)}$  is the desired peak current limit (per phase). The peak current-limit threshold voltage-adjustment range is from 10mV to 50mV.

## Output-Capacitor Selection

The output filter capacitor must have low-enough ESR to meet output ripple and load-transient requirements. In CPU  $V_{CORE}$  converters and other applications where the output is subject to large-load transients, the output capacitor's size typically depends on how much ESR is needed to prevent the output from dipping too low under a load transient. Ignoring the sag due to finite capacitance:

$$(R_{ESR} + R_{PCB}) \leq \frac{V_{STEP}}{\Delta I_{LOAD(MAX)}}$$

In non-CPU applications, the output capacitor's size often depends on how much ESR is needed to maintain an acceptable level of output ripple voltage. The output ripple voltage of a step-down controller equals the total inductor ripple current multiplied by the output capacitor's ESR. When operating multiphase systems out-of-phase, the peak inductor currents of each phase are staggered, resulting in lower output-ripple voltage ( $V_{RIPPLE}$ ) by reducing the total inductor ripple current. For nonoverlapping, multiphase operation ( $V_{IN} \geq V_{OUT}$ ), the maximum ESR to meet the output-ripple-voltage requirement is:

$$R_{ESR} \leq \left[ \frac{V_{IN} f_{SW} L}{(V_{IN} - V_{OUT}) V_{OUT}} \right] V_{RIPPLE}$$

where  $f_{SW}$  is the switching frequency per phase. The actual capacitance value required relates to the physical size needed to achieve low ESR, as well as to the chemistry of the capacitor technology. Thus, the capacitor selection is usually limited by ESR and voltage rating rather than by capacitance value (this is true of polymer types).

The capacitance value required is determined primarily by the output transient-response requirements. Low inductor values allow the inductor current to slew faster, replenishing charge removed from or added to the output filter capacitors by a sudden load step. Therefore, the amount of output soar when the load is removed is a function of the output voltage and inductor value. The minimum output capacitance required to prevent overshoot ( $V_{SOAR}$ ) due to stored inductor energy can be calculated as:

$$C_{OUT} \geq \frac{(\Delta I_{LOAD(MAX)})^2 L}{2 V_{OUT} V_{SOAR}}$$



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When using low-capacity ceramic-filter capacitors, capacitor size is usually determined by the capacity needed to prevent  $V_{SOAR}$  from causing problems during load transients. Generally, once enough capacitance is added to meet the overshoot requirement, undershoot at the rising load edge is no longer a problem.

## Input-Capacitor Selection

The input capacitor must meet the ripple-current requirement ( $I_{RMS}$ ) imposed by the switching currents. For a dual, 180° interleaved controller, the out-of-phase operation reduces the RMS input ripple current, effectively lowering the input capacitance requirements. When both outputs operate with a duty cycle less than 50% ( $V_{IN} > 2 \times V_{OUT}$ ), the RMS input-ripple current is defined by the following equation:

$$I_{RMS} = \sqrt{\left(\frac{V_{OUT1}}{V_{IN}}\right) I_{OUT1}(I_{OUT1} - I_{IN}) + \left(\frac{V_{OUT2}}{V_{IN}}\right) I_{OUT2}(I_{OUT2} - I_{IN})}$$

where  $I_{IN}$  is the average input current:

$$I_{IN} = \left(\frac{V_{OUT1}}{V_{IN}}\right) I_{OUT1} + \left(\frac{V_{OUT2}}{V_{IN}}\right) I_{OUT2}$$

In combined mode ( $GNDS2 = V_{DDIO}$ ) with both phases active, the input RMS current simplifies to:

$$I_{RMS} = I_{OUT} \sqrt{\left(\frac{V_{OUT}}{V_{IN}}\right) \left(\frac{1}{2} - \frac{V_{OUT}}{V_{IN}}\right)}$$

For most applications, nontantalum chemistries (ceramic, aluminum, or OS-CON) are preferred due to their resistance to inrush surge currents typical of systems with a mechanical switch or connector in series with the input. If the MAX17009 is operated as the second stage of a two-stage power-conversion system, tantalum input capacitors are acceptable. In either configuration, choose an input capacitor that exhibits less than 10°C temperature rise at the RMS input current for optimal circuit longevity.

## Voltage Positioning and Loop Compensation

Voltage positioning dynamically lowers the output voltage in response to the load current, reducing the output capacitance and processor's power-dissipation requirements. The controller uses two transconductance amplifiers to set the transient and DC output-voltage droop (Figure 3). The transient-compensation (TRC) amplifier determines how quickly the MAX17009 responds to the load transient. The FBDC\_ amplifier adjusts the steady-state regulation voltage as a function of the load. This adjustability allows flexibility in the

selected current-sense resistor value or inductor DCR, and allows smaller current-sense resistance to be used, reducing the overall power dissipated.

### Steady-State Voltage Positioning

Connect a resistor ( $R_{FBDC\_}$ ) between FBDC\_ and the remote-sense point to set the steady-state DC droop (load line) based on the required voltage-positioning slope ( $RDROOPDC$ ):

$$R_{FBDC\_} = RDROOPDC / (R_{SENSE\_} \times G_m(FBDC\_))$$

where  $RDROOPDC$  is the desired steady-state droop,  $G_m(FBDC\_)$  is typically 1ms as defined in the *Electrical Characteristics* table, and  $R_{SENSE\_}$  is the value of the current-sense resistor that is used to provide the ( $CSP\_$ ,  $CSN\_$ ) current-sense voltage.

When the inductors' DCR is used as the current-sense element ( $R_{SENSE} = R_{DCR}$ ), the inductor DCR circuit should include an NTC thermistor to cancel the temperature dependence of the inductor DCR, maintaining a constant voltage-positioning slope.

### Transient Droop

Connect a resistor ( $R_{FBAC\_}$ ) between FBAC\_ and the remote-sense point to set the DC transient AC droop (load-line) based on the required voltage-positioning slope ( $RDROOPAC$ ):

$$R_{FBAC\_} = RDROOPAC / (R_{SENSE\_} \times G_m(FBAC\_))$$

where  $RDROOPAC$  is the desired steady-state droop,  $G_m(FBAC\_)$  is typically 1mS as defined in the *Electrical Characteristics* table, and  $R_{SENSE\_}$  is the value of the current-sense resistor that is used to provide the ( $CSP\_$ ,  $CSN\_$ ) current-sense voltage.

When the inductors' DCR is used as the current-sense element ( $R_{SENSE} = R_{DCR}$ ), the inductor DCR circuit should include an NTC thermistor to cancel the temperature dependence of the inductor DCR, maintaining a constant voltage-positioning slope.

### Power-MOSFET Selection

Most of the following MOSFET guidelines focus on the challenge of obtaining high load-current capability when using high-voltage (> 20V) AC adapters. Low-current applications usually require less attention.

The high-side MOSFET ( $N_H$ ) must be able to dissipate the resistive losses plus the switching losses at both  $V_{IN(MIN)}$  and  $V_{IN(MAX)}$ . Calculate both these sums. Ideally, the losses at  $V_{IN(MIN)}$  should be roughly equal to losses at  $V_{IN(MAX)}$ , with lower losses in between. If the losses at  $V_{IN(MIN)}$  are significantly higher than the losses at  $V_{IN(MAX)}$ , consider increasing the size of  $N_H$  (reducing  $R_{DS(ON)}$  but with higher  $C_{GATE}$ ). Conversely, if the losses at  $V_{IN(MAX)}$  are significantly higher than the losses at

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$V_{IN(MIN)}$ , consider reducing the size of  $N_H$  (increasing  $R_{DS(ON)}$  to lower  $C_{GATE}$ ). If  $V_{IN}$  does not vary over a wide range, the minimum power dissipation occurs where the resistive losses equal the switching losses.

Choose a low-side MOSFET that has the lowest possible on-resistance ( $R_{DS(ON)}$ ), comes in a moderate-sized package (i.e., one or two 8-pin SOs, DPAK, or D<sup>2</sup>PAK), and is reasonably priced. Make sure that the DL gate driver can supply sufficient current to support the gate charge and the current injected into the parasitic gate-to-drain capacitor caused by the high-side MOSFET turning on; otherwise, cross-conduction problems may occur (see the *MOSFET Gate Drivers* section).

## MOSFET Power Dissipation

Worst-case conduction losses occur at the duty-factor extremes. For the high-side MOSFET ( $N_H$ ), the worst-case power dissipation due to resistance occurs at the minimum input voltage:

$$PD(NHResistive) = \left( \frac{V_{OUT}}{V_{IN}} \right) I_{LOAD}^2 R_{DS(ON)}$$

where  $I_{LOAD}$  is the per-phase current.

Generally, a small high-side MOSFET is desired to reduce switching losses at high input voltages. However, the  $R_{DS(ON)}$  required to stay within package power dissipation often limits how small the MOSFET can be. Again, the optimum occurs when the switching losses equal the conduction ( $R_{DS(ON)}$ ) losses. High-side switching losses do not usually become an issue until the input is greater than approximately 15V.

Calculating the power dissipation in high-side MOSFET ( $N_H$ ) due to switching losses is difficult since it must allow for difficult quantifying factors that influence the turn-on and turn-off times. These factors include the internal gate resistance, gate charge, threshold voltage, source inductance, and PCB layout characteristics. The following switching-loss calculation provides only a very rough estimate and is no substitute for breadboard evaluation, preferably including verification using a thermocouple mounted on  $N_H$ :

$$PD(NHSwitching) = (V_{IN(MAX)})^2 \left( \frac{C_{RSS} f_{SW}}{I_{GATE}} \right) I_{LOAD}$$

where  $C_{RSS}$  is the reverse transfer capacitance of  $N_H$  and  $I_{GATE}$  is the peak gate-drive source/sink current (1A typ), and  $I_{LOAD}$  is the per-phase current.

Switching losses in the high-side MOSFET can become an insidious heat problem when maximum AC adapter voltages are applied, due to the squared term in the  $C \times V_{IN}^2 \times f_{SW}$  switching-loss equation. If the high-side MOSFET chosen for adequate  $R_{DS(ON)}$  at low-battery voltages becomes extraordinarily hot when biased from  $V_{IN(MAX)}$ , consider choosing another MOSFET with lower parasitic capacitance.

For the low-side MOSFET ( $N_L$ ), the worst-case power dissipation always occurs at maximum input voltage:

$$PD(NLResistive) = \left[ 1 - \left( \frac{V_{OUT}}{V_{IN(MAX)}} \right) \right] \left( \frac{I_{LOAD}}{\eta_{TOTAL}} \right)^2 R_{DS(ON)}$$

The worst case for MOSFET power dissipation occurs under heavy overloads that are greater than  $I_{LOAD(MAX)}$  but are not quite high enough to exceed the current limit and cause the fault latch to trip. To protect against this possibility, you can “overdesign” the circuit to tolerate:

$$\begin{aligned} I_{LOAD(MAX)} &= I_{PEAK(MAX)} - \frac{\Delta I_{INDUCTOR}}{2} \\ &= I_{PEAK(MAX)} - \left( \frac{I_{LOAD(MAX)} L_{IR}}{2} \right) \end{aligned}$$

where  $I_{PEAK(MAX)}$  is the maximum valley current allowed by the current-limit circuit, including threshold tolerance and on-resistance variation. The MOSFETs must have a good-size heatsink to handle the overload power dissipation.

Choose a Schottky diode ( $D_L$ ) with a forward voltage low enough to prevent the low-side MOSFET body diode from turning on during the dead time. As a general rule, select a diode with a DC current rating equal to 1/3 the load current per phase. This diode is optional and can be removed if efficiency is not critical.

## Boost Capacitors

The boost capacitors ( $C_{BST}$ ) must be selected large enough to handle the gate-charging requirements of the high-side MOSFETs. Typically, 0.1 $\mu$ F ceramic capacitors work well for low-power applications driving medium-sized MOSFETs. However, high-current applications driving large, high-side MOSFETs require boost capacitors larger than 0.1 $\mu$ F. For these applications, select the boost capacitors to avoid discharging the capacitor more than 200mV while charging the high-side MOSFETs' gates:

$$C_{BST} = \frac{N \times Q_{GATE}}{200mV}$$

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where N is the number of high-side MOSFETs used for one regulator, and Q<sub>GATE</sub> is the gate charge specified in the MOSFET's data sheet. For example, assume (2) IRF7811W n-channel MOSFETs are used on the high side. According to the manufacturer's data sheet, a single IRF7811W has a maximum gate charge of 24nC (V<sub>GS</sub> = 5V). Using the above equation, the required boost capacitance would be:

$$C_{BST} = \frac{2 \times 24nC}{200mV} = 0.24\mu F$$

Selecting the closest standard value, this example requires a 0.22μF ceramic capacitor.

## SVI Applications Information

### I<sup>2</sup>C-Bus-Compatible Interface

The MAX17009 is a receive-only device. The 2-wire serial bus (pins SVC and SVD) is designed to attach on a low-voltage, I<sup>2</sup>C-like bus. In the AMD mobile application, the CPU directly drives the bus at a speed of 3.4MHz. The CPU has a push-pull output driving to the V<sub>DDIO</sub> voltage level. External pullup resistors may be required during the initial power-up sequence before the CPU's push-pull drivers are active. Refer to AMD for specific implementation.

When not used in the specific AMD application, the serial interface can be driven to as high as 2.5V, and operate at the lower speeds (100kHz, 400kHz, or 1.7MHz). At lower clock speeds, external pullup resistors can be used for open-drain outputs. Connect both SVC and SVD lines to V<sub>DDIO</sub> through individual pullup resistors. Calculate the required value of the pullup resistors using:

$$R_{PULLUP} \leq \frac{t_R}{C_{BUS}}$$

where t<sub>R</sub> is the rise time, and should be less than 10% of the clock period. C<sub>BUS</sub> is the total capacitance on the bus.

The MAX17009 is compatible with the standard SVI interface protocol as defined in the following subsections.

### Bus Not Busy

The SVI bus is not busy when both data and clock lines remain HIGH. Data transfers can be initiated only when the bus is not busy.

### Start Data Transfer (S)

Starting from an idle bus state (both SVC and SVD are high), a HIGH to LOW transition of the data (SVD) line while the clock (SVC) is HIGH determines a START condition. All commands must be preceded by a START condition.

### Stop Data Transfer (P)

A LOW to HIGH transition of the SDA line while the clock (SVC) is HIGH determines a STOP condition. All operations must be ended with a STOP condition. Figure 10 shows the SVI bus START, STOP, and data change conditions

### Slave Address

After generating a START condition, the bus master transmits the slave address consisting of a 7-bit device code (110xxxx) for the MAX17009. Since the MAX17009 is a write-only device, the eighth bit of the slave address is zero. The MAX17009 monitors the bus for its corresponding slave address continuously. It generates an acknowledge bit if the slave address was true and it is not in a programming mode.

### SVD Data Valid

The state of the data line represents valid data when, after a START condition, the data line is stable for the duration of the HIGH period of the clock signal. The data on the line must be changed during the LOW period of the clock signal. There is one clock pulse per bit of data.

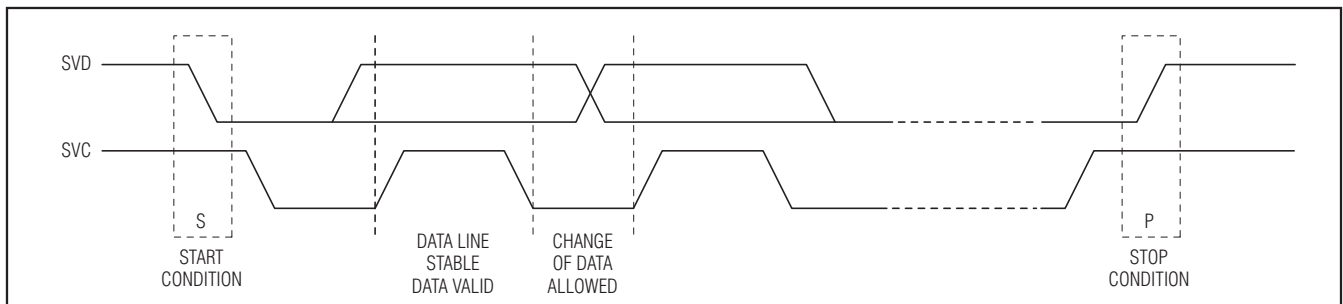


Figure 10. SVI Bus START, STOP, and Data Change Conditions

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## Acknowledge

Each receiving device, when addressed, is obliged to generate an acknowledge after the reception of each byte. The master device must generate an extra clock pulse that is associated with this acknowledge bit. The device that acknowledges has to pull down the SVD line during the acknowledge clock pulse so the SVD line is stable LOW during the HIGH period of the acknowledge-related clock pulse. Setup and hold times must be taken into account. See Figure 11. Figure 12 shows the SVI bus data transfer summary.

## Command Byte

A complete command consists of a START condition (S) followed by the MAX17009's slave address and a data phase, followed by a STOP condition (P).

## SMPS Applications Information

### Duty-Cycle Limits

#### Minimum Input Voltage

The minimum input operating voltage (dropout voltage) is restricted by stability requirements, not the minimum off-time ( $t_{OFF(MIN)}$ ). The MAX17009 does not include slope compensation, so the controller becomes unstable with duty cycles greater than 50% per phase:

$$V_{IN(MIN)} \geq 2 \times V_{OUT(MAX)}$$

However, the controller can briefly operate with duty cycles over 50% during heavy load transients.

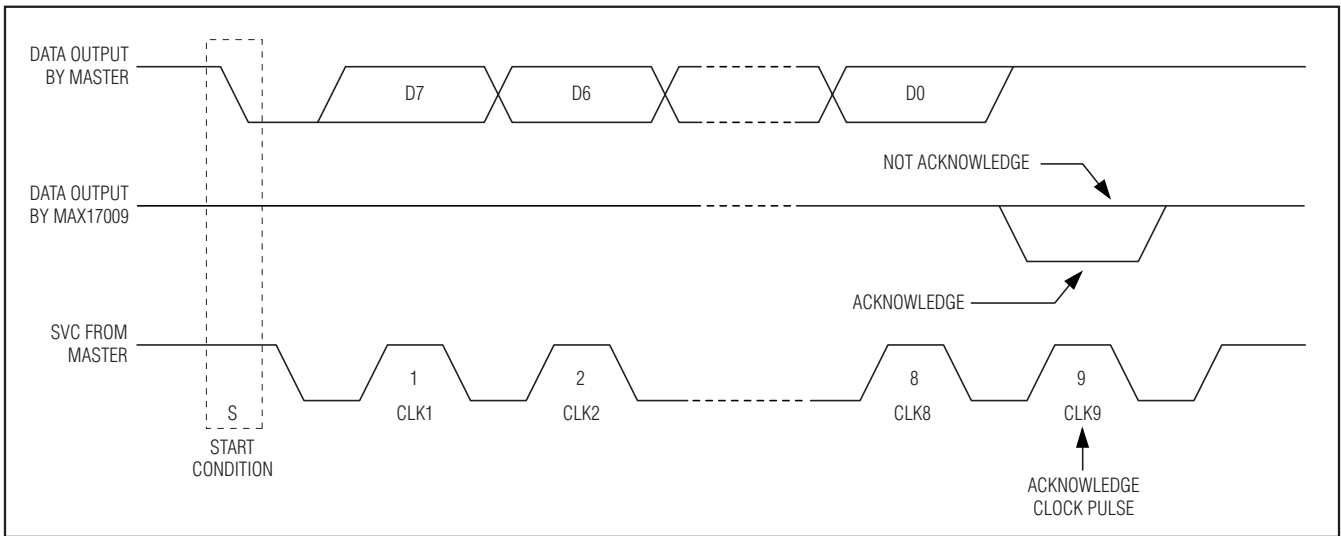


Figure 11. SVI Bus Acknowledge

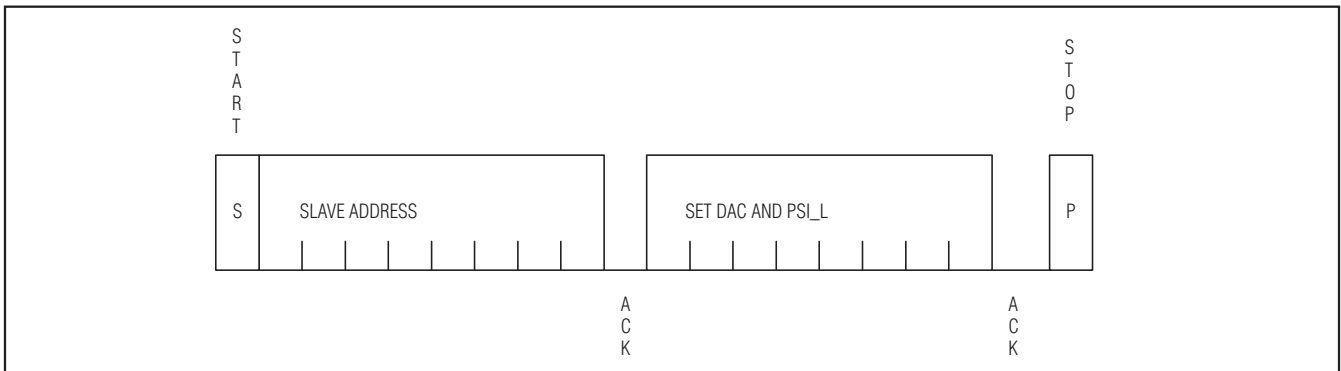


Figure 12. SVI Bus Data Transfer Summary

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**Table 7. SVI Send Byte Address Description**

| BITS | DESCRIPTION  |
|------|--|
| 6:4  | Always 110b  |
| 3    | X = don't care   |
| 2    | V <sub>DAC2</sub> , if set, then the following data byte contains the VID for V <sub>DAC2</sub> ; bit 2 is ignored in combined mode (GNDS2 = V <sub>DDIO</sub> ) |
| 1    | V <sub>DAC1</sub> , if set, then the following data byte contains the VID for V <sub>DAC1</sub> in separate mode, and the unified VDD in combined mode           |
| 0    | V <sub>DAC_NB</sub> , if set then the following data byte contains the VID for V <sub>DAC_NB</sub>   |

**Table 8. Serial VID 8-Bit Data Field Encoding**

| BITS | DESCRIPTION  |
|------|--|
| 7    | PSI_L: Power-Save Indicator: <ul style="list-style-type: none"> <li>0 means the processor is at an optimal load and the regulator(s) can enter power-saving mode. Offset is disabled if previously enabled through the OPTION pin. The MAX17009 enters 1-phase operation if in combined mode (GNDS2 = H).</li> <li>1 means the processor is at a high current-consumption state. Offset is enabled if previously enabled through the OPTION pin. The MAX17009 returns to 2-phase operation if in combined mode (GNDS2 = H).</li> </ul> |
| 6:0  | SVID[6:0] as defined in Table 7.   |

### Maximum Input Voltage

The MAX17009 controller has a minimum on-time, which determines the maximum input operating voltage that maintains the selected switching frequency. With higher input voltages, each pulse delivers more energy than the output is sourcing to the load. At the beginning of each cycle, if the output voltage is still above the feedback threshold voltage, the controller does not trigger an on-time pulse, resulting in pulse-skipping operation. This allows the controller to maintain regulation above the maximum input voltage, but forces the controller to effectively operate with a lower switching frequency. This results in an input threshold voltage at which the controller begins to skip pulses (V<sub>IN(SKIP)</sub>):

$$V_{IN(SKIP)} = V_{OUT} \left( \frac{1}{f_{SW} t_{ONMIN}} \right)$$

where f<sub>SW</sub> is the per-phase switching frequency set by the OSC resistor, and t<sub>ONMIN</sub> is 185ns (max) minus the driver's turn-on delay (DL low to DH high). For the best high-voltage performance, use the slowest switching frequency setting (100kHz per phase, R<sub>OSC</sub> = 432kΩ).

### PCB Layout Guidelines

Careful PCB layout is critical to achieve low switching losses and clean, stable operation. The switching power stage requires particular attention (Figure 13). If possible, mount all the power components on the top side of the board with their ground terminals flush against one another, and mount the controller and analog components on the bottom layer so the internal ground layers shield the analog components from any noise generated by the power components. Follow these guidelines for good PCB layout:

- Keep the high-current paths short, especially at the ground terminals. This is essential for stable, jitter-free operation.
- Connect all analog grounds to a separate solid copper plane, then connect the analog ground to the GND pins of the controller. The following sensitive components connect to analog ground: V<sub>CC</sub>, V<sub>DDIO</sub>, and REF bypass capacitors, remote-sense and GNDS bypass capacitors, and the resistive connections (ILIM, OSC, TIME).
- Keep the power traces and load connections short. This is essential for high efficiency. The use of thick copper PCBs (2oz vs. 1oz) can enhance full-load efficiency by 1% or more. Correctly routing PCB traces is a difficult task that must be approached in terms of fractions of centimeters, where a single mΩ of excess trace resistance causes a measurable efficiency penalty.
- Connections for current limiting (CSP<sub>-</sub>, CSN<sub>-</sub>) and voltage positioning (FBS, GNDS) must be made using Kelvin-sense connections to guarantee the current-sense accuracy. Place current-sense filter capacitors and voltage-positioning filter capacitors as close to the IC as possible.
- Route high-speed switching nodes and driver traces away from sensitive analog areas (REF, V<sub>CC</sub>, FBAC, FBDC, etc.). Make all pin-strap control input connections (SHDN, PGD<sub>IN</sub>, OPTION) to analog ground or V<sub>CC</sub> rather than power ground or V<sub>DD</sub>.
- Route the high-speed serial-interface signals (SVC, SVD) in parallel, keeping the trace lengths identical. Keep the SVC and SVD away from the high-current switching paths.



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- Keep the drivers close to the MOSFET, with the gate-drive traces (DL, DH, LX, and BST) short and wide to minimize trace resistance and inductance. This is essential for high-power MOSFETs that require low-impedance gate drivers to avoid shoot-through currents.
- When trade-offs in trace lengths must be made, it is preferable to allow the inductor charging path to be made longer than the discharge path. For example, it is better to allow some extra distance between the input capacitors and the high-side MOSFET than to allow distance between the inductor and the low-side MOSFET or between the inductor and the output filter capacitor.

## Layout Procedure

- 1) Place the power components first, with ground terminals adjacent (low-side MOSFET source,  $C_{IN}$ ,  $C_{OUT}$ , and DL anode). If possible, make all these connections on the top layer with wide, copper-filled areas.
- 2) Mount the driver IC adjacent to the low-side MOSFETs. The DL gate traces must be short and wide (50 mils to 100 mils wide if the MOSFET is 1in from the driver IC).
- 3) Group the gate-drive components (BST capacitors,  $V_{DD}$  bypass capacitor) together near the driver IC.
- 4) Make the DC-DC controller ground connections as shown in the standard application circuit in Figure 2. This diagram can be viewed as having three separate ground planes: input/output ground, where all the high-power components go; the power ground plane, where the PGND pin,  $V_{DD}$  bypass capacitor, and driver IC ground connection go; and the controller's analog ground plane where sensitive analog components, the master's GND pin, and  $V_{CC}$  bypass capacitor go. The controller's analog ground plane (GND) must meet the power ground plane (PGND) only at a single point directly beneath the IC. The power ground plane should connect to the high-power output ground with a short, thick metal trace from PGND to the source of the low-side MOSFETs (the middle of the star ground).
- 5) Connect the output power planes ( $V_{CORE}$  and system ground planes) directly to the output-filter capacitor positive and negative terminals with multiple vias. Place the entire DC-DC converter circuit as close to the CPU as is practical. Figure 13 is a PCB layout example.

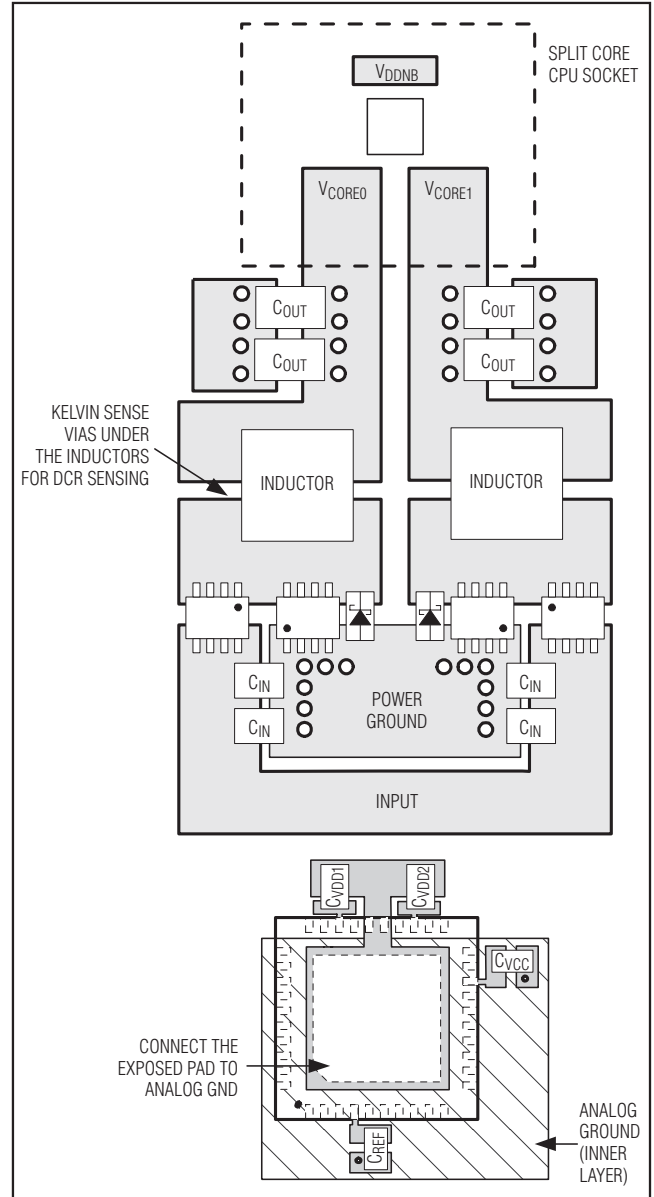


Figure 13. PCB Layout Example



# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

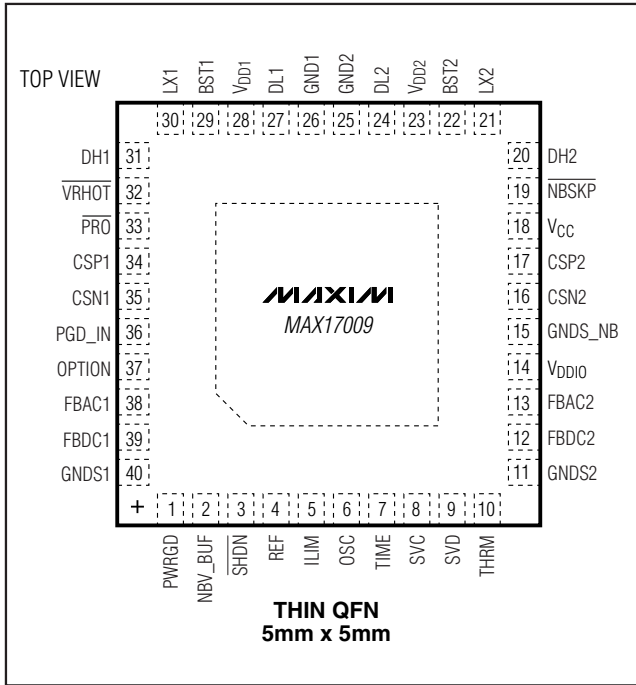
## Pin Configuration

## Chip Information

TRANSISTOR COUNT: 14,497

PROCESS: BiCMOS

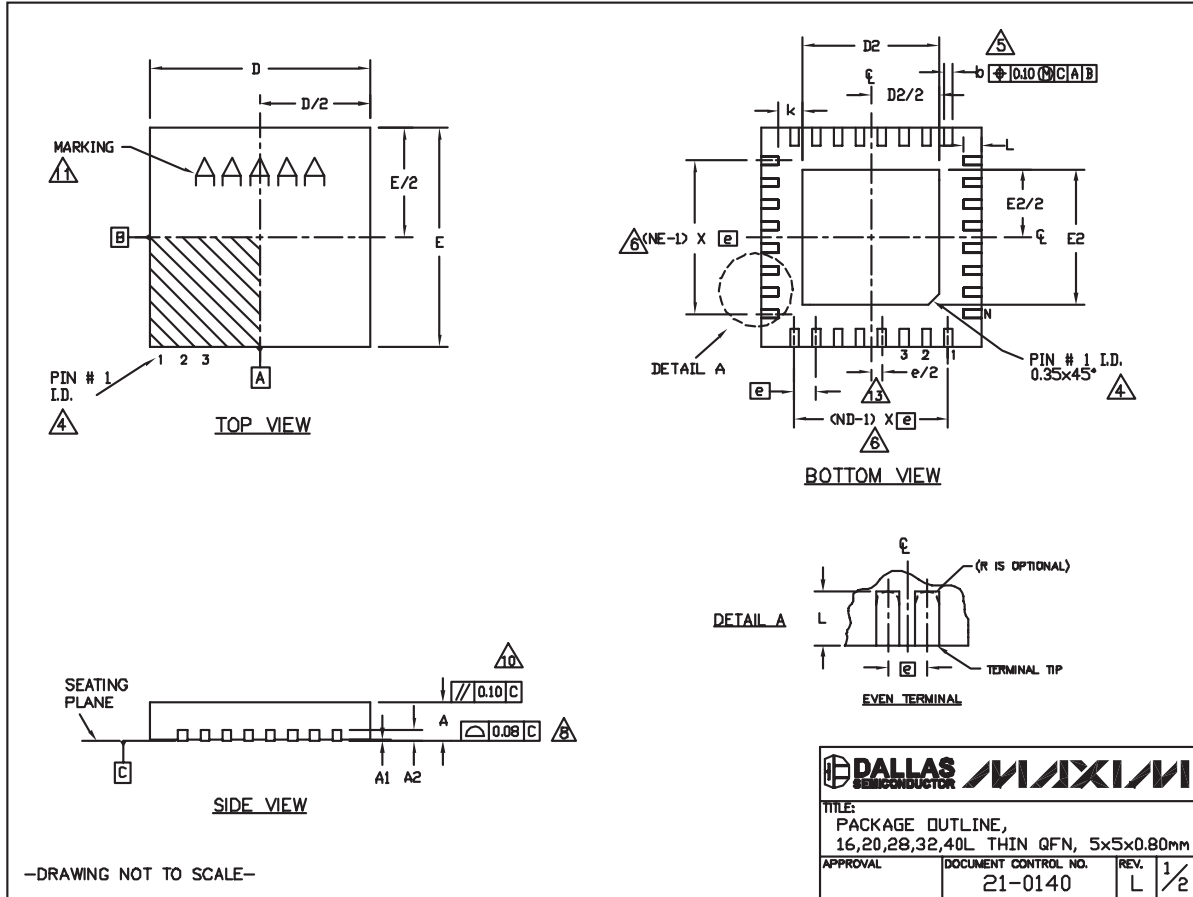
**MAX17009**



# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

## Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to [www.maxim-ic.com/packages](http://www.maxim-ic.com/packages).)



# AMD Mobile Serial VID Dual-Phase Fixed-Frequency Controller

## Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to [www.maxim-ic.com/packages](http://www.maxim-ic.com/packages).)

MAX17009

| COMMON DIMENSIONS |           |      |      |           |      |      |           |      |      |           |      |      |           |      |      |
|-------------------|-----------|------|------|-----------|------|------|-----------|------|------|-----------|------|------|-----------|------|------|
| PKG.              | 16L 5x5   |      |      | 20L 5x5   |      |      | 28L 5x5   |      |      | 32L 5x5   |      |      | 40L 5x5   |      |      |
| SYMBOL            | MIN.      | NOM. | MAX. | MIN.      | NOM. | MAX. | MIN.      | NOM. | MAX. | MIN.      | NOM. | MAX. | MIN.      | NOM. | MAX. |
| A                 | 0.70      | 0.75 | 0.80 | 0.70      | 0.75 | 0.80 | 0.70      | 0.75 | 0.80 | 0.70      | 0.75 | 0.80 | 0.70      | 0.75 | 0.80 |
| A1                | 0         | 0.02 | 0.05 | 0         | 0.02 | 0.05 | 0         | 0.02 | 0.05 | 0         | 0.02 | 0.05 | 0         | 0.02 | 0.05 |
| A2                | 0.20 REF. |      |      | 0.20 REF. |      |      | 0.20 REF. |      |      | 0.20 REF. |      |      | 0.20 REF. |      |      |
| b                 | 0.25      | 0.30 | 0.35 | 0.25      | 0.30 | 0.35 | 0.20      | 0.25 | 0.30 | 0.20      | 0.25 | 0.30 | 0.15      | 0.20 | 0.25 |
| D                 | 4.90      | 5.00 | 5.10 | 4.90      | 5.00 | 5.10 | 4.90      | 5.00 | 5.10 | 4.90      | 5.00 | 5.10 | 4.90      | 5.00 | 5.10 |
| E                 | 4.90      | 5.00 | 5.10 | 4.90      | 5.00 | 5.10 | 4.90      | 5.00 | 5.10 | 4.90      | 5.00 | 5.10 | 4.90      | 5.00 | 5.10 |
| e                 | 0.60 BSC. |      |      | 0.65 BSC. |      |      | 0.50 BSC. |      |      | 0.50 BSC. |      |      | 0.40 BSC. |      |      |
| k                 | 0.25      | -    | -    | 0.25      | -    | -    | 0.25      | -    | -    | 0.25      | -    | -    | 0.25      | -    | -    |
| L                 | 0.30      | 0.40 | 0.50 | 0.45      | 0.55 | 0.65 | 0.45      | 0.55 | 0.65 | 0.30      | 0.40 | 0.50 | 0.30      | 0.40 | 0.50 |
| N                 | 16        |      |      | 20        |      |      | 28        |      |      | 32        |      |      | 40        |      |      |
| ND                | 4         |      |      | 5         |      |      | 7         |      |      | 8         |      |      | 10        |      |      |
| NE                | 4         |      |      | 5         |      |      | 7         |      |      | 8         |      |      | 10        |      |      |
| JEDEC             | WHHB      |      |      | WHHC      |      |      | WHHD-1    |      |      | WHHD-2    |      |      | -----     |      |      |

| EXPOSED PAD VARIATIONS |      |      |      |      |      |      |
|------------------------|------|------|------|------|------|------|
| PKG. CODES             | D2   |      |      | E2   |      |      |
|                        | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. |
| T1655-2                | 3.00 | 3.10 | 3.20 | 3.00 | 3.10 | 3.20 |
| T1655-3                | 3.00 | 3.10 | 3.20 | 3.00 | 3.10 | 3.20 |
| T1655N-1               | 3.00 | 3.10 | 3.20 | 3.00 | 3.10 | 3.20 |
| T2055-3                | 3.00 | 3.10 | 3.20 | 3.00 | 3.10 | 3.20 |
| T2055-4                | 3.00 | 3.10 | 3.20 | 3.00 | 3.10 | 3.20 |
| T2055-5                | 3.15 | 3.25 | 3.35 | 3.15 | 3.25 | 3.35 |
| T2055MN-5              | 3.15 | 3.25 | 3.35 | 3.15 | 3.25 | 3.35 |
| T2855-3                | 3.15 | 3.25 | 3.35 | 3.15 | 3.25 | 3.35 |
| T2855-4                | 2.60 | 2.70 | 2.80 | 2.60 | 2.70 | 2.80 |
| T2855-5                | 2.60 | 2.70 | 2.80 | 2.60 | 2.70 | 2.80 |
| T2855-6                | 3.15 | 3.25 | 3.35 | 3.15 | 3.25 | 3.35 |
| T2855-7                | 2.60 | 2.70 | 2.80 | 2.60 | 2.70 | 2.80 |
| T2855-8                | 3.15 | 3.25 | 3.35 | 3.15 | 3.25 | 3.35 |
| T2855N-1               | 3.15 | 3.25 | 3.35 | 3.15 | 3.25 | 3.35 |
| T3255-3                | 3.00 | 3.10 | 3.20 | 3.00 | 3.10 | 3.20 |
| T3255-4                | 3.00 | 3.10 | 3.20 | 3.00 | 3.10 | 3.20 |
| T3255M-4               | 3.00 | 3.10 | 3.20 | 3.00 | 3.10 | 3.20 |
| T3255-5                | 3.00 | 3.10 | 3.20 | 3.00 | 3.10 | 3.20 |
| T3255N-1               | 3.00 | 3.10 | 3.20 | 3.00 | 3.10 | 3.20 |
| T4055-1                | 3.40 | 3.50 | 3.60 | 3.40 | 3.50 | 3.60 |
| T4055-2                | 3.40 | 3.50 | 3.60 | 3.40 | 3.50 | 3.60 |
| T4055MN-1              | 3.40 | 3.50 | 3.60 | 3.40 | 3.50 | 3.60 |

### NOTES:

- DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994.
- ALL DIMENSIONS ARE IN MILLIMETERS. ANGLES ARE IN DEGREES.
- N IS THE TOTAL NUMBER OF TERMINALS.
- THE TERMINAL #1 IDENTIFIER AND TERMINAL NUMBERING CONVENTION SHALL CONFORM TO JEDEC 95-1 SPP-012. DETAILS OF TERMINAL #1 IDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED WITHIN THE ZONE INDICATED. THE TERMINAL #1 IDENTIFIER MAY BE EITHER A MOLD OR MARKED FEATURE.
- DIMENSION b APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.25 mm AND 0.30 mm FROM TERMINAL TIP.
- ND AND NE REFER TO THE NUMBER OF TERMINALS ON EACH D AND E SIDE RESPECTIVELY.
- DEPOPULATION IS POSSIBLE IN A SYMMETRICAL FASHION.
- COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.
- DRAWING CONFORMS TO JEDEC MO220, EXCEPT EXPOSED PAD DIMENSION FOR T2855-3, T2855-6, T4055-1 AND T4055-2.
- WARPAGE SHALL NOT EXCEED 0.10 mm.
- MARKING IS FOR PACKAGE ORIENTATION REFERENCE ONLY.
- NUMBER OF LEADS SHOWN ARE FOR REFERENCE ONLY.
- LEAD CENTERLINES TO BE AT TRUE POSITION AS DEFINED BY BASIC DIMENSION 'e', ±0.05.
- ALL DIMENSIONS APPLY TO BOTH LEADED AND PbfREE PARTS.

-DRAWING NOT TO SCALE-

|  |                                 |
|--|---------------------------------|
|  |                                 |
| TITLE:<br>PACKAGE OUTLINE,<br>16,20,28,32,40L THIN QFN, 5x5x0.80mm |                                 |
| APPROVAL   | DOCUMENT CONTROL NO.<br>21-0140 |
| REV.<br>L  | 2/2                             |

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[MCP16502TAB-E/S8B](#) [TCKE712BNL,RF](#) [ISL91211AIKZT7AR5874](#) [ISL91211BIKZT7AR5878](#) [MCP16501TC-E/RMB](#) [ISL91212AIIZ-](#)  
[TR5770](#) [ISL91212BIIZ-TR5775](#) [CPX200D](#) [AX-3005D-3](#) [TP-1303](#) [TP-1305](#) [TP-1603](#) [TP-2305](#) [TP-30102](#) [TP-4503N](#) [MIC5167YML-TR](#)  
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